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#### **ETSI**

650 Route des Lucioles F-06921 Sophia Antipolis Cedex - FRANCE

Tel.: +33 4 92 94 42 00 Fax: +33 4 93 65 47 16

Siret N° 348 623 562 00017 - NAF 742 C Association à but non lucratif enregistrée à la Sous-Préfecture de Grasse (06) N° 7803/88

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## **Foreword**

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## 1 Scope

[14]

[15]

The present document establishes the minimum RF requirements for NR User Equipment (UE) operating on frequency Range 2.

## 2 References

The following documents contain provisions which, through reference in this text, constitute provisions of the present document.

- References are either specific (identified by date of publication, edition number, version number, etc.) or non-specific.
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Trevense as m	e present deciment
[1]	3GPP TR 21.905: "Vocabulary for 3GPP Specifications".
[2]	3GPP TS 38.101-1: "NR; User Equipment (UE) radio transmission and reception; Part 1: Range 1 Standalone"
[3]	3GPP TS 38.101-3: "NR; User Equipment (UE) radio transmission and reception; Part 3: Range 1 and Range 2 Interworking operation with other radios"
[4]	Void
[5]	3GPP TS 38.521-2: "NR; User Equipment (UE) conformance specification; Radio transmission and reception; Part 2: Range 2 Standalone"
[6]	Recommendation ITU-R M.1545: "Measurement uncertainty as it applies to test limits for the terrestrial component of International Mobile Telecommunications-2000"
[7]	ITU-R Recommendation SM.329-10, "Unwanted emissions in the spurious domain"
[8]	47 CFR Part 30, "UPPER MICROWAVE FLEXIBLE USE SERVICE, §30.202 Power limits", FCC.
[9]	3GPP TS 38.211: "NR; Physical channels and modulation".
[10]	3GPP TS 38.213: "NR; Physical layer procedures for control".
[11]	3GPP TS 38.215: "NR; Physical layer measurements".
[12]	3GPP TS 38.133: "NR; Requirements for support of radio resource management".
[13]	3GPP TS 38.331: "NR; Radio Resource Control (RRC); Protocol specification".

3GPP TS 38.306: "NR; User Equipment (UE) radio access capabilities".

IEEE Std 149: "IEEE Standard Test Procedures for Antennas", IEEE.

## 3 Definitions, symbols and abbreviations

#### 3.1 Definitions

For the purposes of the present document, the terms and definitions given in 3GPP TR 21.905 [1] and the following apply. A term defined in the present document takes precedence over the definition of the same term, if any, in 3GPP TR 21.905 [1].

**Aggregated Channel Bandwidth:** The RF bandwidth in which a UE transmits and receives multiple contiguously aggregated carriers.

**Beam correspondence:** the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping.

**Carrier aggregation:** Aggregation of two or more component carriers in order to support wider transmission bandwidths.

**Carrier aggregation band:** A set of one or more operating bands across which multiple carriers are aggregated with a specific set of technical requirements.

**Carrier aggregation bandwidth class:** A class defined by the aggregated transmission bandwidth configuration and maximum number of component carriers supported by a UE.

Carrier aggregation configuration: A combination of CA operating band(s) and CA bandwidth class(es) supported by a UE.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

**EIRP(Link=Link angle, Meas=Link angle):** measurement of the UE such that the link angle is aligned with the measurement angle. EIRP (indicator to be measured) can be replaced by EIS, Frequency, EVM, carrier Leakage, Inband eission and OBW. Beam peak search grids, TX beam peak direction, and RX beam peak direction can be selected to describe Link.

**EIRP**(Link=Link angle, Meas=beam peak direction): measurement of the EIRP of the UE such that the measurement angle is aligned with the beam peak direction within an acceptable measurement error uncertainty.

**EIS** (equivalent isotropic sensitivity): sensitivity for an isotropic directivity device equivalent to the sensitivity of the discussed device exposed to an incoming wave from a defined AoA

NOTE 1: The sensitivity is the minimum received power level at which specific requirement is met.

NOTE 2: Isotropic directivity is equal in all directions (i.e. 0 dBi).

**Fallback group:** Group of carrier aggregation bandwidth classes for which it is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group

Inter-band carrier aggregation: Carrier aggregation of component carriers in different operating bands.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

**Intra-band contiguous carrier aggregation:** Contiguous carriers aggregated in the same operating band.

Intra-band non-contiguous carrier aggregation: Non-contiguous carriers aggregated in the same operating band.

Link angle: a DL-signal AoA from the view point of the UE, as described in Annex J.

**Measurement angle:** the angle of measurement of the desired metric from the view point of the UE, as described in Annex J

radiated interface boundary: operating band specific radiated requirements reference point where the radiated requirements apply

**RX** beam peak direction: direction where the maximum total component of RSRP and thus best total component of EIS is found

**Sub-block:** This is one contiguous allocated block of spectrum for transmission and reception by the same UE. There may be multiple instances of sub-blocks within an RF bandwidth.

TX beam peak direction: direction where the maximum total component of EIRP is found

**TRP(Link=Link angle):** measurement of the TRP of the UE such that the measurement angle is aligned with the beam peak direction within an acceptable measurement uncertainty. TX beam peak direction and RX beam peak direction can be selected to describe Link.

NOTE: For requirements based on EIRP/EIS, the radiated interface boundary is associated to the far-field region

**UE transmission bandwidth configuration:** Set of resource blocks located within the UE channel bandwidth which may be used for transmitting or receiving by the UE.

Vehicular UE: A UE embedded in a vehicle

## 3.2 Symbols

For the purposes of the present document, the following symbols apply:

 $\Delta EIRP_{BC}$  The beam correspondence tolerance, where  $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$ 

 $\begin{array}{ll} \Delta F_{Global} & Granularity \ of \ the \ global \ frequency \ raster \\ \Delta F_{Raster} & Band \ dependent \ channel \ raster \ granularity \\ \Delta f_{OOB} & \Delta \ Frequency \ of \ Out \ Of \ Band \ emission \end{array}$ 

 $\Delta_{RB}$  The starting frequency offset between the allocated RB and the measured non-allocated RB

 $\Delta R_{IB}$  Allowed reference sensitivity relaxation due to support for inter-band CA operation

 $\Delta MB_{P,n}$  Allowed relaxation to each, minimum peak EIRP and reference sensitivity due to support for

multi-band operation, per band in a combination of supported bands

 $\Delta MB_{S,n}$  Allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to support

for multi-band operation, per band in a combination of supported bands

∑MB<sub>P</sub> Total allowed relaxation to each, minimum peak EIRP and reference sensitivity due to support for

multi-band operation, for all bands in a combination of supported bands

 $\Sigma$ MB<sub>S</sub> Total allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to

support for multi-band operation, for all bands in a combination of supported bands

BW<sub>Channel</sub> Channel bandwidth

BW<sub>Channel CA</sub> Aggregated channel bandwidth, expressed in MHz

 $BW_{GB}$  max( BWGB, Channel(k) )

BW<sub>GB,Channel(k)</sub> Minimum guard band defined in sub-clause 5.3.3 of carrier k

 $BW_{interferer} \hspace{1.5cm} Bandwidth \ of \ the \ interferer$ 

Ceil(x) Rounding upwards; ceil(x) is the smallest integer such that  $ceil(x) \ge x$ 

EIRP<sub>1</sub> The measured total EIRP based on the beam the UE chooses autonomously (corresponding beam)

to transmit in the direction of the incoming DL signal, which is based on beam correspondence

without relying on UL beam sweeping

EIRP<sub>2</sub> The measured total EIRP based on the beam yielding highest EIRP in a given direction, which is

based on beam correspondence with relying on UL beam sweeping

EIRP<sub>max</sub> The applicable maximum EIRP as specified in sub-clause 6.2.1

Floor(x) Rounding downwards; floor(x) is the greatest integer such that floor(x)  $\leq$  x

F<sub>C</sub> RF reference frequency for the carrier center on the channel raster, given in table 5.4.2.2-1

 $\begin{array}{ll} F_{C,block,\;high} & Fc\;of\;the\;highest\;transmitted/received\;carrier\;in\;a\;sub\text{-}block.\\ F_{C,block,\;low} & Fc\;of\;the\;lowest\;transmitted/received\;carrier\;in\;a\;sub\text{-}block. \end{array}$ 

 $F_{C, low}$  The Fc of the lowest carrier, expressed in MHz. Fc, high The Fc of the highest carrier, expressed in MHz.

 $F_{\text{edge, low}}$  The lower edge of Aggregated Channel Bandwidth, expressed in MHz.  $F_{\text{edge, low}} = F_{\text{C, low}} - F_{\text{offset, low}}$ . The upper edge of Aggregated Channel Bandwidth, expressed in MHz.  $F_{\text{edge, high}} = F_{\text{C, high}} + F_{\text{offset, low}}$ .

hig

F<sub>Interferer</sub> (offset) Frequency offset of the interferer (between the center frequency of the interferer and the carrier

frequency of the carrier measured)

F<sub>Interferer</sub> Frequency of the interferer

Frequency offset from F<sub>C, low</sub> to the lower *UE RF Bandwidth edge*, or from F<sub>C, block, low</sub> to the lower

sub-block edge

 $F_{offset,\,high}$  Frequency offset from  $F_{C,\,high}$  to the upper  $UE\,RF\,Bandwidth\,edge$ , or from  $F_{C,\,block,\,high}$  to the upper

sub-block edge

 $\begin{array}{lll} F\_center & The center frequency of an allocated block of PRBs \\ F_{DL\_low} & The lowest frequency of the downlink operating band \\ F_{DL\_high} & The highest frequency of the downlink operating band \\ F_{UL\_low} & The lowest frequency of the uplink operating band \\ F_{UL\_high} & The highest frequency of the uplink operating band \\ \end{array}$ 

F<sub>Interferer</sub> (offset) Frequency offset of the interferer (between the center frequency of the interferer and the carrier

frequency of the carrier measured)

F<sub>Interferer</sub> Frequency of the interferer

F<sub>loffset</sub> Frequency offset of the interferer (between the center frequency of the interferer and the closest

edge of the carrier measured)

F<sub>OOB</sub> The boundary between the NR out of band emission and spurious emission domains

 $\begin{array}{ll} F_{REF} & RF \ reference \ frequency \\ F_{REF-Offs} & Offset \ used \ for \ calculating \ F_{REF} \end{array}$ 

 $F_{UL\_Meas}$  The sub-carrier frequency for which the equalizer coefficient is evaluated

GB<sub>Channel</sub> Minimum guard band defined in sub-clause 5.3.3

L<sub>CRB</sub> Transmission bandwidth which represents the length of a contiguous resource block allocation

expressed in units of resources blocks

L<sub>CRB,Max</sub> Maximum number of RB for a given Channel bandwidth and sub-carrier spacing

Max() The largest of given numbers
Min() The smallest of given numbers

MPR $_{f,c}$  Maximum output power reduction for carrier f of serving cell c MPR $_{narrow}$  Maximum output power reduction due to narrow PRB allocation

MPR<sub>WT</sub> Maximum power reduction due to modulation orders, transmit bandwidth configurations,

waveform types

 $n_{PRB}$  Physical resource block number

NR<sub>ACLR</sub> NR ACLR

N<sub>RB</sub> Transmission bandwidth configuration, expressed in units of resource blocks

N<sub>RB,low</sub> Transmission bandwidth configurations according to Table 5.3.2-1 for the lowest assigned

component carrier in section 5.3A.1

 $N_{RB,high}$  Transmission bandwidth configurations according to Table 5.3.2-1 for the highest assigned

component carrier in section 5.3A.1

 $N_{REF} \hspace{1cm} NR \hspace{1cm} Absolute \hspace{1cm} Radio \hspace{1cm} Frequency \hspace{1cm} Channel \hspace{1cm} Number \hspace{1cm} (NR\text{-}ARFCN)$ 

 $N_{REF-Offs}$  Offset used for calculating  $N_{REF}$ 

 $P_{CMAX} \hspace{1.5cm} \textbf{The configured maximum UE output power} \\$ 

 $P_{CMAX}$ , f, c The configured maximum UE output power for carrier f of serving cell c  $P_{max}$  The maximum UE output power as specified in sub-clause 6.2.1  $P_{min}$  The minimum UE output power as specified in sub-clause 6.3.1

P<sub>int</sub> The minimum OE output power as specified in sub-clause P<sub>int</sub> The intermediate power point as defined in table 6.3.4.2-2

 $P_{Interferer}$  Modulated mean power of the interferer

P-MPR<sub>f,c</sub> The Power Management UE Maximum Power Reduction for carrier f of serving cell c

P<sub>PowerClass</sub> Nominal UE power class (i.e., no tolerance) as specified in sub-clause 6.2.1

 $P_{RB}$  The transmitted power per allocated RB, measured in dBm  $P_{TMAX,f,c}$  The measured total radiated power for carrier f of serving cell c

P<sub>UMAX</sub> The measured configured maximum UE output power

Pw Power of a wanted DL signal

RB<sub>start</sub> Indicates the lowest RB index of transmitted resource blocks SCS<sub>low</sub> SCS for the lowest assigned component carrier in section 5.3A.1 SCS<sub>high</sub> SCS for the highest assigned component carrier in section 5.3A.1

SS<sub>REF</sub> SS block reference frequency position

 $T(\Delta P)$  The tolerance  $T(\Delta P)$  for applicable values of  $\Delta P$  (values in dB)

TRP<sub>max</sub> The maximum TRP for the UE power class as specified in sub-clause 6.2.1

#### 3.3 Abbreviations

For the purposes of the present document, the abbreviations given in 3GPP TR 21.905 [1] and the following apply. An abbreviation defined in the present document takes precedence over the definition of the same abbreviation, if any, in 3GPP TR 21.905 [1].

ACLR Adjacent Channel Leakage Ratio ACS Adjacent Channel Selectivity

A-MPR Additional Maximum Power Reduction

AoA Angle of Arrival

BCS Bandwidth Combination Set BPSK Binary Phase-Shift Keying

BS Base Station
BW Bandwidth
BWP Bandwidth Part
CA Carrier aggregation

CA\_nX-nY Inter-band CA of component carrier(s) in one sub-block within Band X and component carrier(s)

in one sub-block within Band Y where X and Y are the applicable NR operating band

CC Component carrier

CDF Cumulative Distribution Function

CP-OFDM Cyclic Prefix-OFDM CW Continuous Wave

DFT-s-OFDM Discrete Fourier Transform-spread-OFDM

DM-RS Demodulation Reference Signal
DTX Discontinuous Transmission
EIRP Effective Isotropic Radiated Power
EIS Effective Isotropic Sensitivity
EVM Error Vector Magnitude
FR Frequency Range

FWA Fixed Wireless Access
GSCN Global Synchronization Channel Number

IBB In-band Blocking

IDFT Inverse Discrete Fourier Transformation

ITU-R Radiocommunication Sector of the International Telecommunication Union

MBW Measurement bandwidth defined for the protected band

MPR Allowed maximum power reduction

NR New Radio

NR-ARFCN NR Absolute Radio Frequency Channel Number

OCNG OFDMA Channel Noise Generator

OOB Out-of-band OTA Over The Air

P-MPR Power Management Maximum Power Reduction

PRB Physical Resource Block

QAM Quadrature Amplitude Modulation

RF Radio Frequency
REFSENS Reference Sensitivity
RIB Radiated Interface Boundary
RMS Root Mean Square (value)
RSEP Reference Signal Receiving R

RSRP Reference Signal Receiving Power

Rx Receiver

SCS Subcarrier spacing
SEM Spectrum Emission Mask
SRS Sounding Reference Symbol
SS Synchronization Symbol
TPC Transimission Power Control
TRP Total Radiated Power

Tx Transmitter UE User Equipment

UL MIMO Uplink Multiple Antenna transmission

### 4 General

## 4.1 Relationship between minimum requirements and test requirements

The present document is a Single-RAT specification for NR UE, covering RF characteristics and minimum performance requirements. Conformance to the present specification is demonstrated by fulfilling the test requirements specified in the conformance specification 3GPP TS 38.521-2 [5].

The Minimum Requirements given in this specification make no allowance for measurement uncertainty. The test specification TS 38.521-2 [5] defines test tolerances. These test tolerances are individually calculated for each test. The test tolerances are used to relax the minimum requirements in this specification to create test requirements. For some requirements, including regulatory requirements, the test tolerance is set to zero.

The measurement results returned by the test system are compared - without any modification - against the test requirements as defined in 3GPP TS 38.521-2 [5].

## 4.2 Applicability of minimum requirements

- a) In this specification the Minimum Requirements are specified as general requirements and additional requirements. Where the Requirement is specified as a general requirement, the requirement is mandated to be met in all scenarios
- b) For specific scenarios for which an additional requirement is specified, in addition to meeting the general requirement, the UE is mandated to meet the additional requirements.
- c) The spurious emissions power requirements are for the long-term average of the power. For the purpose of reducing measurement uncertainty it is acceptable to average the measured power over a period of time sufficient to reduce the uncertainty due to the statistical nature of the signal
- d) All the requirements for intra-band contiguous and non-contiguous CA apply under the assumption of the same slot format indicated by *TDD-UL-DL-Config* in the PCell and SCells for NR SA.

## 4.3 Specification suffix information

Unless stated otherwise the following suffixes are used for indicating at 2<sup>nd</sup> level subclause, shown in Table 4.3-1.

Table 4.3-1: Definition of suffixes

Clause suffix	Variant
None	Single Carrier
Α	Carrier Aggregation (CA)
В	Dual-Connectivity (DC)
С	Supplement Uplink (SUL)
D	UL MIMO
MOTE O (C. D.: 41)	16 2 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1

NOTE: Suffix D in this specification represents either polarized UL MIMO or spatial UL MIMO. RF requirements are same. If UE supports both kinds of UL MIMO, then RF requirements only need to be verified under either polarized or spatial UL MIMO.

## 5 Operating bands and channel arrangement

#### 5.1 General

The channel arrangements presented in this clause are based on the operating bands and channel bandwidths defined in the present release of specifications.

NOTE: Other operating bands and channel bandwidths may be considered in future releases.

Requirements throughout the RF specifications are in many cases defined separately for different frequency ranges (FR). The frequency ranges in which NR can operate according to this version of the specification are identified as described in Table 5.1-1.

Table 5.1-1: Definition of frequency ranges

Frequency range designation	Corresponding frequency range
FR1	410 MHz – 7125 MHz
FR2	24250 MHz - 52600 MHz

The present specification covers FR2 operating bands.

## 5.2 Operating bands

NR is designed to operate in the FR2 operating bands defined in Table 5.2-1.

Table 5.2-1: NR operating bands in FR2

Operating Band	Uplink (UL) operating band BS receive UE transmit	Downlink (DL) operating band BS transmit UE receive	Duplex Mode
	Ful_low - Ful_high	F <sub>DL_low</sub> - F <sub>DL_high</sub>	
n257	26500 MHz - 29500 MHz	26500 MHz - 29500 MHz	TDD
n258	24250 MHz - 27500 MHz	24250 MHz - 27500 MHz	TDD
n260	37000 MHz - 40000 MHz	37000 MHz - 40000 MHz	TDD
n261	27500 MHz - 28350 MHz	27500 MHz - 28350 MHz	TDD

## 5.2A Operating bands for CA

#### 5.2A.1 Intra-band CA

NR intra-band contiguous carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.1-1, where all operating bands are within FR2.

Table 5.2A.1-1: Intra-band contiguous CA operating bands in FR2

NR CA Band	NR Band (Table 5.2-1)
CA_n257B	n257
CA_n257D	n257
CA_n257E	n257
CA_n257F	n257
CA_n257G	n257
CA_n257H	n257
CA_n257I	n257
CA_n257J	n257
CA_n257K	n257
CA_n257L	n257
CA_n257M	n257
CA_n260B	n260
CA_n260C	n260
CA_n260D	n260
CA_n260E	n260
CA_n260F	n260
CA_n260G	n260
CA_n260H	n260
CA_n260I	n260
CA_n260J	n260
CA_n260K	n260
CA_n260L	n260
CA_n260M	n260
CA_n260O	n260
CA_n260P	n260
CA_n260Q	n260
CA_n261B	n261
CA_n261C	n261
CA_n261D	n261
CA_n261E	n261
CA_n261F	n261
CA_n261G	n261
CA_n261H	n261
CA_n261I	n261
CA_n261J	n261
CA_n261K	n261
CA_n261L	n261
CA_n261M	n261
CA_n261O	n261
CA_n261P	n261
CA_n261Q	n261

#### 5.2A.2 Void

## 5.2D Operating bands for UL MIMO

NR UL MIMO is designed to operate in the operating bands defined in Table 5.2D-1.

Table 5.2D-1: NR UL MIMO operating bands

UL MIMO operating band		
(	(Table 5.2-1)	
	n257	
	n258	
	n260	
	n261	

#### 5.3 UE Channel bandwidth

#### 5.3.1 General

The UE channel bandwidth supports a single NR RF carrier in the uplink or downlink at the UE. From a BS perspective, different UE channel bandwidths may be supported within the same spectrum for transmitting to and receiving from UEs connected to the BS. Transmission of multiple carriers to the same UE (CA) or multiple carriers to different UEs within the BS channel bandwidth can be supported.

From a UE perspective, the UE is configured with one or more BWP / carriers, each with its own UE channel bandwidth. The UE does not need to be aware of the BS channel bandwidth or how the BS allocates bandwidth to different UEs.

The placement of the UE channel bandwidth for each UE carrier is flexible but can only be completely within the BS channel bandwidth.

The relationship between the channel bandwidth, the guardband and the transmission bandwidth configuration is shown in Figure 5.3.1-1.

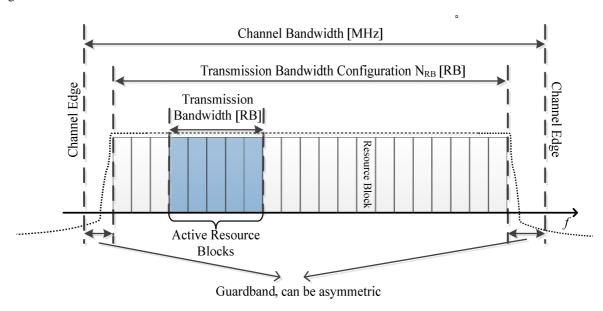


Figure 5.3.1-1: Definition of channel bandwidth and transmission bandwidth configuration for one NR channel

## 5.3.2 Maximum transmission bandwidth configuration

The maximum transmission bandwidth configuration  $N_{RB}$  for each UE channel bandwidth and subcarrier spacing is specified in Table 5.3.2-1

Table 5.3.2-1: Maximum transmission bandwidth configuration N<sub>RB</sub>

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
	N <sub>RB</sub>	N <sub>RB</sub>	N <sub>RB</sub>	N <sub>RB</sub>
60	66	132	264	N.A
120	32	66	132	264

#### 5.3.3 Minimum guardband and transmission bandwidth configuration

The minimum guardband for each UE channel bandwidth and SCS is specified in Table 5.3.3-1

Table 5.3.3-1: Minimum guardband for each UE channel bandwidth and SCS (kHz)

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
60	1210	2450	4930	N. A
120	1900	2420	4900	9860

NOTE: The minimum guardbands have been calculated using the following equation:  $(BW_{Channel} \times 1000 \text{ (kHz)} - N_{RB} \times SCS \times 12) / 2 - SCS/2$ , where  $N_{RB}$  are from Table 5.3.2-1.

The minimum guardband of receiving BS SCS 240 kHz SS/PBCH block for each UE channel bandwidth is specified in table 5.3.3-2 for FR2.

Table: 5.3.3-2: Minimum guardband (kHz) of SCS 240 kHz SS/PBCH block

SCS (kHz)	100 MHz	200 MHz	400 MHz
240	3800	7720	15560

NOTE: The minimum guardband in Table 5.3.3-2 is applicable only when the SCS 240 kHz SS/PBCH block is received adjacent to the edge of the UE channel bandwidth within which the SS/PBCH block is located.

Figure 5.3.3-1: Void

The number of RBs configured in any channel bandwidth shall ensure that the minimum guardband specified in this clause is met.

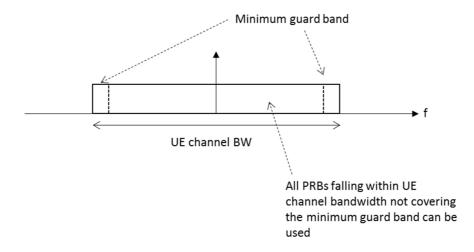


Figure 5.3.3-2 UE PRB utilization

In the case that multiple numerologies are multiplexed in the same symbol due to BS transmission of SSB, the minimum guardband on each side of the carrier is the guardband applied at the configured channel bandwidth for the numerology that is transmitted immediately adjacent to the guard band.

If multiple numerologies are multiplexed in the same symbol and the UE channel bandwidth is > 200 MHz, the minimum guardband applied adjacent to 60 kHz SCS shall be the same as the minimum guardband defined for 120 kHz SCS for the same UE channel bandwidth.

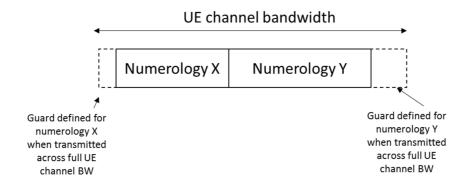


Figure 5.3.3-3 Guard band definition when transmitting multiple numerologies

Note: Figure 5.3.3-3 is not intended to imply the size of any guard between the two numerologies. Internumerology guard band within the carrier is implementation dependent.

#### 5.3.4 RB alignment

For each numerology, its common resource blocks are specified in Section 4.4.4.3 in [9], and the starting point of its transmission bandwidth configuration on the common resource block grid for a given channel bandwidth is indicated by an offset to "Reference point A" in the unit of the numerology. The *UE transmission bandwidth configuration* is indicated by the higher layer parameter *carrierBandwidth* [13] and will fulfil the minimum UE guardband requirement specified in Section 5.3.3.

## 5.3.5 Channel bandwidth per operating band

The requirements in this specification apply to the combination of channel bandwidths, SCS and operating bands shown in Table 5.3.5-1. The transmission bandwidth configuration in Table 5.3.2-1 shall be supported for each of the specified channel bandwidths. The channel bandwidths are specified for both the Tx and Rx path.

Table 5.3.5-1: Channel bandwidths for each NR band

Operat	ing band	/SCS/U	E channe	el bandwi	dth
Operating band	SCS kHz	50 MHz	100 MHz	200 MHz	400 <sup>1</sup> MHz
n257	60	Yes	Yes	Yes	
11257	120	Yes	Yes	Yes	Yes
n258	60	Yes	Yes	Yes	
11236	120	Yes	Yes	Yes	Yes
n260	60	Yes	Yes	Yes	
11200	120	Yes	Yes	Yes	Yes
2061	60	Yes	Yes	Yes	
n261	120	Yes	Yes	Yes	Yes
NOTE 1: T	his UE ch	annel bar	ndwidth is	optional i	n this

release of the specification.

#### 5.3A UE channel bandwidth for CA

#### 5.3A.1 General

## 5.3A.2 Minimum guardband and transmission bandwidth configuration for CA

For intra-band contiguous carrier aggregation, *Aggregated Channel Bandwidth* and *Guard Bands* are defined as follows, see Figure 5.3A.2-1.

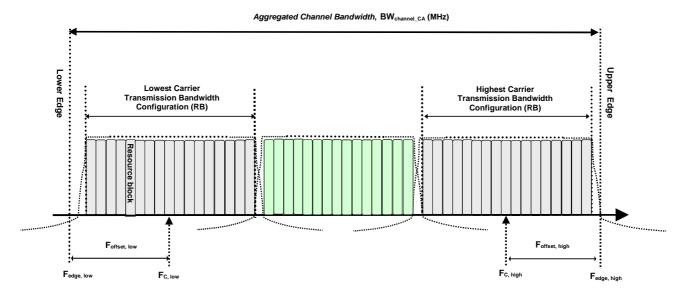


Figure 5.3A.2-1: Definition of Aggregated Channel Bandwidth for intra-band carrier aggregation

The aggregated channel bandwidth, BWChannel\_CA, is defined as

$$BW_{Channel\_CA} = F_{edge,high} - F_{edge,low}$$
 (MHz).

The lower bandwidth edge  $F_{\text{edge, low}}$  and the upper bandwidth edge  $F_{\text{edge, high}}$  of the aggregated channel bandwidth are used as frequency reference points for transmitter and receiver requirements and are defined by

$$F_{edge,low} = F_{C,low} - F_{offset,low}$$

$$F_{edge,high} = F_{C,high} + F_{offset,high} \label{eq:Fedge}$$

The lower and upper frequency offsets depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carrier and are defined as

$$F_{offset,low} = (N_{RB,low}*12 + 1)*SCS_{low}/2 + BW_{GB} (MHz)$$

$$F_{offset,high} = (N_{RB,high}*12 - 1)*SCS_{high}/2 + BW_{GB}(MHz)$$

$$BW_{GB} = max(BW_{GB,Channel(k)})$$

 $BW_{GB,Channel(k)}$  is the minimum guard band defined in sub-clause 5.3.3 of carrier k, while  $N_{RB,low}$  and  $N_{RB,high}$  are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier,  $SCS_{low}$  and  $SCS_{high}$  are the sub-carrier spacing for the lowest and highest assigned component carrier respectively.

For intra-band non-contiguous carrier aggregation *Sub-block Bandwidth* and *Sub-block edges* are defined as follows, see Figure 5.3A.2-2.

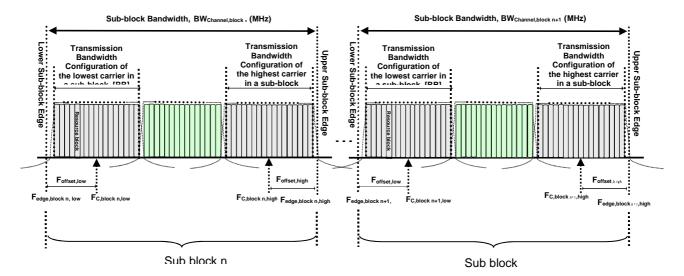


Figure 5.3A.2-2: Definition of sub-block bandwidth for intra-band non-contiguous spectrum

The lower sub-block edge of the Sub-block Bandwidth (BW<sub>Channel,block</sub>) is defined as

$$F_{\text{edge,block, low}} = F_{\text{C,block,low}} - F_{\text{offset, low}}$$

The upper sub-block edge of the Sub-block Bandwidth is defined as

$$F_{\text{edge,block,high}} = F_{\text{C,block,high}} + F_{\text{offset, high.}}$$

The Sub-block Bandwidth, BW<sub>Channel,block</sub>, is defined as follows:

$$BW_{Channel,block} = F_{edge,block,high} - F_{edge,block,low} (MHz)$$

The lower and upper frequency offsets  $F_{offset,block,low}$  and  $F_{offset,block,high}$  depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carriers within a sub-block and are defined as

$$\begin{split} F_{offset,block,low} = & \ (N_{RB,low}*12+1)*SCS_{low}/2 + BW_{GB} \, (MHz) \\ F_{offset,block,high} = & \ (N_{RB,high}*12-1)*SCS_{high}/2 + BW_{GB} \, (MHz) \\ BW_{GB} = & \ max(BW_{GB,Channel(k)}) \end{split}$$

where  $N_{RB,low}$  and  $N_{RB,high}$  are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier within a sub-block, respectively.  $SCS_{low}$  and  $SCS_{high}$  are the sub-carrier spacing for the lowest and highest assigned component carrier within a sub-block, respectively.  $BW_{GB,Channel(k)}$  is the minimum guard band defined in sub-clause 5.3.3 of carrier k within a sub-block.

The sub-block gap size between two consecutive sub-blocks  $W_{\text{gap}}$  is defined as

$$W_{gap} = F_{edge,block \ n+1,low} - F_{edge,block \ n,high} \ (MHz)$$

## 5.3A.3 RB alignment with different numerologies for CA

## 5.3A.4 UE channel bandwidth per operating band for CA

For intra-band contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting a carrier aggregation bandwidth class with associated bandwidth combination sets specified in clause 5.5A.1. For each carrier aggregation configuration, requirements are specified for all aggregated channel bandwidths contained in a bandwidth combination set, UE can indicate support of several bandwidth combination sets per carrier aggregation configuration. The requirements are applicable only when Uplink CCs are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier.

For intra-band non-contiguous downlink carrier aggregation, a carrier aggregation configuration is a single operating band supporting two or more sub-blocks, each supporting a carrier aggregation bandwidth class. The requirements are applicable only when Uplink CCs are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier.

Frequency separation class specified in Table 5.3A.4-2 indicates the maximum frequency span between lower edge of lowest component carrier and upper edge of highest component carrier that UE can support per band in downlink or uplink respectively.

For inter-band carrier aggregation, a carrier aggregation configuration is a combination of operating bands, each supporting a carrier aggregation bandwidth class.

NR CA bandwidth Aggregated channel bandwidth **Number of contiguous** Fallback group class CC BW<sub>Channel</sub> ≤ 400 MHz 1,2,3,4 1 В 400 MHz < BW<sub>Channel\_CA</sub> ≤ 800 MHz 2 1 С 800 MHz < BW<sub>Channel\_CA</sub> ≤ 1200 MHz 3 200 MHz < BW<sub>Channel CA</sub> ≤ 400 MHz D 2 Е 400 MHz < BW<sub>Channel\_CA</sub> ≤ 600 MHz 3 2 F  $600 \text{ MHz} < BW_{Channel\_CA} \le 800 \text{ MHz}$ 4 2 100 MHz < BW<sub>Channel CA</sub> ≤ 200 MHz G Н 200 MHz < BW<sub>Channel\_CA</sub> ≤ 300 MHz 3  $300 \text{ MHz} < BW_{Channel\_CA} \le 400 \text{ MHz}$ 4 400 MHz < BW<sub>Channel\_CA</sub> ≤ 500 MHz 5 3 J 500 MHz < BW<sub>Channel\_CA</sub> ≤ 600 MHz K 6 600 MHz < BW<sub>Channel\_CA</sub> ≤ 700 MHz L 7 700 MHz < BW<sub>Channel CA</sub> ≤ 800 MHz 8 M 0 100 MHz  $\leq$  BW<sub>Channel\_CA</sub>  $\leq$  200 MHz 2 Ρ 150 MHz ≤ BW<sub>Channel\_CA</sub> ≤ 300 MHz 3 4 Q  $200 \text{ MHz} \leq BW_{Channel\_CA} \leq 400 \text{ MHz}$ 4

Table 5.3A.4-1: CA bandwidth classes

NOTE 1: Maximum supported component carrier bandwidths for fallback groups 1, 2, 3 and 4 are 400 MHz, 200 MHz, 100 MHz and 100 MHz respectively.

NOTE 2: It is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration within a fallback group. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group.

 Frequency separation class
 Frequency separation (Fs)

 I
 Fs ≤ 800

 II
 Fs ≤ 1200

 III
 Fs ≤ 1400

Table 5.3A.4-2: Frequency separation classes

## 5.3D Channel bandwidth for UL MIMO

The requirements specified in subclause 5.3 are applicable to UE supporting UL MIMO.

## 5.4 Channel arrangement

## 5.4.1 Channel spacing

#### 5.4.1.1 Channel spacing for adjacent NR carriers

The spacing between carriers will depend on the deployment scenario, the size of the frequency block available and the channel bandwidths. The nominal channel spacing between two adjacent NR carriers is defined as following:

For NR operating bands with 60 kHz channel raster,

Nominal Channel spacing = 
$$(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-20kHz, 0kHz, 20kHz\}$$

where  $BW_{Channel(1)}$  and  $BW_{Channel(2)}$  are the channel bandwidths of the two respective NR carriers. The channel spacing can be adjusted depending on the channel raster to optimize performance in a particular deployment scenario.

#### 5.4.2 Channel raster

#### 5.4.2.1 NR-ARFCN and channel raster

The global frequency raster defines a set of RF reference frequencies  $F_{REF}$ . The RF reference frequency is used in signalling to identify the position of RF channels, SS blocks and other elements.

The global frequency raster is defined for all frequencies from 0 to 100 GHz. The granularity of the global frequency raster is  $\Delta F_{Global}$ .

RF reference frequency is designated by an NR Absolute Radio Frequency Channel Number (NR-ARFCN) in the range [2016667...3279165] on the global frequency raster. The relation between the NR-ARFCN and the RF reference frequency  $F_{REF}$  in MHz is given by the following equation, where  $F_{REF-Offs}$  and  $N_{Ref-Offs}$  are given in table 5.4.2.1-1 and  $N_{REF}$  is the NR-ARFCN

$$F_{REF} = F_{REF\text{-}Offs} + \Delta F_{Global} (N_{REF} - N_{REF\text{-}Offs})$$

Table 5.4.2.1-1: NR-ARFCN parameters for the global frequency raster

Frequency range (MHz)	ΔF <sub>Global</sub> (kHz)	F <sub>REF-Offs</sub> [MHz]	N <sub>REF-Offs</sub>	Range of N <sub>REF</sub>
24250 - 100000	60	24250.08	2016667	2016667 - 3279165

The *channel raster* defines a subset of *RF reference frequencies* that can be used to identify the RF channel position in the uplink and downlink. The *RF reference frequency* for an RF channel maps to a resource element on the carrier. For each operating band, a subset of frequencies from the global frequency raster are applicable for that band and forms a channel raster with a granularity  $\Delta F_{Raster}$ , which may be equal to or larger than  $\Delta F_{Global}$ .

The mapping between the channel raster and corresponding resource element is given in Section 5.4.2.2. The applicable entries for each operating band are defined in subclause 5.4.2.3

#### 5.4.2.2 Channel raster to resource element mapping

The mapping between the RF reference frequency on channel raster and the corresponding resource element is given in Table 5.4.2.2-1 and can be used to identify the RF channel position. The mapping depends on the total number of RBs that are allocated in the channel and applies to both UL and DL. The mapping must apply to at least one numerology supported by the UE.

Table 5.4.2.2-1: Channel raster to resource element mapping

	$N_{RB} \mod 2 = 0$	$N_{RB}$ mod $2 = 1$
Resource element index k	0	6
Physical resource block number n <sub>PRB</sub>	$n_{\text{PRB}} = \left\lfloor \frac{N_{\text{RB}}}{2} \right\rfloor$	$n_{\text{PRB}} = \left\lfloor \frac{N_{\text{RB}}}{2} \right\rfloor$

k,  $n_{RB}$ ,  $N_{RB}$  are as defined in TS 38.211 [9].

#### 5.4.2.3 Channel raster entries for each operating band

The RF channel positions on the channel raster in each NR operating band are given through the applicable NR-ARFCN in Table 5.4.2.3-1, using the channel raster to resource element mapping in subclause 5.4.2.2.

- For NR operating bands with 60 kHz channel raster above 24 GHz,  $\Delta F_{Raster} = I \times \Delta F_{Global}$ , where  $I \in \{1,2\}$ . Every  $I^{th}$  NR-ARFCN within the operating band are applicable for the channel raster within the operating band and the step size for the channel raster in table 5.4.2.3-1 is given as < I >.
- In frequency bands with two  $\Delta F_{Raster}$ , the higher  $\Delta F_{Raster}$  applies to channels using only the SCS that equals the higher  $\Delta F_{Raster}$ .

Uplink and Downlink Operating ΔF<sub>Raster</sub> **Band** (kHz) Range of NREF (First – <Step size> – Last) n257 2054166 - <1> - 2104165 60 2054167 - <2> - 2104165 2016667 - <1> - 2070832 2016667 - <2> - 2070831 120 n258 60 120 2229166 - <1> - 2279165 n260 60

2229167 - <2> - 2279165

2070833 - <1> - 2084999

2070833 - <2> - 2084999

120

60

120

Table 5.4.2.3-1: Applicable NR-ARFCN per operating band

### 5.4.3 Synchronization raster

#### 5.4.3.1 Synchronization raster and numbering

n261

The synchronization raster indicates the frequency positions of the synchronization block that can be used by the UE for system acquisition when explicit signalling of the synchronization block position is not present.

A global synchronization raster is defined for all frequencies. The frequency position of the SS block is defined as  $SS_{REF}$  with corresponding number GSCN. The parameters defining the  $SS_{REF}$  and GSCN for all the frequency ranges are in Table 5.4.3.1-1.

The resource element corresponding to the SS block reference frequency  $SS_{REF}$  is given in subclause 5.4.3.2. The synchronization raster and the subcarrier spacing of the synchronization block is defined separately for each band.

Table 5.4.3.1-1: GSCN parameters for the global frequency raster

Frequency range	SS block frequency position SSREF	GSCN	Range of GSCN
24250 – 100000 MHz	24250.08 MHz + N * 17.28 MHz, N = 0:4383	22256 + N	22256 – 26639

#### 5.4.3.2 Synchronization raster to synchronization block resource element mapping

The mapping between the synchronization raster and the corresponding resource element of the SS block is given in Table 5.4.3.2-1. The mapping depends on the total number of RBs that are allocated in the channel and applies to both UL and DL.

Table 5.4.3.2-1: Synchronization raster to SS block resource element mapping

Resource element index k	0
Physical resource block number n <sub>PRB</sub> of the SS block	<i>n</i> <sub>PRB</sub> = 10

k,  $n_{PRB}$  are as defined in TS 38.211 [9].

#### 5.4.3.3 Synchronization raster entries for each operating band

The synchronization raster for each band is give in Table 5.4.3.3-1. The distance between applicable GSCN entries is given by the <Step size> indicated in Table 5.4.3.3-1.

SS Block SCS **NR Operating Band** SS Block pattern<sup>1</sup> Range of GSCN (First - <Step size> - Last) 22388 - <1> - 22558 120 kHz Case D n257 22390 - <2> - 22556 Case E 240 kHz 22257 - <1> - 22443 120 kHz Case D n258 22258 - <2> - 22442 22995 - <1> - 23166 240 kHz Case E Case D 120 kHz n260 22996 - <2> - 23164 240 kHz Case E 22446 - <1> - 22492 120 kHz Case D n261 Case E 22446 - <2> - 22490 240 kHz SS Block pattern is defined in subclause 4.1 in TS 38.213 [10].

Table 5.4.3.3-1: Applicable SS raster entries per operating band

## 5.4A Channel arrangement for CA

### 5.4A.1 Channel spacing for CA

For intra-band contiguous carrier aggregation with two or more component carriers, the nominal channel spacing between two adjacent NR component carriers is defined as the following unless stated otherwise:

For NR operating bands with 60kHz channel raster:

Nominal channel spacing = 
$$\left[ \frac{BW_{Channel (1)} + BW_{Channel (2)} - 2 \left| GB_{Channel (1)} - GB_{Channel (2)} \right|}{0.06 * 2^{n+1}} \right] 0.06 * 2^{n} [MHz]$$

with

$$n = \mu_0 - 2n$$

where BW<sub>Channel(1)</sub> and BW<sub>Channel(2)</sub> are the channel bandwidths of the two respective NR component carriers according to Table 5.3.2-1 with values in MHz,  $\mu_0$  the largest  $\mu$  value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1, and  $GB_{Channel(i)}$  the minimum guard band for channel bandwidth i according to Table 5.3.3-1 for the said  $\mu$  value, with  $\mu$  as defined in TS 38.211 [9].

The channel spacing for intra-band contiguous carrier aggregation can be adjusted to any multiple of sub-carrier spacing less than the nominal channel spacing to optimize performance in a particular deployment scenario.

For intra-band non-contiguous carrier aggregation, the channel spacing between two NR component carriers in different sub-blocks shall be larger than the nominal channel spacing defined in this subclause.

## 5.5 Configurations

## 5.5A Configurations for CA

## 5.5A.1 Configurations for intra-band contiguous CA

Table 5.5A.1-1: NR CA configurations, bandwidth combination sets, and fallback group defined for intra-band contiguous CA

			NR CA	configuration	n / Bandwidth	combination	set / Fallback	group				
NR CA configuration	Uplink CA configurations	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group
CA_n257B	CA_n257B	50, 100, 200, 400	400							800	0	1
CA_n257D	CA_n257D	50, 100, 200	200							400	0	
CA_n257E	CA_n257E	50, 100, 200	200	200						600	0	2
CA_n257F	CA_n257F	50, 100, 200	200	200	200					800 0 200 0	0	
CA_n257G	CA_n257G	100	100									
CA_n257H	CA_n257H	100	100	100						300	0 0 0 0	
CA_n257I	CA_n257I	100	100	100	100					400		
CA_n257J	CA_n257J	100	100	100	100	100				500		3
CA_n257K	CA_n257K	100	100	100	100	100	100			600		
CA_n257L	CA_n257L	100	100	100	100	100	100	100		700		
CA_n257M	CA_n257M	100	100	100	100	100	100	100	100	800	0	
CA_n260B	CA_n260B	50, 100, 200, 400	400							800	0	4
CA_n260C	CA_n260B	50, 100, 200, 400	400	400						1200	0	<b>1</b>
OA = 000D	OA000D	50, 100, 200	200							400	0	
CA_n260D	CA_n260D	200	50, 100, 200							400	0	
04 0005	040005	50, 100, 200	200	200						600 0	_	2
CA_n260E	CA_n260E	200	200	50, 100, 200								
CA_n260F	CA_n260F	50, 100, 200	200	200	200					800	0	
CA_n260G	CA_n260G	100	50, 100							200	0	3

	T	NR CA configuration / Bandwidth combination set / Fallback group										T		
NR CA configuration	Uplink CA configurations	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group		
		50, 100	100											
CA_n260H	CA_n260H	100	100	50, 100						300	0			
CA_IIZ00II	CA_IIZ00II	50, 100	100	100						300	U			
CA_n260I	CA_n260I	100	100	100	50, 100					400	0			
_		50, 100	100	100	100									
CA_n260J	CA_n260J	100	100	100	100	50, 100				500	0			
CA_n260K	CA_n260K	100	100	100	100	100	50, 100			600	0			
CA_n260L	CA_n260L	100	100	100	100	100	100	50, 100		700	0			
CA_n260M	CA_n260M	100	100	100	100	100	100	100	50, 100					
CA_n260O	CA_n260O	50, 100	50, 100							200	0			
CA_n260P	CA_n260P	50, 100	50, 100	50, 100						300	0	4		
CA_n260Q	CA_n260Q	50, 100	50, 100,	50, 100	50, 100					400	0			
CA_n261B	CA_n261B	50, 100, 200, 400	400							800	0	1		
CA_n261C	CA_n261B	50	400	400						850 <sup>1</sup>	0			
OA = 004D	OA = 004D	50, 100, 200	200							400	400	0		
CA_n261D	CA_n261D -	200	50, 100, 200									0		
CA_n261E	CA_n261E	50, 100, 200	200	200						600	600	600	0	2
OA_IIZOTE	OA_11201L	200	200	50, 100, 200						000	U			
CA_n261F	CA_n261F	50, 100, 200	200	200	200					800	0			
CA_n261G	CA_n261G	100	50, 100							200	0			
OA_112010	0A_112010	50, 100	100							200	U			
CA_n261H	CA_n261H	100	100	50, 100						300	0			
O/ (_1120111	0/\_1120111	50, 100	100	100						300	0			
CA_n261I	CA_n261I	100	100	100	50, 100					400	0	3		
		50, 100	100	100	100									
CA_n261J	CA_n261J	100	100	100	100	50, 100				500 0				
CA_n261K	CA_n261K	100	100	100	100	100	50, 100			600	0			
CA_n261L	CA_n261L	100	100	100	100	100	100	50, 100		700 0				
CA_n261M	CA_n261M	100 50, 100	100 100	100 100	100 100	100 100	100 100	100 100	50, 100 100	800	0			
CA_n261O	CA_n261O	50, 100	50, 100				1.22			200	0			
CA_n261P	CA_n261P	50, 100	50, 100	50, 100					1	300	0	4		
CA_n261Q	CA_n261Q	50, 100	50, 100,	50, 100	50, 100		1			400	0	1 .		
	naximum bandwidtl	,		55, 155	55, 100	1	1	1	1	.00		<u> </u>		

	NR CA configuration / Bandwidth combination set / Fallback group											
NR CA	Uplink CA									Maximum		Fallback
_	- 1	CBW	CBW	CBW	CBW	CBW	CBW	CBW	CBW	aggregated	BCS	
configuration configurations	(MHz)	(MHz)	(MHz)	(MHz)	(MHz)	(MHz)	(MHz)	(MHz)	BW (MHz)		group	
MOTE OF 1	- ND OA				4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	. 600						

NOTE 2: For the NR CA configuration with more than two component carries, the bandwidths in a BCS which may introduce combinations more than requested unintentionally should be listed in a row separately.

## 5.5A.2 Configurations for intra-band non-contiguous CA

Configurations listed in this clause apply to downlink carrier aggregation only.

Table 5.5A.2-1: NR CA configurations with single CA bandwidth class defined for intra-band non-contiguous CA

			NR CA conf	iguration / Ban	dwidth combin	ation set				
	Uplink CA		Compor	nent carriers in	order of increa	asing carrier fro	equency	Maximum		
NR configuration	configuratio	scs	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	aggregated bandwidth (MHz)	BCS	
		60	50, 100, 200	50, 100, 200				400		
CA_n257(2A)	-	120	50, 100, 200, 400	50, 100, 200, 400				800	0	
		60	50, 100, 200	50, 100, 200				400		
CA_n260(2A)	-	120	50, 100, 200, 400	50, 100, 200, 400				800	0	
	60 50	50, 100, 200	50, 100, 200	50, 100, 200			600			
CA_n260(3A) -	-	120	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400			1200	0	
		60	50, 100, 200	50, 100, 200	50, 100, 200	50, 100, 200		800		
CA_n260(4A)	-	120	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400		1600	0	
		60	50, 100, 200	50, 100, 200		·		400		
CA_n261(2A)	-	120	50, 100, 200, 400	50, 100, 200, 400				800	0	
		60	50, 100, 200	50, 100, 200	50, 100, 200			600		
CA_n261(3A) -	-	120	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400			700 <sup>1</sup>	0	
		60	50, 100, 200	50, 100, 200	50, 100, 200	50, 100, 200		700¹	)1	
CA_n261(4A)	-	120	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400	50, 100, 200, 400		700 <sup>1</sup>	0	

NOTE 1: Parameter value accounts for both, the maximum frequency range of band n261 (850 MHz), and the minimum frequency gaps in between non-contiguous component carriers.

NOTE 2: The maximum frequency span including frequency gaps in between non-contiguous component carriers shall not exceed 1400 MHz for all CA configurations in the current release of specifications.

NOTE 3: Parameter value accounts for both, the constraint in NOTE 2, and the minimum frequency gaps in between non-contiguous component carriers.

Table 5.5A.2-2: NR CA configurations and bandwidth combination sets for intra-band non-contiguous CA

		1				dth combination in the combination of the combined in the comb		CV		Maximum	
CA Uplink CA configurations	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	aggregated bandwidth (MHz)	BCS	
	See CA_n260 Channel Bandwidth in Table 5.3.5-1	CA_n260 Channel andwidth in Table  See CA_n260I BCS0 in Table 5.5A.1-1							- 800	0	
CA_n260(A-I)		See C	A_n260I BCS	0 in Table 5.5	A.1-1	See CA_n260 Channel Bandwidth in Table 5.3.5-1				800	U
CA_n260(D-G)	CA_n260D- CA_n260G	See CA_n26 Table 5. See CA_n26 Table 5.	.5A.1-1 0G BCS0 in	Table 5 See CA_n26	60G BCS0 in 5.5A.1-1 60D BCS0 in 5.5A.1-1					600	0
CA_n260(D-H)	CA_n260D CA_n260H-	Table 5.	See CA_n260D BCS0 in Table 5.5A.1-1         See CA_n260H BCS0 in Table 5.5A.1-1           See CA_n260H BCS0 in Table 5.5A.1-1         1           See CA_n260D BCS0 in Table 5.5A.1-1         See CA_n260D BCS0 in Table 5.5A.1-1			700	0				
CA_n260(D-I)	CA_n260D CA_n260I-	Table 5.	See CA_n260D BCS0 in Table 5.5A.1-1         See CA_n260I BCS0 in Table 5.5A.1-1           See CA_n260I BCS0 in Table 5.5A.1-1         See CA_n260D BCS0 in Table 5.5A.1-1				800	0			
CA_n260(D-O)	CA_n260D CA_n260O-	See CA_n26 Table 5. See CA_n26 Table 5.	.5A.1-1 0O BCS0 in	Table 5	5.5A.1-1 60D BCS0 in 5.5A.1-1					600	0
CA_n260(D-P)	CA_n260D CA_n260P-	See CA_n26 Table 5.	0D BCS0 in .5A.1-1	See CA_n26	See CA_n2	Table 5.5A.1-1 60D BCS0 in 5.5A.1-1				700	0
CA_n260(D-Q)	CA_n260D CA_n260Q-	See CA_n26 Table 5. See	.5A.1-1	See 0	CA_n260Q BC	S0 in Table 5.5	5A.1-1 n260D BCS0 e 5.5A.1-1			800	0

						dth combination				T	
•			Com	ponent carrie	ers in order o	f increasing ca	rrier frequen	су		Maximum	
CA configuration	Uplink CA configurations	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	aggregated bandwidth (MHz)	BCS
CA_n260(E-O)	CA_n260E	See CA_n26 Table 5.		See CA_n2		Гable 5.5A.1-1				800	0
CA_11200(E-O)	CA_n260O-	See CA_n260				600 BCS0 in 5.5A.1-1				800	0
CA_n260(E-P)	CA_n260E CA_n260P-	See CA_n260				60P BCS0 in Ta				800 <sup>1</sup>	0
		See CA_n260 See CA_n260				60E BCS0 in Ta CA_n260Q BCS		A 1-1			
CA_n260(E-Q)	CA_n260E CA_n260Q-	See C	A_n260Q BC	S0 in Table 5.			DE BCS0 in Ta			1000	0
CA_n260(G-I)	CA_n260G	See CA_n26 Table 5.		See	CA_n260I BC	S0 in Table 5.5	A.1-1			000	0
_	CA_n260I -	See C	See CA_n260I BCS0 in Table 5.5A.1-1 See CA_n260G BCS0 in Table 5.5A.1-1				600	0			
CA_n261(D-G)	CA_n261D	See CA_n26 Table 5.	.5A.1-1	Table 5	61G BCS0 in 5.5A.1-1					600	0
OA_11201(D-0)	CA_n261G-	See CA_n26 Table 5.	.5A.1-1	Table 5	61D BCS0 in 5.5A.1-1					000	0
CA_n261(D-H)	CA_n261D		See CA_n261D BCS0 in See CA_n261H BCS0 in Table 5.8  Table 5.5A.1-1 1						700	0	
o, (	CA_n261H-	See CA_n261		able 5.5A.1-1		261D BCS0 in 5.5A.1-1					
CA_n261(D-I)	CA_n261D	See CA_n26 Table 5	.5A.1-1		_	S0 in Table 5.5				800	0
	CA_n261I-		_	60 in Table 5.5		See CA_n26 Table 5					
CA =204/D C\	CA_n261D	See CA_n26 Table 5.		Table 5	610 BCS0 in 5.5A.1-1					000	_
CA_n261(D-O)	A_n261(D-O)		10 BCS0 in .5A.1-1		61D BCS0 in 5.5A.1-1					600	0
CA_n261(D-P)	CA_n261D	See CA_n26 Table 5.		See CA_n2		Гable 5.5А.1-1				700	0
5/(_11201(D-1 )	CA_n261P-		See CA_n261P BCS0 in Table 5.5A.1-1 See CA_n261D BCS0 in Table 5.5A.1-1			700					
CA_n261(D-Q)	CA_n261D	See CA_n26 Table 5	.5A.1-1			S0 in Table 5.5				800	0
OA_11201(D-Q)	CA_n261Q-	See C	A_n261Q BCS	30 in Table 5.	5A.1-1	See CA_n26 Table 5					,

	NR CA configuration / Bandwidth combination set										
		Component carriers in order of increasing carrier frequency						Maximum			
CA Uplink CA configurations	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	CBW (MHz)	aggregated bandwidth (MHz)	BCS	
CA =261/E O)	CA_n261E	See CA_n261	See CA_n261E BCS0 in Table 5.5A.1-1		_	2610 BCS0 in 5.5A.1-1				900	0
CA_n261(E-O)	CA_n261O-	See CA_n26 <sup>-</sup> Table 5.		See CA_n26	61E BCS0 in	Table 5.5A.1-1				800	0
CA_n261(E-P)	CA_n261E CA_n261P-	See CA_n261	See CA_n261E BCS0 in Table 5.5A.1-1  See CA_n261P BCS0 in Table 5.5A.1-1		See CA_n2	261P BCS0 in Ta	able 5.5A.1-1			900	0
	0.10	See CA_n261			See CA_n2	261E BCS0 in Ta	Table 5.5A.1-1				
CA_n261(E-Q)		See CA_n261E BCS0 in Table 5.5A.1-1		See CA_n261Q BCS0 in Table 5.5A.1-1				0001	0		
		See CA	e CA_n261Q BCS0 in Table 5.5A.1		A.1-1 See CA_n261E BCS0 in Table 5.5A.1-			8001	0		

NOTE 1: Parameter value accounts for both, the maximum frequency range of band n261 (850 MHz), and a minimum frequency gap in between non-contiguous component carriers.

## 5.5D Configurations for UL MIMO

The requirements specified in subclause 5.5 are applicable to UE supporting UL MIMO.

NOTE 2: The maximum frequency span including the frequency gap in between non-contiguous component carriers shall not exceed 1400 MHz for all CA configurations in the current release of specifications.

#### 6 Transmitter characteristics

#### 6.1 General

Unless otherwise stated, the transmitter characteristics are specified over the air (OTA) with a single or multiple transmit chains

## 6.2 Transmitter power

#### 6.2.1 UE maximum output power

#### 6.2.1.0 General

NOTE: Power class 1, 2, 3, and 4 are specified based on the assumption of certain UE types with specific device architectures. The UE types can be found in Table 6.2.1.0-1.

Table 6.2.1.0-1: Assumption of UE Types

UE Power class	UE type		
1 Fixed wireless access (FWA) UE			
2	Vehicular UE		
3	Handheld UE		
4	High power non-handheld UE		

Power class 3 is default power class.

#### 6.2.1.1 UE maximum output power for power class 1

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.1-1: UE minimum peak EIRP for power class 1

Operating band	Min peak EIRP (dBm)		
n257	40.0		
n258	40.0		
n260	38.0		
n261	40.0		
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance			

The maximum output power values for TRP and EIRP are found in Table 6.2.1.1-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.1-2: UE maximum output power limits for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.1-3 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.1-3: UE spherical coverage for power class 1

Operating band	Min EIRP at 85 %-tile CDF (dBm)
n257	32.0
n258	32.0
n260	30.0
n261	32.0
	EIRP at 85 %-tile CDF is defined as
	limit without tolerance
NOTE 2: The requi	rements in this table are verified only
under nor	mal temperature conditions as
defined in	Annex E.2.1.

#### 6.2.1.2 UE maximum output power for power class 2

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.2-1: UE minimum peak EIRP for power class 2

Operating band	Min peak EIRP (dBm)
n257	29
n258	29
n261	29
NOTE 1: Minimum peak EIRP is	s defined as the lower limit without tolerance

The maximum output power values for TRP and EIRP are found in Table 6.2.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.2-2: UE maximum output power limits for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

The minimum EIRP at the 60<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.2-3 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.2-3: UE spherical coverage for power class 2

Operating band	Min EIRP at 60 %-tile CDF (dBm)		
n257	18.0		
n258	18.0		
n261	18.0		
	Minimum EIRP at 60 %-tile CDF is defined as the lower limit without tolerance		
NOTE 2: The require under norm	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.		

#### 6.2.1.3 UE maximum output power for power class 3

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of total component of EIRP (Link=Beam peak search grids, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-1 and Table 6.2.1.3-4.

Table 6.2.1.3-1: UE minimum peak EIRP for power class 3

Operating band	Min peak EIRP (dBm)			
n257	22.4			
n258	22.4			
n260	20.6			
n261	22.4			
NOTE 1: Minimum p	peak EIRP is defined as the			
lower limit without tolerance				

The maximum output power values for TRP and EIRP are found on the Table 6.2.1.3-2. The max allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and the total component of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.3-2: UE maximum output power limits for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.3-3 below. The requirement is verified with the test metric of the total component of EIRP (Link=Beam peak search grids, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-3. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-3 and Table 6.2.1.3-4.

Table 6.2.1.3-3: UE spherical coverage for power class 3

Operating band	Min EIRP at 50 %-tile CDF (dBm)
n257	11.5
n258	11.5
n260	8
n261	11.5

NOTE 1: Minimum EIRP at 50 %-tile CDF is defined as the

lower limit without tolerance

NOTE 2: Void

NOTE 3: The requirements in this table are verified only under normal temperature conditions as defined in Annex

E.2.1.

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.3-1 and 6.2.1.3-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter  $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter  $\Delta MB_{S,n}$ . For each combination of supported bands  $\Delta MB_{P,n}$  and  $\Delta MB_{S,n}$  apply to each supported band n, such that the total relaxations,  $\sum MB_P$  and  $\sum MB_S$ , across all supported bands shall not exceed the total value indicated in Table 6.2.1.3-4.

Table 6.2.1.3-4: UE multi-band relaxation factors for power class 3

Supported bands	∑MB <sub>P</sub> (dB)	∑MB <sub>S</sub> (dB)
n257, n258	≤ 1.3	≤ 1.25
n257, n260	≤ 1.0	≤ 0.75 <sup>3</sup>
n258, n260	<u> </u>	≥ 0.75
n257, n261	0.0	0.0
n258, n261	≤ 1.0	≤ 1.25
n260, n261	0.0	≤ 0.75 <sup>2</sup>
n257, n258, n260	≤ 1.7	≤ 1.75 <sup>3</sup>
n257, n258, n261		
n257, n258, n260, n261		
n257, n260, n261	≤ 0.5	≤ 1.25 <sup>3</sup>
n258, n260, n261	≤ 1.5	≤ 1.25 <sup>3</sup>

NOTE 1: The requirements in this table are applicable to UEs which support only the indicated bands

NOTE 2: For supported bands n260 + n261,  $\Delta MB_{S,n}$  is not applied for band n260

NOTE 3: For n260, maximum applicable  $\Delta MB_{S,n}$  is 0.4 dB

## 6.2.1.4 UE maximum output power for power class 4

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.4-1: UE minimum peak EIRP for power class 4

Operating band	Min peak EIRP (dBm)
n257	34
n258	34
n260	31
n261	34
NOTE 4 NO :	1 EIDD: 1 (1 1 1

NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance

The maximum output power values for TRP and EIRP are found in Table 6.2.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.4-2: UE maximum output power limits for power class 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

The minimum EIRP at the 20<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.4-3 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2.1.4-3: UE spherical coverage for power class 4

Operating band	Min EIRP at 20 %-tile CDF (dBm)	
n257	25	
n258	25	
n260	19	
n261	25	
NOTE 1: Minimum	EIRP at 20 %-tile CDF is defined as	
the lower limit without tolerance		
NOTE 2: The requirements in this table are verified only		
under normal temperature conditions as		
defined in Annex E.2.1.		

## 6.2.2 UE maximum output power reduction

#### 6.2.2.0 General

The requirements in section 6.2.2 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. A UE may reduce its maximum output power due to modulation orders, transmit bandwidth configurations, waveform types and narrow allocations. This Maximum Power Reduction (MPR) is defined in subclauses below. When the maximum output power of a UE is modified by MPR, the power limits specified in subclause 6.2.4 apply.

For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in section 6.2A.2 apply.

For all power classes, the waveform defined by BW = 100 MHz, SCS = 120 kHz, DFT-S-OFDM QPSK, 20RB23 is the reference waveform with 0 dB MPR and is used for the power class definition.

## 6.2.2.1 UE maximum output power reduction for power class 1

For power class 1, MPR for contiguous allocations is defined as:

 $MPR = max(MPR_{WT}, MPR_{narrow})$ 

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$ , when  $BW_{alloc,RB}$  is less than or equal to 1.44 MHz,  $MPR_{narrow} = 10 \text{ dB}$ , when 1.44 MHz <  $BW_{alloc,RB} \le 10.8 \text{ MHz}$ , where  $BW_{alloc,RB}$  is the bandwidth of the RB allocation size.

 $MPR_{WT}$  is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in table 5.3.2-1, and waveform types.  $MPR_{WT}$  is defined in Tables 6.2.2.1-1 and 6.2.2.1-2.

Table 6.2.2.1-1 MPR<sub>WT</sub> for power class 1, BW<sub>channel</sub> ≤ 200 MHz

		MPR <sub>WT</sub> (dB), BW <sub>channel</sub> ≤ 200 MHz		
Modul	ation	Outer RB allocations	Inner RB a	allocations
			Region 1	Region 2
	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0
DFT-s-OFDM	QPSK	≤ 6.5	0.0	≤ 3.0
DE 1-2-OLDINI	16 QAM	≤ 6.5	≤ 4.0	≤ 4.0
	64 QAM	≤ 6.5	≤ 5.0	≤ 5.0
	QPSK	≤ 7.0	≤ 4.5	≤ 4.5
CP-OFDM	16 QAM	≤ 7.0	≤ 5.5	≤ 5.5
	64 QAM	≤ 7.5	≤ 7.5	≤ 7.5

≤ 9.0

MPRwT (dB), BWchannel = 400 MHz Outer RB allocations Inner RB allocations Modulation Region 1 Region 2 Pi/2 BPSK ≤ 5.5 0.0 ≤ 3.0 **QPSK** ≤ 6.5 0.0 ≤ 3.5 DFT-s-OFDM 16 QAM ≤ 4.5 ≤ 4.5 ≤ 6.5 64 QAM ≤ 6.5 ≤ 6.5 ≤ 6.5 QPSK ≤ 7.0 ≤ 5.0 ≤ 5.0 **CP-OFDM 16 QAM** ≤ 7.0 ≤ 6.5 ≤ 6.5

≤ 9.0

Table 6.2.2.1-2 MPR<sub>WT</sub> for power class 1, BW<sub>channel</sub> = 400 MHz

Where the following parameters are defined to specify valid RB allocation ranges for the RB allocations regions in Tables 6.2.2.1-1 and 6.2.2.1-2:

≤ 9.0

N<sub>RB</sub> is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

 $RB_{Start,Low} = Max(1, Floor(L_{CRB}/2))$ 

$$RB_{Start,High}\!=N_{RB}-RB_{Start,Low}-L_{CRB}$$

An RB allocation is an Outer RB allocation if

64 QAM

$$RB_{Start} < RB_{Start,Low} \; OR \; RB_{Start} > RB_{Start,High} \; OR \; L_{CRB} > Ceil(N_{RB}/2)$$

An RB allocation belonging to table 6.2.2.1-1 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/3 N_{RB}) AND RB_{end} < Ceil(2/3 N_{RB})$$

An RB allocation belonging to table 6.2.2.1-2 is a Region 1 inner RB allocation if

$$[RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})]$$

An RB allocation is a Region 2 inner allocation if it is NOT an Outer allocation AND NOT a Region 1 inner allocation For the UE maximum output power modified by MPR, the power limits specified in subclause 6.2.4 apply.

#### 6.2.2.2 UE maximum output power reduction for power class 2

For power class 2, MPR specified in subclause 6.2.2.3 applies.

#### Table 6.2.2.2-1: Void

## 6.2.2.3 UE maximum output power reduction for power class 3

For power class 3, MPR for contiguous allocations is defined as:

$$MPR = max(MPR_{WT}, MPR_{narrow})$$

Where,

 $MPR_{narrow} = 2.5 \text{ dB}$ , when the allocated RB size is less than or equal to 1.44 MHz, and  $0 \le RB_{start} < Ceil(1/3 N_{RB})$  or  $Ceil(2/3N_{RB}) \le RB_{start} \le N_{RB}$ -L<sub>CRB</sub>, where  $N_{RB}$  is the maximum transmission bandwidth configuration defined in Table 5.3.2-1.

 $MPR_{WT}$  is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types.  $MPR_{WT}$  is defined in Table 6.2.2.3-1 and Table 6.2.2.3-2.

Table 6.2.2.3-1 MPR<sub>WT</sub> for power class 3, BWchannel ≤ 200 MHz

		MPR <sub>WT</sub> , BW <sub>channel</sub> ≤ 200 MHz		
Modula	tion	Inner RB allocations, Region 1	Edge RB allocations	
	Pi/2 BPSK	0.0	≤ 2.0	
DFT-s-OFDM	QPSK	0.0	≤ 2.0	
DF1-8-0FDIVI	16 QAM	≤ 3.0	≤ 3.5	
	64 QAM	≤ 5.0	≤ 5.5	
	QPSK	≤ 3.5	≤ 4.0	
CP-OFDM	16 QAM	≤ 5.0	≤ 5.0	
	64 QAM	≤ 7.5	≤ 7.5	

Table 6.2.2.3-2 MPR<sub>WT</sub> for power class 3, BW<sub>channel</sub> = 400 MHz

		MPRwt, BWchannel = 400 MHz		
Modula	tion	Inner RB allocations, Region 1	Edge RB allocations	
	Pi/2 BPSK	0.0	≤ 3.0	
DFT-s-OFDM	QPSK	0.0	≤ 3.0	
DF1-8-OFDIVI	16 QAM	≤ 4.5	≤ 4.5	
	64 QAM	≤ 6.5	≤ 6.5	
	QPSK	≤ 5.0	≤ 5.0	
CP-OFDM	16 QAM	≤ 6.5	≤ 6.5	
	64 QAM	≤ 9.0	≤ 9.0	

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Tables 6.2.2.3-1 and 6.2.2.3-2:

N<sub>RB</sub> is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

An RB allocation belonging to table 6.2.2.3-1 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/3 N_{RB}) AND RB_{end} < Ceil(2/3 N_{RB})$$

An RB allocation belonging to table 6.2.2.3-2 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})$$

An RB allocation is an Edge allocation if it is NOT a Region 1 inner allocation

#### 6.2.2.4 UE maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2.2.3 applies.

Table 6.2.2.4-1: Void

## 6.2.3 UE maximum output power with additional requirements

#### 6.2.3.1 General

Additional emission requirements can be signalled by the network. Each additional emission requirement is associated with a unique network signalling (NS) value indicated in RRC signalling by an NR frequency band number of the applicable operating band and an associated value in the field additional Spectrum Emission. Throughout this specification, the notion of indication or signalling of an NS value refers to the corresponding indication of an NR frequency band number of the applicable operating band (the IE field freqBandIndicatorNR) and an associated value of additional Spectrum Emission in the relevant RRC information elements

To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in section 6.2.1. Unless stated otherwise, an A-MPR of 0 dB shall be used.

Table 6.2.3.1-1 specifies the additional requirements with their associated network signalling values and the allowed A-MPR and applicable operating band(s) for each NS value. The mapping of NR frequency band numbers and values of and the *additionalSpectrumEmission* to network signalling labels is specified in Table 6.2.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in subclause 6.2.2.

Table 6.2.3.1-1: Additional maximum power reduction (A-MPR)

Network Signalling label	Requirements (subclause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (N <sub>RB</sub> )	A-MPR (dB)
NS_200					N/A
NS_201	6.5.3.2.2	n258			6.2.3.2

Table 6.2.3.1-2: Mapping of Network Signaling label

Value of additionalSpectrumEmission							
0	1	2	3	4	5	6	7
NS_200							
NS_200	NS_201						
NS_200							
NS_200							
	NS_200 NS_200 NS_200	NS_200 NS_200 NS_201 NS_200	0 1 2 NS_200 NS_200 NS_201 NS_200	0 1 2 3 NS_200 NS_200 NS_201 NS_200	0 1 2 3 4  NS_200  NS_200 NS_201  NS_200	0 1 2 3 4 5  NS_200  NS_200 NS_201  NS_200	0 1 2 3 4 5 6  NS_200  NS_200 NS_201  NS_200

NOTE: additionalSpectrumEmission corresponds to an information element of the same name defined in sub-clause 6.3.2 of TS 38.331 [13].

#### 6.2.3.2 A-MPR for NS\_201

## 6.2.3.2.1 A-MPR for NS\_201 for power class 1

Table 6.2.3.2.1-1: AMPR for NS\_201 for power class 1

	Char	nnel Bandwidth,	MHz
Offset Frequency	50, 100, 200	40	00
	Outer	Outer	Inner
0 MHz	3.0	5.0	3.5
> 100 MHz, ≤ 300 MHz	1.5	2.5	3.5
> 300 MHz	0	0	0

NOTE 1: The Offset frequency is defined as the frequency from the lower band edge to the lower channel edge.

NOTE 2: The back off applied is the max(MPR, AMPR), where the MPR is defined in Table 6.2.2.1-1

NOTE 3: Any undefined region, MPR applies

### 6.2.3.2.2 A-MPR for NS\_201 for power class 2

For power class 2, A-MPR specified in subclause 6.2.3.2.3 applies

Table 6.2.3.2.2-1: (Void)

#### 6.2.3.2.3 A-MPR for NS\_201 for power class 3

Table 6.2.3.2.3-1: AMPR for NS\_201 for power class 3

Channel Bandwidth, MHz			
400			
Outer RB allocations			
≤ 1.5			
0			
0			

NOTE 1: The Offset frequency is defined as the frequency from the lower band edge to the lower channel edge.

NOTE 2: The back off applied is the max(MPR, AMPR), where the MPR is defined in Table 6.2.2.3-1

NOTE 3: Any undefined region, MPR applies

# 6.2.4 Configured transmitted power

The UE can configure its maximum output power. The configured UE maximum output power  $P_{CMAX,f,c}$  for carrier f of a serving cell c is defined as that available to the reference point of a given transmitter branch that corresponds to the reference point of the higher-layer filtered RSRP measurement as specified in TS 38.215 [11].

The configured UE maximum output power  $P_{CMAX,f,c}$  for carrier f of a serving cell c shall be set such that the corresponding measured peak EIRP  $P_{UMAX,f,c}$  is within the following bounds

$$\begin{aligned} P_{Powerclass} - MAX(MAX(MPR_{f,c}, \text{ A- MPR}_{f,c})) + \Delta MB_{P,n}, P-MPR_{f,c}) - MAX\{T(MAX(MPR_{f,c}, \text{ A- MPR}_{f,c})), T(P-MPR_{f,c})\} \\ < P_{UMAX,f,c} < EIRP_{max} \end{aligned}$$

while the corresponding measured total radiated power P<sub>TMAX,f,c</sub> is bounded by

$$P_{TMAX,f,c} \leq TRP_{max}$$

with  $P_{Powerclass}$  the UE power class as specified in sub-clause 6.2.1, EIRP $_{max}$  the applicable maximum EIRP as specified in sub-clause 6.2.1, MPR $_{f,c}$  as specified in sub-clause 6.2.3,  $\Delta MB_{P,n}$  the peak EIRP relaxation as specified in section 6.2.1 and TRP $_{max}$  the maximum TRP for the UE power class as specified in sub-clause 6.2.1.

maxUplinkDutyCycle-FR2 as defined in TS 38.306 [14] is the UEcapability to facilitate to electromagnetic power density exposure requirements .

If the field of UE capability *maxUplinkDutyCycle-FR2* is present and the percentage of uplink symbols transmitted within any 1 s evaluation period is larger than maxUplinkDutyCycle-FR2, the UE follows the uplink scheduling and can apply P-MPR<sub>f.c</sub>.

If the field of UE capability *maxUplinkDutyCycle-FR2* is absent, the compliance to electromagnetic power density exposure requirements are ensured by means of scaling down the power density or by other means.

 $P ext{-MPR}_{f,c}$  is the allowed maximum output power reduction. The UE shall apply  $P ext{-MPR}_{f,c}$  for carrier f of serving cell c only for the cases described below. For UE conformance testing  $P ext{-MPR}_{f,c}$  shall be 0 dB.

- a) ensuring compliance with applicable electromagnetic power density exposure requirements and addressing unwanted emissions / self desense requirements in case of simultaneous transmissions on multiple RAT(s) for scenarios not in scope of 3GPP RAN specifications;
- b) ensuring compliance with applicable electromagnetic power density exposure requirements in case of proximity detection is used to address such requirements that require a lower maximum output power.
- NOTE 1: P-MPR<sub>f,c</sub> was introduced in the P<sub>CMAX,f,c</sub> equation such that the UE can report to the gNB the available maximum output transmit power. This information can be used by the gNB for scheduling decisions.
- NOTE 2: P-MPR<sub>f,c</sub> and *maxUplinkDutyCycle-FR2* may impact the maximum uplink performance for the selected UL transmission path.

The tolerance  $T(\Delta P)$  for applicable values of  $\Delta P$  (values in dB) is specified in Table 6.2.4-1.

Table 6.2.4-1: P<sub>UMAX,f,c</sub> tolerance

Operating Band	∆ <b>P (dB)</b>	Tolerance T(∆P) (dB)		
	$\Delta P = 0$	0		
	$0 < \Delta P \le 2$	[1.5]		
	2 < ΔP ≤ 3	[2.0]		
n257, n258, n260,	3 < ΔP ≤ 4	[3.0]		
n261	4 < ΔP ≤ 5	[4.0]		
	5 < ΔP ≤ 10	[5.0]		
	10 < ΔP ≤ 15	[7.0]		
$15 < \Delta P ≤ X$ [8.0]				
NOTE: X is the value such that P <sub>umax,f,c</sub> lower bound, P <sub>Powerclass</sub> -				
$\Delta P - T(\Delta P) = minimum output power specified in$				
subclause 6.3.1				

# 6.2A Transmitter power for CA

## 6.2A.1 UE maximum output power for CA

For downlink intra-band contiguous and non-contiguous carrier aggregation with a single uplink component carrier configured in the NR band, the maximum output power is specified in section 6.2.1.

For uplink intra-band contiguous carrier aggregation for any CA bandwidth class, the maximum output power is specified in section 6.2.1.

Power class 3 is default power class.

# 6.2A.2 UE maximum output power reduction for CA

#### 6.2A.2.1 General

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA. In CA operation, the UE may reduce its maximum output power due to higher order modulations and transmit bandwidth configurations. This Maximum Power Reduction (MPR) is defined in subclauses below.

The cumulative aggregated channel bandwidth is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs. When the maximum output power of a UE is modified by MPR, the power limits specified in subclause 6.2A.4 apply.

The requirements in the following subclauses are only applicable to intra-band contiguous uplink CA, with the aggregated channelbandwidth up to 800 MHz.

#### 6.2A.2.2 Maximum output power reduction for power class 1

For power class 1, MPR for UL contiguous allocations within the cumulative aggregated bandwidth is defined as:

$$MPR_{C\_CA} = max(MPR_{WT\_C\_CA}, MPR_{narrow})$$

Where,

MPR<sub>narrow</sub> = 14.4 dB, when  $BW_{alloc,RB}$  is less than or equal to 1.44 MHz, MPR<sub>narrow</sub> = 10 dB, when 1.44 MHz <  $BW_{alloc,RB} \le 10.8$  MHz, where  $BW_{alloc,RB}$  is the bandwidth of the RB allocation size.

 $MPR_{WT\_C\_CA}$  is the maximum power reduction due to modulation orders, transmit bandwidth configurations, and waveform types.  $MPR_{WT\_contiguous}$  is defined in Table 6.2A.2.2-1.

Table 6.2A.2.2-1: Maximum power reduction (MPR<sub>WT\_C\_CA</sub>) for UE power class 1

Waveform Type		Cumulative aggregated channel bandwidth			
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	
	Pi/2 BPSK	≤ 5.5 <sup>1</sup>	7.7 <sup>1</sup>	[8.2]	
DFT-s-OFDM	QPSK	≤ 6.5 <sup>1</sup>	8.7 <sup>1</sup>	[9.7]	
DFT-S-OFDIVI	16 QAM	≤ 6.5	8.7	[9.2]	
	64 QAM	≤ 9.0	10.7	[11.2]	
	QPSK	≤ 6.5	8.7	[8.7]	
CP-OFDM	16 QAM	≤ 6.5	8.7	[8.7]	
	64 QAM	≤ 9.0	10.7	[11.2]	

NOTE 1: The following condition applies only when the cumulative aggregated BW of the CA configuration ≤ 400MHz. For a contiguous RB allocation in a single CC of the CA configuration, the single CC MPR of subclause 6.2.2.1 applies. The cumulative aggregated bandwidth shall be used as BW<sub>channel</sub> in Tables 6.2.2.1-1 and 6.2.2.1-2 shall be determined based on the transmission bandwidth of the CA allocation in relation to the allocation regions defined in the tables.

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest  $MPR_{C\_CA}$ .

For non-contiguous RB allocations, the following rule for MPR applies:

$$MPR = max(MPR_{C\_CA}, -10*A + [14.4])$$

#### Where:

 $A = N_{RB \text{ alloc}} / N_{RB \text{ agg C}}$ .

 $N_{RB\ alloc}$  is the total number of allocated UL RBs

 $N_{RB\_agg\_C}$  is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth

#### 6.2A.2.3 Maximum output power reduction for power class 2

For power class 2, MPR specified in sub-clause 6.2A.2.4 applies.

Table 6.2A.2.3-1: (Void)

## 6.2A.2.4 Maximum output power reduction for power class 3

For power class 3, MPR for UL contiguous allocations within the cumulative aggregated bandwidth is denoted as  $MPR_{CCA}$  and is defined in Table 6.2A.2.4-1.

Table 6.2A.2.4-1: Maximum power reduction (MPR<sub>C\_CA</sub>) for UE power class 3

		Cumulative aggregated bandwidth configuration		
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz
	Pi/2 BPSK	≤ 5.0 <sup>1</sup>	≤ 7.7 <sup>1</sup>	≤ [8.2]
DFT-s-OFDM	QPSK	≤ 5.0 <sup>1</sup>	≤ 7.7 <sup>1</sup>	≤ [8.2]
DF1-S-OFDIVI	16 QAM	≤ 6.5	≤ 8.7	≤ [9.3]
	64 QAM	≤ 9.0	≤ 10.7	≤ [11.2]
	QPSK	≤ 5.0	≤ 7.5	≤ [8.0]
CP-OFDM	16 QAM	≤ 6.5	≤ 8.7	≤ [9.2]
	64 QAM	≤ 9.0	≤ 10.7	≤ [11.2]

NOTE 1: The following condition applies only when the cumulative aggregated BW of the CA configuration ≤ 400 MHz. For a contiguous RB allocation in a single CC of the CA configuration, the single CC MPR of subclause 6.2.2.1 applies. The cumulative aggregated bandwidth shall be used as BW<sub>channel</sub> in Tables 6.2.2.1-1 and 6.2.2.1-2. The applicable column in Tables 6.2.2.1-1 and 6.2.2.1-2 shall be determined based on the transmission bandwidth of the CA allocation in relation to the allocation regions defined in the tables.

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the highest contiguous MPR.

For non-contiguous RB allocations, the following rule for MPR applies:

 $MPR = max(MPR_{C CA}, -10*A +7.0)$ 

Where:

 $A = N_{RB \text{ alloc}} / N_{RB \text{ agg C}}$ 

 $N_{RB\ alloc}$  is the total number of allocated UL RBs

N<sub>RB agg C</sub> is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth

#### 6.2A.2.5 Maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2A.2.4 applies.

## 6.2A.3 UE maximum output power with additional requirements for CA

#### 6.2A.3.1 General

Additional emission requirements can be signalled by the network with network signalling value indicated by the field *additionalSpectrumEmission*. To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in section 6.2A.1. Unless stated otherwise, an A-MPR of 0 dB shall be used.

For intra-band contiguous aggregation with the UE configured for transmissions on two serving cells, the maximum output power reduction specified in Table 6.2A.3.1-1 is allowed for all serving cells of the applicable uplink contiguous CA configurations according to the CA network signalling value indicated by the field *additionalSpectrumEmissionSCell*.

Table 6.2A.3.1-1 specifies the additional requirements and allowed A-MPR with corresponding network signalling label and operating band. The mapping between network signalling labels and the *additionalSpectrumEmission* IE defined in TS 38.331 [13] is specified in Table 6.2A.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in subclause 6.2A.2.

Table 6.2A.3.1-1: Additional maximum power reduction (A-MPR)

Network Signalling value	Requirements (subclause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (N <sub>RB</sub> )	A-MPR (dB)
CA_NS_200					N/A
CA_NS_201	6.5.3.2.2	n258			6.2A.3.2

Table 6.2A.3.1-2: Value of additionalSpectrumEmission

NR Band	Value of additionalSpectrumEmission / NS number							
	0	1	2	3	4	5	6	7
n257	CA_NS_200							
n258	CA_NS_200	CA_NS_201						
n260	CA_NS_200							
n261	CA_NS_200							

NOTE: additionalSpectrumEmission corresponds to an information element of the same name defined in clause 6.3.2 of TS 38.331 [13].

#### 6.2A.3.2 A-MPR for CA\_NS\_201

#### 6.2A.3.2.1 A-MPR for CA\_NS\_201 for power class 1

For intra-band contiguous CA, AMPR is specified as follows.

Table 6.2A.3.2.1-1: Contiguous Allocations, AMPR<sub>C CA</sub> for CA\_NS\_201 for power class 1

	Cumulative Aggregated Bandwidth, MHz		
Offset Frequency	< 400	≥ 400, ≤ 800	
0 MHz	5.0	7.0	
> 100 MHz, ≤ 300 MHz	3.5	4.0	
> 300 MHz	0	0	

NOTE 1: The Offset frequency is defined as the frequency from the lower band edge to the lower channel edge.

NOTE 2: The back off applied is the max(MPR, AMPR), where the MPR is defined in Table 6.2A.2.2-1.

NOTE 3: Any undefined region, MPR applies.

For power class 1 CA non-contiguous RB allocations, the following rule for AMPR applies:

 $AMPR = max(AMPR_{C\_CA}, -10*A + 9.0)$ , Offset Frequency  $\leq 550 \text{ MHz}$ 

#### 6.2A.3.2.2 A-MPR for CA\_NS\_201 for power class 2

For intra-band contiguous CA, A-MPR specified in sub-clause 6.2A.3.2.3 applies.

Table 6.2A.3.2.2-1: (Void)

#### 6.2A.3.2.3 A-MPR for CA\_NS\_201 for power class 3

For intra-band contiguous CA, AMPR is specified as follows.

Table 6.2A.3.2.3-1: Contiguous Allocations, AMPR<sub>C\_CA</sub> for CA\_NS\_201 for power class 3

	Cumulative Aggregated Bandwidth, MHz		
Offset Frequency	< 400	≥ 400, ≤ 800	
0 MHz	≤ 1.5	≤ 3.0	
> 100 MHz, ≤ 300 MHz	0	0	
> 300 MHz	0	0	

NOTE 1: The Offset frequency is defined as the frequency from the lower band edge to the lower channel edge.

NOTE 2: The back off applied is the max(MPR, AMPR), where the MPR is defined in Table 6.2A.2.4-1.

NOTE 3: Any undefined region, MPR applies.

For power class 3 CA non-contiguous RB allocations, the following rule for AMPR applies:

 $AMPR = max(AMPR_{C\_CA},$  -  $10^*A + 5.0)$  , Offset Frequency  $\leq 550~MHz$ 

## 6.2A.4 Configured transmitted power for CA

A UE configured with carrier aggregation can configure its maximum output power for each uplink carrier f of activated serving cell c and its total configured output power  $P_{CMAX}$ . The definition of the configured UE maximum output power  $P_{CMAX,f,c}$  for each carrier f of a serving cell c is used for power headroom reporting for carrier f of serving cell c only and is in accordance with that specified in clause 6.2.4 with parameters MPR, A-MPR and P-MPR replaced with those specified below. The total configured power  $P_{CMAX}$  in a transmission occasion is the sum of the configured power for carrier f of serving cell c with non-zero granted transmission power in the respective reference point.

For uplink intra-band contiguous carrier aggregation, MPR is specified in subclause 6.2A.2. P<sub>CMAX</sub> is calculated under the assumption that power spectral density for each RB in each component carrier is same.

The total configured UE maximum output power  $P_{CMAX}$  shall be set such that the corresponding measured total peak EIRP  $P_{UMAX}$  is within the following bounds

 $P_{Powerclass} - MAX(MAX(MPR, A\_MPR), P-MPR) - MAX\{T(MAX(MPR, A\_MPR)), T(P-MPR)\} \leq P_{UMAX} \leq EIRP_{max} + P_{UMAX} + P$ 

with  $P_{Powerclass}$  the UE power class as specified in sub-clause 6.2A.1, EIRP<sub>max</sub> the applicable maximum EIRP as specified in sub-clause 6.2A.1, MPR as specified in sub-clause 6.2A.2, A-MPR as specified in sub-clause 6.2A.3, P-MPR the power management term for the UE as described in 6.2.4 and TRP<sub>max</sub> the maximum TRP for the UE power class as specified in sub-clause 6.2A.1.

 $P_{UMAX} \text{ is defined as } 10*log10(\sum p_{UMAX,fli),c(j)}) \text{ for each carrier } f \text{ } (i=1\dots n) \text{ and serving cell } c \text{ } (j=1\dots m) \text{ where } p_{UMAX,fli),c(j)} \text{ is linear value of } P_{UMAX,fli),c(j)}$ 

The tolerance  $T(\Delta P)$  for applicable values of  $\Delta P$  (values in dB) is specified in Table 6.2A.4-1.

Tolerance T(∆P) **Operating Band**  $\Delta P (dB)$ (dB)  $\Delta P = 0$ 0 [1.5] $0 < \Delta P \le 2$  $2 < \Delta P \le 3$ [2.0]n257, n258, n260,  $3 < \Delta P \le 4$ [3.0] n261  $4 < \Delta P \le 5$ [4.0] $5 < \Delta P \le 10$ [5.0]10 < ΔP ≤ 15 [7.0] $15 < \Delta P \le X$ [8.0]

Table 6.2A.4-1: Pumax tolerance

NOTE: X is the value such that  $P_{umax}$  lower bound,  $P_{Powerclass}$  -  $\Delta P$ -  $T(\Delta P)$  = minimum output power specified in subclause
6.3A.1

# 6.2D Transmitter power for UL MIMO

# 6.2D.1 UE maximum output power for UL MIMO

#### 6.2D.1.1 UE maximum output power for UL MIMO for power class 1

The following requirements define the maximum output power radiated by the UE with UL MIMO for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. Requirements in Table 6.2D.1.1-1 shall be met with the UE configured for 2 layer UL MIMO transmission as specified in Table 6.2D.1.1-2. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle). Power class 1 UE is used for fixed wireless access (FWA).

Table 6.2D.1.1-1: UE minimum peak EIRP for UL MIMO for power class 1

Operating band	Min peak EIRP (dBm)	
n257	40.0	
n258	40.0	
n260	38.0	
n261	40.0	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerand		

Table 6.2D.1.1-2: UL MIMO configuration

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.1-3 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.1-3: UE maximum output power limits for UL MIMO for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE with UL MIMO is defined as the spherical coverage requirement and is found in Table 6.2D.1.1-4 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.1-4: UE spherical coverage for UL MIMO for power class 1

Operating band	Min EIRP at 85 %-tile CDF (dBm)		
n257	32.0		
n258	32.0		
n260	30.0		
n261	32.0		
NOTE 1: Minimum E	EIRP at 85 %-tile CDF is defined as		
the lower limit without tolerance			

## 6.2D.1.2 UE maximum output power for UL MIMO for power class 2

The following requirements define the maximum output power radiated by the UE with UL MIMO for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. Requirements in Table 6.2D.1.2-1 shall be met with the UE configured for 2 layer UL MIMO transmission specified in Table 6.2D.1.2-3. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.2-1: UE minimum peak EIRP for UL MIMO for power class 2

Operating band		Min peak EIRP (dBm)	
n257		29	
n258		29	
n261		29	
NOTE 1:	Minimum p	peak EIRP is defined as the	
	lower limit without tolerance.		
NOTE 2:	Min Peak B	EIRP refers to the total EIRP	
	for the UL	beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.2-2: UE maximum output power limits for UL MIMO for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

Table 6.2D.1.2-3: UL MIMO configuration

Transmission scheme	Transmission scheme DCI format TPMI Index	
Codebook based uplink	DCI format 0_1	0

The minimum EIRP at the 60<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.2-4 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.2-4: UE spherical coverage for UL MIMO for power class 2

Operating band	Min EIRP at 60 %-tile CDF (dBm)	
n257	18.0	
n258	18.0	
n261	18.0	
NOTE 1: Minimum EIRP at 60 %-tile CDF is defined as		
the lower limit without tolerance		

#### 6.2D.1.3 UE maximum output power for UL MIMO for power class 3

The following requirements define the maximum output power radiated by the UE with UL MIMO for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. Requirements in Table 6.2D.1.3-1 shall be met with the UE configured for 2 layer UL MIMO transmission specified in Table 6.2D.1.3-3. The period of measurement shall be at least one sub frame (1 ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.3-1: UE minimum peak EIRP for UL MIMO for power class 3

Operating band	Min peak EIRP (dBm)
n257	22.4
n258	22.4
n260	20.6
n261	22.4
NOTE 1: Minimum peak Elf tolerance.	RP is defined as the lower limit without
NOTE 2: Min Peak EIRP re peaks.	fers to the total EIRP for the UL beams

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.3-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.3-2: UE maximum output power limits for UL MIMO for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

Table 6.2D.1.3-3: UL MIMO configuration

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0

The minimum EIRP at the 50<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.3-4 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.3-4: UE spherical coverage for UL MIMO for power class 3

	Operating band	Min EIRP at 50 %-tile CDF (dBm)
	n257	11.5
n258		11.5
n260		8
n261		11.5
NOTE 1:	NOTE 1: Minimum EIRP at 50 %-tile CDF is defined as the lower limit without tolerance	
NOTE 2: The requirements in this table are only applicable for UE which supports single band in FR2		

## 6.2D.1.4 UE maximum output power for UL MIMO for power class 4

The following requirements define the maximum output power radiated by the UE with UL MIMO for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. Requirements in Table 6.2D.1.4-1 shall be met with the UE configured for 2 layer UL MIMO transmission specified in Table 6.2D.1.4-3. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.4-1: UE minimum peak EIRP for UL MIMO for power class 4

Operating band	Min peak EIRP (dBm)	
n257	34	
n258	34	
n260	31	
n261	34	
NOTE 1: Minimum peak Ell tolerance.	RP is defined as the lower limit without	
NOTE 2: Min Peak EIRP re peaks.	Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.4-2: UE maximum output power limits for UL MIMO for power class 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

Table 6.2D.1.4-3: UL MIMO configuration

Transmission scheme	DCI format	TPMI Index	
Codebook based uplink	DCI format 0_1	0	

The minimum EIRP at the 20<sup>th</sup> percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.4-4 below. The requirement is verified with the test metric of EIRP (Link=Beam peak search grids, Meas=Link angle).

Table 6.2D.1.4-4: UE spherical coverage for UL MIMO for power class 4

Operating band	Min EIRP at 20 %-tile CDF (dBm)
n257	25
n258	25
n260	19
n261	25
NOTE 1: Minimum EIRP at 20 %-tile CDF is defined as	
the lower limit without tolerance	

# 6.2D.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO

# 6.2D.2.1 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 1

For UE with UL MIMO, the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.1-1 is specified in sub-clause 6.2.2.1. The requirements shall be met with UL MIMO configurations specified in sub-clause 6.2D.1.1.

For the UE maximum output power modified by MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.2.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 2

For UE with UL MIMO, the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.2-1 is specified in sub-clause 6.2.2.2. The requirements shall be met with UL MIMO configurations specified in sub-clause 6.2D.1.2.

For the UE maximum output power modified by MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.2.3 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 3

For UE with UL MIMO, the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.3-1 is specified in sub-clause 6.2.2.3. The requirements shall be met with UL MIMO configurations specified in sub-clause 6.2D.1.3.

For the UE maximum output power modified by MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.2.4 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 4

For UE with UL MIMO, the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.4-1 is specified in sub-clause 6.2.2.4. The requirements shall be met with UL MIMO configurations specified in sub-clause 6.2D.1.4.

For the UE maximum output power modified by MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.3 UE maximum output power reduction with additional requirements for UL MIMO

# 6.2D.3.1 UE maximum output power reduction with additional requirements for UL MIMO for power class 1

For UE with UL MIMO, the A-MPR values specified in subclause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.1-1. The requirements shall be met with the UL MIMO configurations specified in sub-clause 6.2D.1.1.

For the UE maximum output power modified by A-MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.3.2 UE maximum output power reduction with additional requirements for UL MIMO for power class 2

For UE with UL MIMO, the A-MPR values specified in subclause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.2-1. The requirements shall be met with the UL MIMO configurations specified in subclause 6.2D.1.2.

For the UE maximum output power modified by A-MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.3.3 UE maximum output power reduction with additional requirements for UL MIMO for power class 3

For UE with UL MIMO, the A-MPR values specified in subclause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.3-1. The requirements shall be met with the UL MIMO configurations specified in subclause 6.2D.1.3.

For the UE maximum output power modified by A-MPR, the power limits specified in subclause 6.2D.4 apply.

# 6.2D.3.4 UE maximum output power reduction with additional requirements for UL MIMO for power class 4

For UE with UL MIMO, the A-MPR values specified in subclause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.4-1. The requirements shall be met with the UL MIMO configurations specified in subclause 6.2D.1.4.

# 6.2D.4 Configured transmitted power for UL MIMO

For UE configured with ULMIMO, the configured maximum output power  $P_{CMAX,c}$  for serving cell c is defined as sum of all streams and is bound by limits set in section 6.2.4.

# 6.3 Output power dynamics

## 6.3.1 Minimum output power

#### 6.3.1.0 General

The minimum controlled output power of the UE is defined as the EIRP in the channel bandwidth for all transmit bandwidth configurations (resource blocks) when the power is set to a minimum value.

## 6.3.1.1 Minimum output power for power class 1

For power class 1 UE, the minimum output power shall not exceed the values specified in Table 6.3.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3.1.1-1: Minimum output power for power class 1

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.52
	100	4	95.04
	200	4	190.08
	400	4	380.16

## 6.3.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3.1.2-1: Minimum output power for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)	
n257, n258, n260, n261	50	-13	47.52	
	100	-13	95.04	
	200	-13	190.08	
400 -13 380.16				
NOTE 1: n260 is not applied for power class 2.				

## 6.3.2 Transmit OFF power

The transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports.

The transmit OFF power shall not exceed the values specified in Table 6.3.2-1 for each operating band supported. The requirement is verified with the test metric of TRP (Link=TX beam peak direction).

Table 6.3.2-1: Transmit OFF power

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n260, n261	-35	-35	-35	-35
	47.52 MHz	95.04 MHz	190.08 MHz	380.16 MHz

#### 6.3.3 Transmit ON/OFF time mask

#### 6.3.3.1 General

The transmit ON/OFF time mask defines the transient period(s) allowed

- between transmit OFF power and transmit ON power symbols (transmit ON/OFF)
- between continuous ON-power transmissions when power change or RB hopping is applied.

In case of RB hopping, transition period is shared symmetrically.

Unless otherwise stated the minimum requirements in clause 6.5 apply also in transient periods.

The transmit ON/OFF time mask is defined as a directional requirement. The requirement is verified in beam locked mode at beam peak direction. The maximum allowed EIRP OFF power level is -30dBm at beam peak direction. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

In the following sub-clauses, following definitions apply:

- A slot transmission is a Type A transmission.
- A long subslot transmission is a Type B transmission with more than 2 symbols.
- A short subslot transmission is a Type B transmission with 1 or 2 symbols.

#### 6.3.3.2 General ON/OFF time mask

The general ON/OFF time mask defines the observation period allowed between transmit OFF and ON power. ON/OFF scenarios include: contiguous, and non-contiguous transmission, etc

The OFF power measurement period is defined in a duration of at least one slot excluding any transient periods. The ON power is defined as the mean power over one slot excluding any transient period.



Figure 6.3.3.2-1: General ON/OFF time mask for NR UL transmission in FR2

## 6.3.3.3 Transmit power time mask for slot and short or long subslot boundaries

The transmit power time mask for slot and a long subslot transmission boundaries defines the transient periods allowed between slot and long subslot PUSCH transmissions. For PUSCH-PUCCH and PUSCH-SRS transitions and multiplexing the time masks in sub-clause 6.3.3.7 apply.

The transmit power time mask for slot or long subslot and short subslot transmission boundaries defines the transient periods allowed between slot or long subslot and short subslot transmissions. The time masks in sub-clause 6.3.3.8 apply.

The transmit power time mask for short subslot transmissiona boundaries defines the transient periods allowed between short subslot transmissions. The time masks in sub-clause 6.3.3.9 apply.

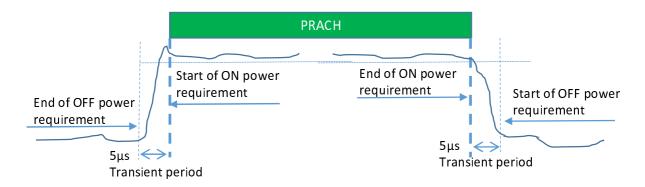
## 6.3.3.4 PRACH time mask

NOTE:

The PRACH ON power is specified as the mean power over the PRACH measurement period excluding any transient periods as shown in Figure 6.3.3.4-1. The measurement period for different PRACH preamble format is specified in Table 6.3.3.4-1.

**Format SCS** Measurement period 60 kHz 0.035677 ms Αı 120 kHz 0.017839 ms 60 kHz 0.071354 ms A<sub>2</sub> 120 kHz 0.035677 ms 60 kHz 0.107031 ms Аз 120 kHz 0.053516 ms 60 kHz 0.035091 ms В 120 kHz 0.0175455 ms 60 kHz 0.207617 ms  $B_4$ 120 kHz 0.103809 ms 60 kHz 0.035677 ms for front X1 occasion 0.035091 ms for last occasion X1 = [2,5]A<sub>1</sub>/B<sub>1</sub> 120 kHz 0.017839 ms for front X1occasion 0.017546 ms for last occasion X1 = [2,5]60 kHz 0.071354 ms for front X2 occasion 0.069596 ms for last occasion X2 = [1,2] $A_2/B_2$ 120 kHz 0.035677 ms for front X2 occasion 0.034798 ms for last occasion X2 = [1,2]60 kHz 0.107031 ms for first occasion 0.104101 ms for second occasion A<sub>3</sub>/B<sub>3</sub> 0.053515 ms for first occasion 120 kHz 0.052050 ms for second occasion 0.026758 ms 60 kHz  $C_0$ 120 kHz 0.013379 ms 60 kHz 0.083333 ms  $C_2$ 120 kHz 0.0416667 ms

Table 6.3.3.4-1: PRACH ON power measurement period



the measurement period will plus 0.032552 µs

For PRACH on PRACH occasion start from begin of 0ms or 0.5 ms boundary,

Figure 6.3.3.4-1: PRACH ON/OFF time mask

#### 6.3.3.5 Void

#### 6.3.3.6 SRS time mask

In the case a single SRS transmission, the ON power is defined as the mean power over the symbol duration excluding any transient period; Figure 6.3.3.6-1.

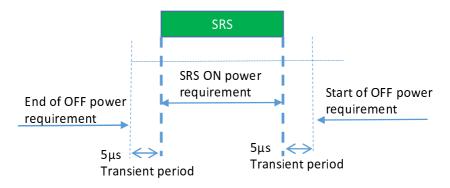


Figure 6.3.3.6-1: Single SRS time mask for NR UL transmission

In the case multiple consecutive SRS transmission, the ON power is defined as the mean power for each symbol duration excluding any transient period. See Figure 7.7.4-2

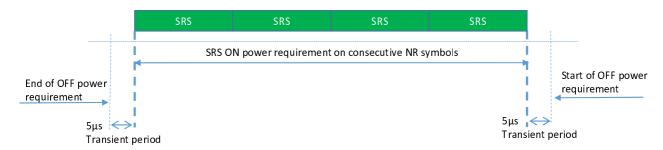


Figure 6.3.3.6-2: Consecutive SRS time mask for the case when no power change is required

When power change between consecutive SRS transmissions is required, then Figure 6.3.3.6-3 and Figure 6.3.3.6-4 apply.

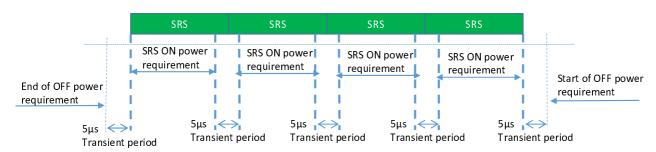


Figure 6.3.3.6-3: Consecutive SRS time mask for the case when power change is required and when 60kHz SCS is used in FR2

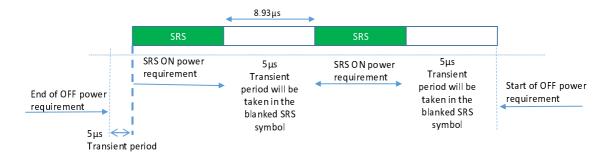


Figure 6.3.3.6-4: Consecutive SRS time mask for the case when power change is required and when 120kHz SCS is used in FR2

#### 6.3.3.7 PUSCH-PUCCH and PUSCH-SRS time masks

The PUCCH/PUSCH/SRS time mask defines the observation period between sounding reference symbol (SRS) and an adjacent PUSCH/PUCCH symbol and subsequent UL transmissions. The time masks apply for all types of frame structures and their allowed PUCCH/PUSCH/SRS transmissions unless otherwise stated.

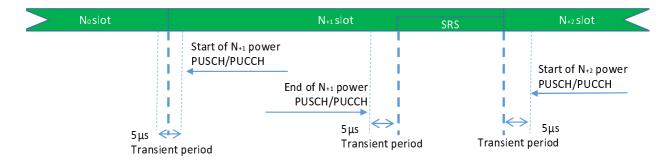


Figure 6.3.3.7-1: PUCCH/PUSCH/SRS time mask when there is a transmission before or after or both before and after SRS

When there is no transmission preceding SRS transmission or succeeding SRS transmission, then the same time mask applies as shown in Figure 6.3.3.7-1.

# 6.3.3.8 Transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries

The transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries defines the transient periods allowed between such transmissions.

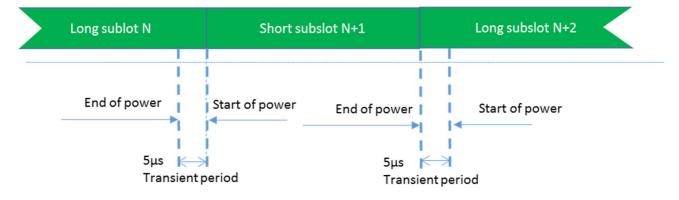


Figure 6.3.3.8-1: Consecutive slot or long subslot transmission and short subslot transmission time mask

# 6.3.3.9 Transmit power time mask for consecutive short subslot transmissions boundaries

The transmit power time mask for consecutive short subslot transmission boundaries defines the transient periods allowed between short subslot transmissions.

The transient period shall be equally shared as shown on Figure 6.3.3.9-2.

Figure 6.3.3.9-1: Void

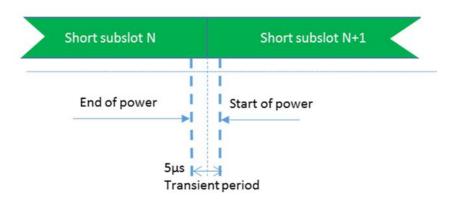


Figure 6.3.3.9-2: Consecutive short subslot transmissions time mask where DMRS is not the first symbol in the adjacent short subslot transmission

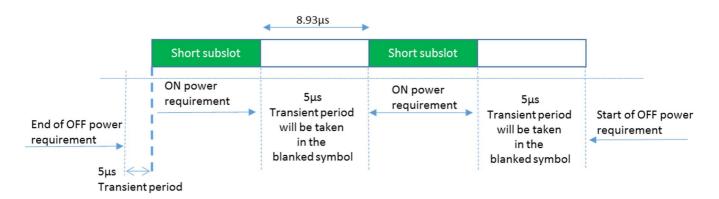


Figure 6.3.3.9-3: Consecutive short subslot (1 symbol gap) time mask for the case when transient period is required on both sides of the symbol and when 120 kHz SCS is used in FR2

#### 6.3.4 Power control

#### 6.3.4.1 General

The requirements on power control accuracy apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction.

#### 6.3.4.2 Absolute power tolerance

The absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame (1 ms) at the start of a contiguous transmission or non-contiguous transmission with a transmission gap larger than 20 ms. The tolerance includes the channel estimation error RSRP estimate.

The minimum requirements specified in Table 6.3.4.2-1 apply in the power range bounded by the minimum output power as specified in sub-clause 6.3.1 (' $P_{min}$ ') and the maximum output power as specified in sub-clause 6.2.1 as minimum peak EIRP (' $P_{max}$ '). The intermediate power point ' $P_{int}$ ' is defined in table 6.3.4.2-2

Table 6.3.4.2-1: Absolute power tolerance

Power Range	Tolerance
$P_{int} \ge P \ge P_{min}$	± [14.0] dB
$P_{max} \ge P > P_{int}$	± [12.0] dB

Table 6.3.4.2-2: Intermediate power point

Power Parameter	Value
Pint	P <sub>max</sub> – 12.0 dB

## 6.3.4.3 Relative power tolerance

The relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame (1 ms) relatively to the power of the most recently transmitted reference sub-frame (1 ms) if the transmission gap between these sub-frames is 20 ms.

The minimum requirements specified in Table 6.3.4.3-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and Pint as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.3-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the measured  $P_{UMAX}$  as defined in sub-clause 6.2.4.

For a test pattern that is either a monotonically increasing or monotonically decreasing power sweep over the range specified for Tables 6.3.4.3-1 and 6.3.4.3-2, [3] exceptions are allowed for each of the test patterns. For these exceptions, the power tolerance limit is a maximum of  $[\pm 11.0]$  dB.

Table 6.3.4.3-1: Relative power tolerance,  $P_{int} \ge P \ge P_{min}$ 

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between subframes, PRACH (dB)	
ΔP < 2	[±5.0]	
2 ≤ ΔP < 3	[±6.0]	
3 ≤ ΔP < 4	[±7.0]	
4 ≤ ΔP < 10	[±8.0]	
10 ≤ ΔP < 15	[±10.0]	
15 ≤ ΔP [±11.0]		
NOTE: The requirements apply with <i>ue-BeamLockFunction</i> enabled.		

Table 6.3.4.3-2: Relative power tolerance, P<sub>UMAX</sub> ≥ P > P<sub>int</sub>

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between subframes, PRACH (dB)	
ΔP < 2	[± 3.0]	
2 ≤ ΔP < 3	[± 4.0]	
3 ≤ ΔP < 4	[± 5.0]	
4 ≤ ΔP < 10	[± 6.0]	
10 ≤ ΔP < 15	[± 8.0]	
15 ≤ ∆P	[± 9.0]	
NOTE 1: The requirements apply with <i>ue-BeamLockFunction</i> enabled.		

NOTE 2: For PUSCH to PUSCH transitions with the allocated resource blocks fixed in frequency and no transmission gaps other than those generated by downlink subframes, guard periods: for a power step ΔP = 1 dB, the relative power

tolerance for transmission is  $\pm 1.0$  dB.

### 6.3.4.4 Aggregate power tolerance

The aggregate power control tolerance is the ability of the UE transmitter to maintain its power in a sub-frame (1 ms) during non-contiguous transmissions within 21ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in 38.213 kept constant.

The minimum requirements specified in Table 6.3.4.4-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and  $P_{int}$  as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.4-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the maximum output power as specified in sub-clause 6.2.1.

Table 6.3.4.4-1: Aggregate power tolerance, P<sub>int</sub> ≥ P ≥ P<sub>min</sub>

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± [5.5] dB
0 dB	PUSCH	± [5.5] dB

Table 6.3.4.4-2: Aggregate power tolerance, P<sub>max</sub> ≥ P ≥ P<sub>int</sub>

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± [3.5] dB
0 dB	PUSCH	± [3.5] dB

# 6.3A Output power dynamics for CA

# 6.3A.1 Minimum output power for CA

**Table 6.3A.1-1: Void** 

#### 6.3A.1.0 General

For intra-band contiguous carrier aggregation, the minimum controlled output power of the UE is defined as the transmit power of the UE per component carrier, i.e., EIRP in the channel bandwidth of each component carrier for all transmit bandwidth configurations (resource blocks), when the power on both component carriers are set to a minimum value.

### 6.3A.1.1 Minimum output power for power class 1

The minimum output power shall not exceed the values specified in Table 6.3A.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3A.1.1-1: Minimum output power for power class 1

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.52
	100	4	95.04
	200	4	190.08
	400	4	380.16

## 6.3A.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3A.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3A.1.2-1: Minimum output power for CA for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	-13	47.52
	100	-13	95.04
	200	-13	190.08
	400	-13	380.16
NOTE 1: n260 is not applied for power class 2.			

## 6.3A.2 Transmit OFF power for CA

For intra-band contiguous carrier aggregation, the transmit OFF power is defined as the TRP in the channel bandwidth per component carrier when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of it sports.

The transmit OFF power shall not exceed the values specified in Table 6.3A.2-1 for each operating band supported.

Table 6.3A.2-1: Transmit OFF power for CA

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n260, n261	-35	-35	-35	-35
	47.52 MHz	95.04 MHz	190.08 MHz	380.16 MHz

## 6.3A.3 Transmit ON/OFF time mask for CA

For intra-band contiguous carrier aggregation, the general output power ON/OFF time mask specified in subclause 6.3.3.2 is applicable for each component carrier during the ON power period and the transient periods. The OFF period as specified in subclause 6.3.3.2 shall only be applicable for each component carrier when all the component carriers are OFF.

#### 6.3A.4 Power control for CA

#### 6.3A.4.1 General

The requirements in this section apply to a UE when it has at least one of UL or DL configured for CA operation. The requirements on power control accuracy in CA operation apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction. The requirements apply for one single PUCCH, PUSCH or SRS transmission of contiguous PRB allocation per configured UL CC with power setting in accordance with Clause 7.1 of [10]

#### 6.3A.4.2 Absolute power tolerance

The absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on each active component carriers larger than 20 ms. For SRS switching, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on component carriers (to which SRS switching occurs) larger than 20 ms. The requirement can be tested by time aligning any transmission gaps on the component carriers. For intra-band contiguous CA, the absolute power control tolerance per configured UL CC is given in Tables 6.3.4.2-1 and 6.3.4.2-2.

#### 6.3A.4.3 Relative power tolerance

The relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame relative to the power of the most recently transmitted reference sub-frame if the transmission gap between these sub-frames is <20ms.

For intra-band contiguous CA, the requirements apply when the power of the target and reference sub-frames on each component carrier exceed the minimum output power as defined in subclause 6.3A.1 and the total power is limited by  $P_{UMAX}$  as defined in subclause 6.2A.4. For the purpose of these requirements, the power in each component carrier is specified over only the transmitted resource blocks. The UE shall meet the requirements in tables 6.3.4.3-1 and 6.3.4.3-2 for transmission on each assigned component carrier, when the average PSDs over each CC are aligned with each other in the reference sub-frame. The requirements apply per component carrier to:

- a. All possible combinations of PUSCH and PUCCH transitions
- b. SRS and PUSCH/PUCCH transitions, only with simultaneous SRS of constant SRS bandwidth allocated in the target and reference subrames
- c. RACH, primary component carrier

When applicable, the power step  $\Delta P$  between the reference and target subframes shall be set by a TPC command and/or an uplink scheduling grant transmitted by means of an appropriate DCI Format.

## 6.3A.4.4 Aggregate power tolerance

The aggregate power control tolerance is the ability of the UE transmitter to maintain its power during non-contiguous transmissions within 21 ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in [10] kept constant.

For intra-band contiguous CA, the aggregate power tolerance per CC is given in Tables 6.3.4.4.1-1 and 6.3.4.4.1-2, with simultaneous PUSCH configured. The average PSDs over each assigned CC shall be aligned before the start of the test. The requirement can be tested with the transmission gaps time aligned between component carriers.

# 6.3D Output power dynamics for UL MIMO

## 6.3D.1 Minimum output power for UL MIMO

## 6.3D.1.1 Minimum output power for UL MIMO for power class 1

For UE supporting UL MIMO, the minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value. The minimum output power shall not exceed the values specified in Table 6.3.1.1-1. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

#### 6.3D.1.2 Minimum output power for UL MIMO for power class 2, 3 and 4

For UE supporting UL MIMO, the minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value. The minimum output power shall not exceed the values specified in Table 6.3.1.2-1. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

## 6.3D.2 Transmit OFF power for UL MIMO

For UE supporting UL MIMO, the transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports. During DTX and measurements gaps, the transmitter is not considered OFF. The minimum output power shall not exceed the values specified in Table 6.3.2-1. The requirement is verified with the test metric of TRP (Link=TX beam peak direction).

#### 6.3D.3 Transmit ON/OFF time mask for UL MIMO

For UE supporting UL MIMO, the ON/OFF time mask requirements in subclause 6.3.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

# 6.4 Transmit signal quality

# 6.4.1 Frequency Error

The UE modulated carrier frequency shall be accurate to within  $\pm$  0.1 PPM observed over a period of 1 msec compared to the carrier frequency received from the NR gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of Frequency (Link=TX beam peak direction, Meas=Link angle).

# 6.4.2 Transmit modulation quality

#### 6.4.2.0 General

Transmit modulation quality defines the modulation quality for expected in-channel RF transmissions from the UE. The transmit modulation quality is specified in terms of:

- Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)
- EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process
- Carrier leakage
- In-band emissions for the non-allocated RB

All the parameters defined in subclause 6.4.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with parameter *maxRank* (as defined in TS 38.331 [13]) set to 1. The requirements are applicable to UL transmission from each configurable antenna port (as defined in TS 38.331 [13]) of UE, enabled one at a time.

### 6.4.2.1 Error vector magnitude

The Error Vector Magnitude is a measure of the difference between the reference waveform and the measured waveform. This difference is called the error vector. Before calculating the EVM, the measured waveform is corrected by the sample timing offset and RF frequency offset. Then the carrier leakage shall be removed from the measured waveform before calculating the EVM.

The measured waveform is further equalised using the channel estimates subjected to the EVM equaliser spectrum flatness requirement specified in sub-clauses 6.4.2.4 and 6.4.2.5. For DFT-s-OFDM waveforms, the EVM result is defined after the front-end FFT and IDFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %. For CP-OFDM waveforms, the EVM result is defined after the front-end FFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %.

The basic EVM measurement interval in the time domain is one preamble sequence for the PRACH and the duration of PUCCH/PUSCH channel, or one hop, if frequency hopping is enabled for PUCCH and PUSCH in the time domain. The EVM measurement interval is reduced by any symbols that contains an allowable power transient as defined in subclause 6.3.3.

The RMS average of the basic EVM measurements for the average EVM case, and for the reference signal EVM case, for the different modulation schemes shall not exceed the values specified in Table 6.4.2.1-1 for the parameters defined in Table 6.4.2.1-2 or Table 6.4.2.1-3 depending on UE power class. For EVM evaluation purposes, all 13 PRACH preamble formats and all 5 PUCCH formats are considered to have the same EVM requirement as QPSK modulated.

The measurement interval for the EVM determination is 10 subframes. The requirement is verified with the test metric of EVM (Link=TX beam peak direction, Meas=Link angle).

Average EVM level Reference signal EVM level **Parameter** Unit Pi/2 BPSK % 30.0 30.0 QPSK % 17.5 17.5 12.5 16 QAM % 12.5 64 QAM 8.0

Table 6.4.2.1-1: Minimum requirements for error vector magnitude

Table 6.4.2.1-2: Parameters for Error Vector Magnitude for power class 1

Parameter	Unit	Level
UE EIRP	dBm	≥ 4
UE EIRP for UL 16 QAM	dBm	≥ 7
UE EIRP for UL 64 QAM	dBm	≥ 11
Operating conditions		Normal conditions

Table 6.4.2.1-3: Parameters for Error Vector Magnitude for power class 2, 3, and 4

Parameter	Unit	Level
UE EIRP	dBm	≥ -13
UE EIRP for UL 16 QAM	dBm	≥ -10
UE EIRP for UL 64 QAM	dBm	≥ -6
Operating conditions		Normal conditions

#### 6.4.2.2 Carrier leakage

#### 6.4.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier. The measurement interval is one slot in the time domain. The relative carrier leakage power is a power ratio of the additive sinusoid waveform to the power in the modulated waveform.

The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

#### 6.4.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum confined within the configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.1 for power class 1 UEs.

Table 6.4.2.2.2-1: Minimum requirements for relative carrier leakage power for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

#### 6.4.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.3-1 for power class 2.

Table 6.4.2.2.3-1: Minimum requirements for relative carrier leakage power for power class 2

Parameters	Relative Limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

#### 6.4.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.4-1 for power class 3 UEs.

Table 6.4.2.2.4-1: Minimum requirements for relative carrier leakage power for power class 3

Parameters	Relative Limit (dBc)
EIRP > 0 dBm	-25
-13 dBm ≤ EIRP ≤ 0 dBm	-20

#### 6.4.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.5-1 for power class 4.

Table 6.4.2.2.5-1: Minimum requirements for relative carrier leakage power for power class 4

Parameters	Relative Limit (dBc)
EIRP > 11 dBm	-25
-13 dBm ≤ EIRP ≤ 11 dBm	-20

#### 6.4.2.3 In-band emissions

#### 6.4.2.3.1 General

The in-band emission is defined as the average across 12 sub-carriers and as a function of the RB offset from the edge of the allocated UL transmission bandwidth. The in-band emission is measured as the ratio of the UE output power in a non-allocated RB to the UE output power in an allocated RB.

The basic in-band emissions measurement interval is identical to that of the EVM test.

The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

#### 6.4.2.3.2 In-band emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.2-1 for power class 1 UEs.

Table 6.4.2.3.2-1: Requirements for in-band emissions for power class 1

Parameter description	Unit	Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(\text{EVM}) - 5.\frac{( \Delta_{RB}  - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25 Output power > 27 dBm -20 Output power ≤ 27 dBm	Image frequencies (NOTES 2, 3)
Carrier leakage	dBc	-25 Output power > 17 dBm -20 4 dBm ≤ Output power ≤ 17 dBm	Carrier frequency (NOTES 4, 5)

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrent* IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6:  $L_{CRB}$  is the Transmission Bandwidth (see Section 5.3).
- NOTE 7: N<sub>RB</sub> is the Transmission Bandwidth Configuration (see Section 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB}$  = 1 or  $\Delta_{RB}$  = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10:  $\overline{P}_{RB}$  is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

#### 6.4.2.3.3 In-band emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.3-1 for power class 2.

Table 6.4.2.3.3-1: Requirements for in-band emissions for power class 2

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{( \Delta_{RB}  - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated (NOTE 2)
IQ Image	dB	-25 -20	Output power > 16 dBm Output power ≤ 16 dBm	Image frequencies (NOTES 2, 3)
Carrier	dBc	-25	Output power > 6 dBm	Carrier frequency
leakage	ubc	-20	-13 dBm ≤ Output power ≤ 6 dBm	(NOTES 4, 5)

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrent* IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6: L<sub>CRB</sub> is the Transmission Bandwidth (see Section 5.3).
- NOTE 7: N<sub>RB</sub> is the Transmission Bandwidth Configuration (see Section 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB}$  = 1 or  $\Delta_{RB}$  = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10: P<sub>RB</sub> is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

#### 6.4.2.3.4 In-band emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.4-1 for power class 3 UEs.

Table 6.4.2.3.4-1: Requirements for in-band emissions for power class 3

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	m	$ax \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{( \Delta_{RB}  - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25 -20	Output power > 10 dBm Output power ≤ 10 dBm	Image frequencies (NOTES 2, 3)
Carrier	dBc	-25	Output power > 0 dBm	Carrier frequency
leakage	ubc	-20	-13 dBm ≤ Output power ≤ 0 dBm	(NOTES 4, 5)

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6:  $L_{CRB}$  is the Transmission Bandwidth (see Section 5.3).
- NOTE 7:  $N_{RB}$  is the Transmission Bandwidth Configuration (see Section 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB}$  = 1 or  $\Delta_{RB}$  = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10:  $\overline{P}_{RB}$  is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

## 6.4.2.3.5 In-band emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.5-1 for power class 4 UEs.

Image frequencies

(NOTES 2, 3)

Carrier frequency

(NOTES 4, 5)

Parameter description	Unit	Limit (NOTE 1)	Applicable Frequencies
General	dB	$max egin{bmatrix} -25 & -10.\log_{10}\left(rac{N_{RB}}{L_{CRB}} ight), \ 20.\log_{10}(EVM) - 5.rac{( \Delta_{RB} -1)}{L_{CRB}}, \ -55.1dBm - rac{P_{PB}}{P_{PB}} \end{bmatrix}$	Any non-allocated (NOTE 2)

Table 6.4.2.3.5-1: Requirements for in-band emissions for power class 4

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$ - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 10.

-13 dBm ≤ Output power ≤ 11 dBm

Output power > 21 dBm

Output power ≤ 21 dBm

Output power > 11 dBm

- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6:  $L_{CRB}$  is the Transmission Bandwidth (see Section 5.3).

-25

-20

-25

-20

IQ Image

Carrier

leakage

dB

dBc

- NOTE 7:  $N_{RB}$  is the Transmission Bandwidth Configuration (see Section 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB}$  = 1 or  $\Delta_{RB}$  = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10:  $\overline{P}_{RB}$  is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

#### 6.4.2.4 EVM equalizer spectrum flatness

The EVM measurement process (as described in Annex F) entails generation of a zero-forcing equalizer. The EVM equalizer spectrum flatness is defined in terms of the maximum peak-to-peak ripple of the equalizer coefficients (dB) across the allocated uplink block. The basic measurement interval is the same as for EVM.

For Pi/2 BPSK modulation, the minimum requirements are defined in Clause 6.4.2.5.

The peak-to-peak variation of the EVM equalizer coefficients contained within the frequency range of the uplink allocation shall not exceed the maximum ripple specified in Table 6.4.2.4-1 for normal conditions. For uplink allocations contained within both Range 1 and Range 2, the coefficients evaluated within each of these frequency ranges shall meet the corresponding ripple requirement and the following additional requirements: the relative difference between the maximum coefficient in Range 1 and the minimum coefficient in Range 2 (Table 6.4.2.4-1) must not be larger than 7 dB, and the relative difference between the maximum coefficient in Range 2 and the minimum coefficient in Range 1 must not be larger than 8 dB (see Figure 6.4.2.4-1).

The requirement is verified with the test metric of EVM SF (Link=TX beam peak direction, Meas=Link angle).

Table 6.4.2.4-1: Minimum requirements for EVM equalizer spectrum flatness (normal conditions)

Frequency range	Maximum ripple (dB)
Ful_Meas - F_center  ≤ X MHz	6 (p-p)
(Range 1)	
Ful_Meas - F_center  > X MHz	9 (p-p)
(Range 2)	
NOTE 1: FUL_Meas refers to the sub-carrier frequency for which	the equalizer coefficient is
evaluated	
NOTE 2: F_center refers to the center frequency of the CC	
NOTE 3: X, in MHz, is equal to 30 % of the CC bandwidth	

Table 6.4.2.4-2: (Void)

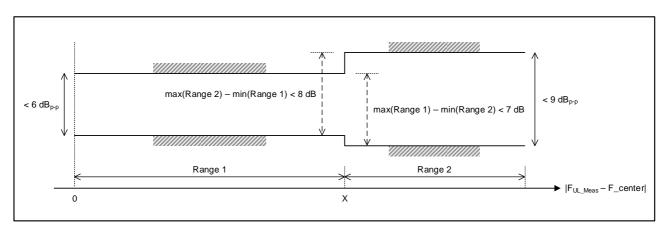


Figure 6.4.2.4-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation of the coefficients indicated under normal conditions

## 6.4.2.5 EVM spectral flatness for Pi/2 BPSK modulation

These requirements are defined for Pi/2 BPSK modulation. The EVM equalizer coefficients across the allocated uplink block shall be modified to fit inside the mask specified in Table 6.4.2.5-1 for normal conditions, prior to the calculation of EVM. The limiting mask shall be placed to minimize the change in equalizer coefficients in a sum of squares sense.

Table 6.4.2.5-1: Mask for EVM equalizer coefficients for pi/2 BPSK (normal conditions)

Frequency range	Parameter	Maximum ripple (dB)		
F <sub>UL_Meas</sub> – F_center  ≤ X MHz	X1	6 (p-p)		
(Range 1)				
Ful_Meas - F_center  > X MHz	X2	14 (p-p)		
(Range 2)				
NOTE 1: Ful_Meas refers to the sub-carrier frequency for which the equalizer coefficient is evaluated				
NOTE 2: F_center refers to the center frequency of an allocat	ed block of PR	Bs		
NOTE 3: X, in MHz, is equal to 25% of the bandwidth of the PRB allocation				
NOTE 4: See Figure 6.4.2.5-1 for description of X1, X2 and X3				

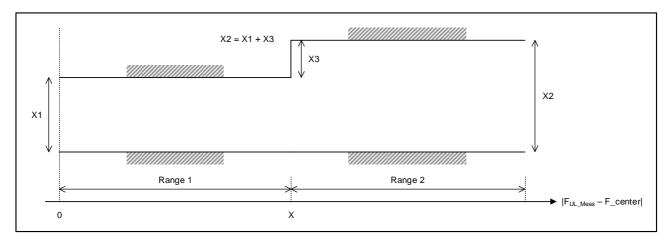


Figure 6.4.2.5-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation.

F\_center denotes the center frequency of the allocated block of PRBs.

This requirement does not apply to other modulation types. The UE shall be allowed to employ spectral shaping for Pi/2 BPSK. The shaping filter shall be restricted so that the impulse response of the transmit chain shall meet

$$\left| \tilde{a}_{l}(t,0) \right| \geq \left| \tilde{a}_{l}(t,\tau) \right| \quad \forall \tau \neq 0$$

$$20log_{10} \left| \tilde{a}_{l}(t,\tau) \right| < -15 \text{ dB} \quad 1 < \tau < M - 1,$$

Where:

$$|\tilde{\mathbf{a}}_{t}(t,\tau)| = IDFT\{ |\tilde{\mathbf{a}}_{t}(t,f)| e^{j\varphi(t,f)} \},$$

f is the frequency of the M allocated subcarriers,

 $\tilde{a}(t,f)$  and  $\phi(t,f)$  are the amplitude and phase response, respectively of the transmit chain

0dB reference is defined as  $20\log_{10} |\tilde{a}_t(t,0)|$ 

# 6.4A Transmit signal quality for CA

The requirements in this section apply if the UE has at least one of UL or DL configured for CA.

# 6.4A.1 Frequency error

The requirements in this subclause apply to UEs of all power classes.

For intra-band contiguous carrier aggregation, the UE modulated carrier frequencies per band shall be accurate to within  $\pm~0.1$  PPM observed over a period of 1ms compared to the carrier frequency of primary component carrier received from the gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction.

# 6.4A.2 Transmit modulation quality

#### 6.4A.2.0 General

For intra-band contiguous carrier aggregation, the requirements in subclauses 6.4A.2.1, 6.4A.2.2, and 6.4A.2.3.

All the parameters defined in subclause 6.4A.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4A.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with both UL polarizations active.

### 6.4A.2.1 Error Vector magnitude

The requirements in this subclause apply to UEs of all power classes. For intra-band contiguous carrier aggregation, the Error Vector Magnitude requirement of section 6.4.2.2 is defined for each component carrier. Requirements only apply with PRB allocation in one of the component carriers. Similar transmitter impairment removal procedures are applied for CA waveform before EVM calculation as is specified for non-CA waveform.

## 6.4A.2.2 Carrier leakage

#### 6.4A.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier and is measured on the component carrier with PRBs allocated. The measurement interval is one slot in the time domain.

Note: When UE has DL configured for non-contiguous CA, carrier leakage may land outside the spectrum occupied by all configured UL and DL CC.

The relative carrier leakage power is a power ratio of the additive sinusoid waveform and the modulated waveform. The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

## 6.4A.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.2-1 for power class 1 UEs.

Table 6.4A.2.2.2-1: Minimum requirements for relative carrier leakage for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

## 6.4A.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.3-1 for power class 2.

Table 6.4A.2.2.3-1: Minimum requirements for relative carrier leakage power class 2

Parameters	Relative limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

#### 6.4A.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.4-1 for power class 3 UEs.

Table 6.4A.2.2.4-1: Minimum requirements for relative carrier leakage power class 3

Parameters	Relative limit (dBc)
Output power > 0 dBm	-25
-13 dBm ≤ Output power EIRP ≤ 0 dBm	-20

### 6.4A.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.5-1 for power class 4 UEs.

Table 6.4A.2.2.5-1: Minimum requirements for relative carrier leakage power class 4

Parameters	Relative limit (dBc)
Output power > 11 dBm	-25
-13 dBm ≤ Output power EIRP ≤ 11 dBm	-20

#### 6.4A.2.3 Inband emissions

#### 6.4A.2.3.1 General

Inband emission requirement is defined over the spectrum occupied by all configured UL and DL CCs. The measurement interval is as defined in section 6.4.2.4. The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

For intra-band contiguous carrier aggregation, the requirements in this clause apply with all component carriers active and with one single contiguous PRB allocation in one of uplink component carriers. The inband emission is defined as the interference falling into the non-allocated resource blocks for all component carriers.

#### 6.4A.2.3.2 Inband emissions for power class 1

The relative in-band emission shall not exceed the values specified in Table 6.4A.2.3.2-1 for power class 1 UEs.

Table 6.4A.2.3.2-1: Requirements for in-band emissions for power class 1

Parameter description	Unit	Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10 \cdot \log_{10} \left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20 \cdot \log_{10} (\text{EVM}) - 5 \cdot \frac{\left( \Delta_{RB}  - 1\right)}{L_{CRB}}, \\ -55.1 dBm - P_{RB} \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25 Output power > 27 dBm -20 Output power ≤ 27 dBm	Image frequencies (NOTES 2, 3)
Carrier leakage	dBc	-25 Output power > 17 dBm -20 4 dBm ≤ Output power ≤ 17 dBm	Carrier frequency (NOTES 4, 5)

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L<sub>CRB</sub> is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB}$  = 1 or  $\Delta_{RB}$  = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9:  $P_{RB}$  is the transmitted power per allocated RB, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

#### 6.4A.2.3.3 Inband emissions for power class 2

The relative in-band emission shall not exceed the values specified in Table 6.4A.2.3.3-1 for power class 2.

Table 6.4A.2.3.3-1: Requirements for in-band emissions for power class 2

Parameter description	Unit		Applicable Frequencies	
General	dB	$max \begin{bmatrix} -25 - 10 \cdot \log_{10} \left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20 \cdot \log_{10}(\text{EVM}) - 5 \cdot \frac{( \Delta_{RB}  - 1)}{L_{CRB}}, \\ -55.1 dBm - P_{RB} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25		
		-20	(NOTES 2, 3)	
Carrier	dD.	-25	Carrier frequency	
leakage	dBc	-20	-13 dBm ≤ Output power ≤ 6 dBm	(NOTES 4, 5)

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L<sub>CRB</sub> is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB} = 1$  or  $\Delta_{RB} = -1$  for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: P<sub>RR</sub> is the transmitted power per allocated RB, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

#### 6.4A.2.3.4 Inband emissions for power class 3

The relative in-band emission shall not exceed the values specified in Table 6.4A.2.3.4-1 for power class 3 UEs.

Table 6.4A.2.3.4-1: Requirements for in-band emissions for power class 3

Parameter description	Unit		Applicable Frequencies					
General	dB	$max \begin{bmatrix} -25 - 10 \cdot \log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20 \cdot \log_{10}(\text{EVM}) - 5 \cdot \frac{\left( \Delta_{RB}  - 1\right)}{L_{CRB}}, \\ -55.1dBm - P_{RB} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)				
IQ Image	dB	-25	To the process of the control of the					
		-20	(NOTES 2, 3)					
Carrier	dBc	-25	-25 Output power > 0 dBm					
leakage	ubc	-20	Carrier frequency (NOTES 4, 5)					

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L<sub>CRB</sub> is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB} = 1$  or  $\Delta_{RB} = -1$  for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: P<sub>RB</sub> is the transmitted power per allocated RB, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

#### 6.4A.2.3.5 Inband emissions for power class 4

The relative in-band emission shall not exceed the values specified in Table 6.4A.2.3.5-1 for power class 4 UEs.

Table 6.4A.2.3.5-1: Requirements for in-band emissions for power class 4

Parameter description	Unit		Limit (NOTE 1)					
General	dB	r	$nax \begin{bmatrix} -25 - 10 \cdot \log_{10} \left( \frac{N_{RB}}{L_{CRB}} \right), \\ 20 \cdot \log_{10} (EVM) - 5 \cdot \frac{( \Delta_{RB}  - 1)}{L_{CRB}}, \\ -55.1 dBm - P_{RB} \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)				
IQ Image	dB	-25	-25 Output power > 21 dBm					
. a image	מט	-20	(NOTES 2, 3)					
Carrier	dBc	-25	-25 Output power > 11 dBm					
leakage	ubc	-20						

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of ( $P_{RB}$  25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply.  $P_{RB}$  is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6:  $L_{CRB}$  is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8:  $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB} = 1$  or  $\Delta_{RB} = -1$  for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9:  $P_{RB}$  is the transmitted power per allocated RB, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

#### 6.4A.2.4 EVM equalizer spectrum flatness

## 6.4D Transmit signal quality for UL MIMO

#### 6.4D.0 General

For a UE supporting UL MIMO, the transmit modulation quality requirements in subclause 6.4 apply. The requirements apply when the UE is configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.3-3.

The requirement may alternatively be verified in each of the single layer UL MIMO configurations as specified in Table 6.4D.0-1.

Table 6.4D.0-1: Alternative UL MIMO configuration for transmit signal quality tests

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0
Codebook based uplink	DCI format 0_1	1

## 6.4D.1 Frequency error for UL MIMO

For a UE supporting UL MIMO, the UE modulated carrier frequency at each layer shall be accurate to within  $\pm$  0.1 PPM observed over a period of one sub-frame (1 ms) compared to the carrier frequency received from the NR Node B.

## 6.4D.2 Transmit modulation quality for UL MIMO

For UE supporting UL MIMO, the transmit modulation quality requirements are specified at each layer separately.

The transmit modulation quality requirements are specified in terms of:

Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)

EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process

Carrier leakage (caused by IQ offset)

In-band emissions for the non-allocated RB

## 6.4D.3 Time alignment error for UL MIMO

For a UE with multiple physical antenna ports supporting UL MIMO, this requirement applies to frame timing differences between transmissions on multiple physical antenna ports in the codebook transmission scheme.

The time alignment error (TAE) is defined as the average frame timing difference between any two transmissions on different physical antenna ports.

For a UE with multiple physical antenna ports, the Time Alignment Error (TAE) shall not exceed 130 ns.

## 6.4D.4 Requirements for coherent UL MIMO

For coherent UL MIMO, Table 6.4D.4-1 lists the maximum allowable difference between the measured relative power and phase errors between different physical antenna ports in any slot within the specified time window from the last transmitted SRS on the same antenna ports, for the purpose of uplink transmission (codebook or non-codebook usage) and those measured at that last SRS. The requirements in Table 6.4D.4-1 apply when the UL transmission power at each physical antenna port is larger than [0] dBm for SRS transmission and for the duration of time window. The requirement is verified with the test metric of EIRP (Link=Beam peak direction, Meas=Link angle).

Table 6.4D.4-1: Maximum allowable difference of relative phase and power errors in a given slot compared to those measured at last SRS transmitted

Difference of relative phase error	Difference of relative power error	Time window
[40] degrees	[4] dB	20 msec

The above requirements apply when all of the following conditions are met within the specified time window:

- UE is not signaled with a change in number of SRS ports in SRS-config, or a change in PUSCH-config
- UE remains in DRX active time (UE does not enter DRX OFF time)
- No measurement gap occurs
- No instance of SRS transmission with the usage antenna switching occurs
- Active BWP remains the same
- EN-DC and CA configuration is not changed for the UE (UE is not configured or de-configured with PScell or SCell(s))

## 6.5 Output RF spectrum emissions

## 6.5.1 Occupied bandwidth

Occupied bandwidth is defined as the bandwidth containing 99 % of the total integrated mean power of the transmitted spectrum on the assigned channel. The occupied bandwidth for all transmission bandwidth configurations (Resources Blocks) shall be less than the channel bandwidth specified in Table 6.5.1-1.

The occupied bandwidth is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of OBW (Link=TX beam peak direction, Meas=Link angle).

Table 6.5.1-1: Occupied channel bandwidth

	Occupied channel bandwidth / Channel bandwidth						
	50 100 200 400 MHz MHz MHz MHz						
Channel bandwidth (MHz)	50	100	200	400			

## 6.5.2 Out of band emissions

#### 6.5.2.0 General

The Out of band emissions are unwanted emissions immediately outside the assigned channel bandwidth resulting from the modulation process and non-linearity in the transmitter but excluding spurious emissions. This out of band emission limit is specified in terms of a spectrum emission mask and an adjacent channel leakage power ratio. Additional requirements to protect specific bands are also considered.

The requirements in section 6.5.2.1 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in section 6.5A.2.1 apply.

All out of band emissions for frequency range 2 are TRP.

#### 6.5.2.1 Spectrum emission mask

The spectrum emission mask of the UE applies to frequencies ( $\Delta f_{OOB}$ ) starting from the  $\pm$  edge of the assigned NR channel bandwidth. For frequencies offset greater than  $F_{OOB}$  as specified in Table 6.5.2.1-1 the spurious requirements in subclause 6.5.3 are applicable.

The power of any UE emission shall not exceed the levels specified in Table 6.5.2.1-1 for the specified channel bandwidth. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

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Spectrum emission limit (dBm) / Channel bandwidth Δfоов 100 200 400 Measurement 50 MHz (MHz) MHz MHz MHz bandwidth  $\pm 0-5$ -5 -5 -5 -5 1 MHz -13 -5 -5 -5 1 MHz ± 5-10 -13 -13 1 MHz  $\pm 10-20$ -5 -5 ± 20-40 -13 -13 -13 -5 1 MHz -13 -13 -13 -13 1 MHz ± 40-100

-13

-13

-13

-13

-13

1 MHz

1 MHz

1 MHz

Table 6.5.2.1-1: General NR spectrum emission mask for frequency range 2.

#### 6.5.2.2 Void

## .

## 6.5.2.3 Adjacent channel leakage ratio

± 100-200

± 200-400

± 400-800 NOTE 1: Void

Adjacent Channel Leakage power Ratio (ACLR) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency. ACLR requirement is specified for a scenario in which adjacent carrier is another NR channel.

NR Adjacent Channel Leakage power Ratio ( $NR_{ACLR}$ ) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency at nominal channel spacing. The assigned NR channel power and adjacent NR channel power are measured with rectangular filters with measurement bandwidths specified in Table 6.5.2.3-1.

If the measured adjacent channel power is greater than -35 dBm then the  $NR_{ACLR}$  shall be higher than the value specified in Table 6.5.2.3-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

Table 6.5.2.3-1: General requirements for NR<sub>ACLR</sub>

	Channel bandwidth / NR <sub>ACLR</sub> / Measurement bandwidth						
	50 100 MHz MHz		200 MHz	400 MHz			
NR <sub>ACLR</sub> for band n257, n258, n261	17 dB	17 dB	17 dB	17 dB			
NR <sub>ACLR</sub> for band n260	16 dB	16 dB	16 dB	16 dB			
NR channel measurement bandwidth	47.52 MHz	95.04 MHz	190.08 MHz	380.16 MHz			
Adjacent channel centre frequency offset (MHz)	+50 / -50	+100.0 / -100.0	+200 / -200	+400 / -400			

## 6.5.3 Spurious emissions

Spurious emissions are emissions which are caused by unwanted transmitter effects such as harmonics emission, parasitic emissions, intermodulation products and frequency conversion products, but exclude out of band emissions unless otherwise stated. The spurious emission limits are specified in terms of general requirements in line with SM.329 [7] and NR operating band requirement to address UE co-existence. Spurious emissions are measured as TRP.

To improve measurement accuracy, sensitivity and efficiency, the resolution bandwidth may be smaller than the measurement bandwidth. When the resolution bandwidth is smaller than the measurement bandwidth, the result should be integrated over the measurement bandwidth in order to obtain the equivalent noise bandwidth of the measurement bandwidth.

Unless otherwise stated, the spurious emission limits apply for the frequency ranges that are more than  $F_{OOB}$  (MHz) in Table 6.5.3-1 starting from the edge of the assigned NR channel bandwidth. The spurious emission limits in Table 6.5.3-2 apply for all transmitter band configurations (NRB) and channel bandwidths. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Table 6.5.3-1: Boundary between NR out of band and spurious emission domain

Channel bandwidth	50	100	200	400
	MHz	MHz	MHz	MHz
OOB boundary F <sub>OOB</sub> (MHz)	100	200	400	800

Table 6.5.3-2: Spurious emissions limits

Frequency Range	Maximum Level	Measurement bandwidth
30 MHz ≤ f < 1000 MHz	-36 dBm	100 kHz
1 GHz ≤ f < 12.75 GHz	-30 dBm	1 MHz
12.75 GHz ≤ f ≤ 2 <sup>nd</sup> harmonic of the upper frequency edge of the UL operating band in GHz	-13 dBm	1 MHz

#### 6.5.3.1 Spurious emission band UE co-existence

This clause specifies the requirements for the specified NR band, for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Table 6.5.3.1-1: Requirements

Spurious emission						
Protected band/frequency range	Frequency range (MHz)		Maximum Level (dBm)	MBW (MHz)		
NR Band n260	F <sub>DL_low</sub>	-	F <sub>DL_high</sub>	-2	100	
Frequency range	57000	-	66000	2	100	
Frequency range	57000	-	66000	2	100	
NR Band 257	F <sub>DL_low</sub>	-	FDL_high	-5	100	
NR Band 261	$F_{DL\_low}$	-	$F_{DL\_high}$	-5	100	
Frequency range	57000	-	66000	2	100	
NR Band 260	$F_{DL\_low}$	-	$F_{DL\_high}$	-2	100	
Frequency range	57000	-	66000	2	100	
	NR Band n260 Frequency range Frequency range NR Band 257 NR Band 261 Frequency range NR Band 260	Protected band/frequency range         Frequency           NR Band n260         FDL_low           Frequency range         57000           Frequency range         57000           NR Band 257         FDL_low           NR Band 261         FDL_low           Frequency range         57000           NR Band 260         FDL_low	Protected band/frequency range         Frequency (MHz           NR Band n260         F <sub>DL_low</sub> -           Frequency range         57000 -           Frequency range         57000 -           NR Band 257         F <sub>DL_low</sub> -           NR Band 261         F <sub>DL_low</sub> -           Frequency range         57000 -           NR Band 260         F <sub>DL_low</sub> -	Protected band/frequency range         Frequency range (MHz)           NR Band n260         FDL_low         -         FDL_high           Frequency range         57000         -         66000           Frequency range         57000         -         66000           NR Band 257         FDL_low         -         FDL_high           NR Band 261         FDL_low         -         FDL_high           Frequency range         57000         -         66000           NR Band 260         FDL_low         -         FDL_high	Protected band/frequency range         Frequency range (MHz)         Maximum Level (dBm)           NR Band n260         FDL_low         - FDL_high         -2           Frequency range         57000 - 66000         2           Frequency range         57000 - 66000         2           NR Band 257         FDL_low - FDL_high         -5           NR Band 261         FDL_low - FDL_high         -5           Frequency range         57000 - 66000         2           NR Band 260         FDL_low - FDL_high         -2	

NOTE 1: F<sub>DL\_low</sub> and F<sub>DL\_high</sub> refer to each NR frequency band specified in Table 5.2-1

NOTE 2: Void

## 6.5.3.2 Additional spurious emissions

#### 6.5.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

#### 6.5.3.2.2 Additional spurious emission requirements for NS 201

When "NS\_201" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.2-1. This requirement also applies for the frequency ranges that are less than  $F_{OOB}$  (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth.

Table 6.5.3.2.2-1: Additional requirements (NS\_201)

Frequency band (GHz)	Channel bandwidth / Spectrum emission limit (dBm)		Measurement bandwidth	NOTE		
	50 MHz	100 MHz	200 MHz	400 MHz		
23.6 ≤ f ≤ 24	-8	-8	-8	-8	200 MHz	1

NOTE 1: The protection of frequency range 23600 - 24000 MHz is meant for protection of satellite passive services.

## 6.5A Output RF spectrum emissions for CA

## 6.5A.1 Occupied bandwidth for CA

For intra-band contiguous carrier aggregation, the occupied bandwidth is a measure of the bandwidth containing 99 % of the total integrated power of the transmitted spectrum. The occupied bandwidth for CA shall be less than the aggregated channel bandwidth defined in subclause 5.5A.

The occupied bandwidth for CA is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction.

#### 6.5A.2 Out of band emissions

#### 6.5A.2.1 Spectrum emission mask for CA

The requirement specified in this section shall apply if the UE has at least one of UL or DL configured for CA or if the UE is configured for single CC operation with different channel bandwidths in UL and DL carriers.

For intra-band contiguous carrier aggregation, the spectrum emission mask of the UE applies to frequencies ( $\Delta f_{OOB}$ ) starting from the  $\pm$  edge of the aggregated channel bandwidth (Table 5.3A.5-1). For any bandwidth class defined in Table 5.3A.5-1, the UE emission shall not exceed the levels specified in Table 6.5A.2.1-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

Table 6.5A.2.1-1: General NR spectrum emission mask for intra-band contiguous CA in frequency range 2

Δf <sub>OOB</sub> (MHz)	Any carrier aggregation bandwidth class	Measurement bandwidth
± 0-0.1*BW <sub>Channel_CA</sub>	-5	1 MHz
± 0.1*BWChannel_CA -	-13	1 MHz
2*BWChannel CA		

NOTE 1: If carrier leakage or I/Q image lands inside the spectrum occupied by the configured UL and DL CCs, exception to the general spectrum emission mask limit applies. For carrier leakage the requirements specified in section 6.4A.2.2 shall apply. For I/Q image the requirements specified in section 6.4A.2.3 shall apply.

## 6.5A.2.3 Adjacent channel leakage ratio for CA

For intra-band contiguous carrier aggregation, the carrier aggregation NR adjacent channel leakage power ratio (CA  $NR_{ACLR}$ ) is the ratio of the filtered mean power centred on the aggregated channel bandwidth to the filtered mean power centred on an adjacent aggregated channel bandwidth at nominal channel spacing. The assigned aggregated channel bandwidth power and adjacent aggregated channel bandwidth power are measured with rectangular filters with measurement bandwidths specified in 6.5A.2.3-1. If the measured adjacent channel power is greater than -35 dBm then the  $NR_{ACLR}$  shall be higher than the value specified in Table 6.5A.2.3-1.

Table 6.5A.2.3-1: General requirements for CA NR<sub>ACLR</sub>

	CA bandwidth class / CA NR <sub>ACLR</sub> / Measurement bandwidth			
	Any CA bandwidth class			
CA NR <sub>ACLR</sub> for band n257, n258, n261	17 dB			
CA NR <sub>ACLR</sub> for band n260	16 dB			
NR channel measurement bandwidth <sup>1</sup>	BW <sub>Channel_CA</sub> - GB <sub>Channel(1)</sub> - GB <sub>Channel(2)</sub>			
NOTE 1: The GB <sub>Channel(i)</sub> is the minimum guard band of the component carriers at the lower edge				
F <sub>edge, low</sub> and the upper edge F <sub>edge,high</sub> o	f the sub-block respectively.			

## 6.5A.3 Spurious emissions for CA

This clause specifies the spurious emission requirements for carrier aggregation.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

For intra-band contiguous carrier aggregation, the spurious emission limits apply for the frequency ranges that are more than  $F_{OOB}$  (MHz) from the edge of the aggregated channel bandwidth, where  $F_{OOB}$  is defined as the twice the aggregated channel bandwidth. For frequencies  $\Delta f_{OOB}$  greater than  $F_{OOB}$ , the spurious emission requirements in Table 6.5.3-2 are applicable. If carrier leakage or I/Q image lands inside the spectrum occupied by the configured UL and DL CCs, exception to the spurious emissions requirement applies. For carrier leakage the requirements specified in section 6.4A.2.2 shall apply. For I/Q image the requirements specified in section 6.4A.2.3 shall apply.

#### 6.5A.3.1 Spurious emission band UE co-existence for CA

This clause specifies the requirements for the specified carrier aggregation configurations for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

For intra-band contiguous carrier aggregation, the requirements in Table 6.5A.3-1 apply.

Table 6.5A.3-1: Requirements for CA

UL CA for	Spurious emission						
any CA bandwidth class	Protected band / frequency range		Frequency range (MHz)		Maximum Level (dBm)	MBW (MHz)	NOTE
	NR Band n260	F <sub>DL_low</sub>	•	F <sub>DL_high</sub>	-2	100	
CA_n257	Frequency range	23600	-	24000	TBD	200	2
	Frequency range	57000	-	66000	2	100	
CA 5250	Frequency range	23600	-	24000	TBD	200	2
CA_n258	Frequency range	57000	-	66000	2	100	
	NR Band 257	F <sub>DL_low</sub>	-	F <sub>DL_high</sub>	-5	100	
CA n260	NR Band 261	F <sub>DL_low</sub>	-	F <sub>DL_high</sub>	-5	100	
CA_IIZ00	Frequency range	23600	-	24000	TBD	200	2
	Frequency range	57000	-	66000	2	100	
	NR Band 260	$F_{DL\_low}$	-	F <sub>DL_high</sub>	-2	100	
CA_n261	Frequency range	23600	-	24000	TBD	200	2
	Frequency range	57000	-	66000	2	100	

NOTE 1: F<sub>DL\_low</sub> and F<sub>DL\_high</sub> refer to each NR frequency band specified in Table 5.2-1

NOTE 2: The protection of frequency range 23600-2400MHz is meant for protection of satellite passive services.

## 6.5A.3.2 Additional spurious emissions

#### 6.5A.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

#### 6.5A.3.2.2 Additional spurious emission requirements for CA NS 201

When "CA\_NS\_201" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.2-1. This requirement also applies for the frequency ranges that are less than  $F_{OOB}$  (MHz) as defined in section 6.5A.3.

## 6.5D Output RF spectrum emissions for UL MIMO

## 6.5D.1 Occupied bandwidth for UL MIMO

For UE(s) supporting UL MIMO, the occupied bandwidth requirement in subclause 6.5.1 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 6.5D.2 Out of band emissions for UL MIMO

For UE(s) supporting UL MIMO, the out of band emissions requirements in subclause 6.5.2 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 6.5D.3 Spurious emissions for UL MIMO

For UE(s) supporting UL MIMO, the spurious emissions requirements in subclause 6.5.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 6.6 Beam correspondence

#### 6.6.1 General

Beam correspondence is the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping. The beam correspondence requirement is satisfied assuming the presence of both SSB and CSI-RS signals and Type D QCL is maintained between SSB and CSI-RS.

- 6.6.2 Beam correspondence for power class 1
- 6.6.3 Beam correspondence for power class 2
- 6.6.4 Beam correspondence for power class 3

#### 6.6.4.1 General

The beam correspondence requirement for power class 3 UEs consists of three components: UE minimum peak EIRP (as defined in Clause 6.2.1.3), UE spherical coverage (as defined in Clause 6.2.1.3), and beam correspondence tolerance (as defined in Clause 6.6.4.2). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability, as defined in TS 38.306 [14]:

- If [bit-1], the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If [bit-0], the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].

## 6.6.4.2 Beam correspondence tolerance for power class 3

The beam correspondence tolerance requirement  $\Delta EIRP_{BC}$  for power class 3 UEs is defined based on a percentile of the distribution of  $\Delta EIRP_{BC}$ , defined as  $\Delta EIRP_{BC}$  =  $EIRP_2$  -  $EIRP_1$  over the link angles spanning a subset of the spherical coverage grid points, such that

- EIRP<sub>1</sub> is the total EIRP in dBm calculated based on the beam the UE chooses autonomously (corresponding beam) to transmit in the direction of the incoming DL signal, which is based on beam correspondence without relying on UL beam sweeping.
- EIRP<sub>2</sub> is the best total EIRP (beam yielding highest EIRP in a given direction) in dBm which is based on beam correspondence with relying on UL beam sweeping.
- The link angles are the ones corresponding to the top N<sup>th</sup> percentile of the EIRP<sub>2</sub> measurement over the whole sphere, where the value of N is according to the test point of EIRP spherical coverage requirement for power class 3, i.e. N = 50.
- The side condition for SSB and CSI-RS are TBD.

For power class 3 UEs, the requirement is fulfilled if the UE's corresponding UL beams satisfy the maximum limit in Table 6.6.4.2-1.

Table 6.6.4.2-1: UE beam correspondence tolerance for power class 3

Operating band	Max ∆EIRP <sub>BC</sub> at 85 <sup>th</sup> %-tile ∆EIRP <sub>BC</sub> CDF (dB)
n257	[3.0]
n258	[3.0]
n260	[3.2]
n261	[3.0]
	nents in this table are verified ormal temperature conditions as

## 6.6.5 Beam correspondence for power class 4

# 6.6A Beam correspondence for CA

For intra-band CA in FR2, the same beam correspondence relationship for beam management is supported across CCs in Rel-15 and no requirement is specified. Beam correspondence performance for intra-band CA is fulfilled if the beam correspondence requirements defined in section 6.6 is met for non-CA case.

## 7 Receiver characteristics

## 7.1 General

Unless otherwise stated, the receiver characteristics are specified over the air (OTA). The reference receive sensitivity (REFSENS) is defined assuming a 0 dBi reference antenna located at the center of the quiet zone.

## 7.2 Diversity characteristics

The minimum requirements on effective isotropic sensitivity (EIS) apply to two measurements, corresponding to DL signals in orthogonal polarizations.

## 7.3 Reference sensitivity

#### 7.3.1 General

The reference sensitivity power level REFSENS is defined as the EIS level at the centre of the quiet zone in the RX beam peak direction, at which the throughput shall meet or exceed the requirements for the specified reference measurement channel.

## 7.3.2 Reference sensitivity power level

## 7.3.2.1 Reference sensitivity power level for power class 1

The throughput shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A3.2 (with one sided dynamic OCNG Pattern OP.1 FDD/TDD for the DL-signal) with peak reference sensitivity specified in Table 7.3.2.1-1. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link Angle).

REFSENS (dBm) / Channel bandwidth Operating band 50 MHz 100 MHz 200 MHz 400 MHz n257 -97.5 -94.5 -91.5 -88.5 -94.5 n258 -97.5 -91.5 -88.5 n260 -94.5 -91.5 -88.5 -85.5 -97.5 -94.5 n261 -91.5 -88.5 The transmitter shall be set to Pumax as defined in subclause 6.2.4

Table 7.3.2.1-1: Reference sensitivity for power class 1

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Table 7.3.2.1-2: Uplink configuration for reference sensitivity

Operating	NR Band / Channel bandwidth / NRB / SCS / Duplex mode					
Operating band	50 MHz	100 MHz	200 MHz	400 MHz	scs	Duplex Mode
n257	32	64	128	256	120 kHz	TDD
n258	32	64	128	256	120 kHz	TDD
n260	32	64	128	256	120 kHz	TDD
n261	32	64	128	256	120 kHz	TDD

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

Table 7.3.2.1-3: Network signaling value for reference sensitivity

Operating band	Network Signalling value
n258	NS_201

## 7.3.2.2 Reference sensitivity power level for power class 2

The throughput shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A.3.2 (with one sided dynamic OCNG Pattern OP.1 FDD/TDD for the DL-signal) with peak reference sensitivity specified in Table 7.3.2.2-1. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link Angle).

Table 7.3.2.2-1: Reference sensitivity for power class 2

Operating band	REFSENS (dBm) / Channel bandwidth					
	50 MHz	50 MHz 100 MHz 200 MHz 400 MH				
n257	-92.0	-89.0	-86.0	-83.0		
n258	-92.0	-89.0	-86.0	-83.0		
n261	-92.0	-89.0	-86.0	-83.0		
NOTE 1: The trans	NOTE 1: The transmitter shall be set to P <sub>UMAX</sub> as defined in subclause 6.2.4					

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

#### 7.3.2.3 Reference sensitivity power level for power class 3

The throughput shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A.3.2 (with one sided dynamic OCNG Pattern OP.1 FDD/TDD for the DL-signal) with peak reference sensitivity specified in Table 7.3.2.3-1. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link Angle).

For the UEs that support multiple FR2 bands, the minimum requirement for Reference sensitivity in Table 7.3.2.3-1 shall be increased per band, respectively, by the reference sensitivity relaxation parameter  $\Delta MB_{P,n}$  as specified in section 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.2.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.2.3-1 and Table 6.2.1.3-4.

Table 7.3.2.3-1: Reference sensitivity

Operating band	REFSENS (dBm) / Channel bandwidth					
	50 MHz	50 MHz 100 MHz 200 MHz 4				
n257	-88.3	-85.3	-82.3	-79.3		
n258	-88.3	-85.3	-82.3	-79.3		
n260	-85.7	-82.7	-79.7	-76.7		
n261	-88.3	-85.3	-82.3	-79.3		
NOTE 1: The trans	NOTE 1: The transmitter shall be set to P <sub>UMAX</sub> as defined in subclause 6.2.4					

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

## 7.3.2.4 Reference sensitivity power level for power class 4

The throughput shall be  $\geq$  95% of the maximum throughput of the reference measurement channels as specified in Annex A.3.2 (with one sided dynamic OCNG Pattern OP.1 FDD/TDD for the DL-signal) with peak reference sensitivity specified in Table 7.3.2.4-1. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link Angle).

Operating band REFSENS (dBm) / Channel bandwidth 50 MHz 200 MHz 400 MHz 100 MHz n257 -97.0 -94.0 -91.0 -88.0 n258 -97.0 -94.0 -91.0 -88.0 n260 -95.0 -92.0 -89.0 -86.0 n261 -97.0 -94.0 -91.0 -88.0 NOTE 1: The transmitter shall be set to Pumax as defined in subclause 6.2.4

Table 7.3.2.4-1: Reference sensitivity for power class 4

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

### 7.3.3 Void

## 7.3.4 EIS spherical coverage

#### 7.3.4.1 EIS spherical coverage for power class 1

The reference measurement channels and throughput criterion shall be as specified in section 7.3.2.1

The maximum EIS at the 85<sup>th</sup> percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.1-1 below. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

Table 7.3.4.1-1: EIS spherical coverage for power class 1

Operating	EIS at 85th %-tile CCDF (dBm) / Channel bandwidth					
band	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-89.5	-86.5	-83.5	-80.5		
n258	-89.5	-86.5	-83.5	-80.5		
n260	-86.5	-83.5	-80.5	-77.5		
n261	-89.5	-86.5	-83.5	-80.5		

NOTE 1: The transmitter shall be set to PuMAX as defined in subclause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

## 7.3.4.2 EIS spherical coverage for power class 2

The reference measurement channels and throughput criterion shall be as specified in section 7.3.2.2

The maximum EIS at the 60<sup>th</sup> percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.2-1 below. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

Table 7.3.4.2-1: EIS spherical coverage for power class 2

Operating band	EIS at 60th %-tile CCDF (dBm) / Channel bandwidth						
	50 MHz	50 MHz 100 MHz 200 MHz 400 MF					
n257	-81.0	-78.0	-75.0	-72.0			
n258	-81.0	-78.0	-75.0	-72.0			
n261	-81.0	-78.0	-75.0	-72.0			

NOTE 1: The transmitter shall be set to Pumax as defined in subclause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

#### 7.3.4.3 EIS spherical coverage for power class 3

The reference measurement channels and throughput criterion shall be as specified in section 7.3.2.3

The maximum EIS at the 50<sup>th</sup> percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.3-1 below. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

For the UEs that support multiple FR2 bands, the minimum requirement for EIS spherical coverage in Table 7.3.4.3-1 shall be increased per band, respectively, by the EIS spherical coveragerelaxation parameter  $\Delta MB_{S,n}$  as specified in section 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.4.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.4.3-1 and Table 6.2.1.3-4.

Table 7.3.4.3-1: EIS spherical coverage for power class 3

Operating band	EIS at 50th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-77.4	-74.4	-71.4	-68.4		
n258	-77.4	-74.4	-71.4	-68.4		
n260	-73.1	-70.1	-67.1	-64.1		
n261	-77.4	-74.4	-71.4	-68.4		

NOTE 1: The transmitter shall be set to Pumax as defined in subclause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

#### 7.3.4.4 EIS spherical coverage for power class 4

The reference measurement channels and throughput criterion shall be as specified in section 7.3.2.4

The maximum EIS at the 20<sup>th</sup> percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.4-1 below. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

Table 7.3.4.4-1: EIS spherical coverage for power class 4

Operating band	EIS at 20th %-tile CCDF (dBm) / Channel bandwidth				
	50 MHz	100 MHz	200 MHz	400 MHz	
n257	-88.0	-85.0	-82.0	-79.0	
n258	-88.0	-85.0	-82.0	-79.0	
n260	-83.0	-80.0	-77.0	-74.0	
n261	-88.0	-85.0	-82.0	-79.0	

NOTE 1: The transmitter shall be set to Pumax as defined in subclause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS\_200 (Table 6.2.3-1) configured.

## 7.3A Reference sensitivity for CA

#### 7.3A.1 General

## 7.3A.2 Reference sensitivity power level for CA

#### 7.3A.2.1 Intra-band contiguous CA

For each component carrier in the intra-band contiguous carrier aggregation, the throughput in QPSK R = 1/3 shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal) with peak reference sensitivity values determined from section 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.1-1.

Table 7.3A.2.1-1: ΔR<sub>IB</sub> EIS Relaxation for CA operation by aggregated channel bandwidth

Aggregated Channel BW 'BWchannel_CA' (MHz)	ΔR <sub>IB</sub> (dB)
BW <sub>Channel_CA</sub> ≤ 800	0.0
800 < BW <sub>Channel_CA</sub> ≤ 1200	0.5

### 7.3A.2.2 Intra-band non-contiguous CA

For each component carrier in the intra-band non-contiguous carrier aggregation, the throughput in QPSK R=1/3 shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal) with peak reference sensitivity values determined from section 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.2-1. The cumulative aggregated channel bandwidth is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs.

Table 7.3A.2.2-1: ΔR<sub>IB</sub> EIS Relaxation for CA operation by cumulative aggregated channel bandwidth

Cumulative Aggregated Channel BW (MHz)	ΔR <sub>IB</sub> (dB)
≤ 800	0.0
[> 800 and ≤ 1400]	[0.5]

## 7.3D Reference sensitivity for UL MIMO

For UL MIMO, the reference sensitivity requirements in subclause 7.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 7.4 Maximum input level

The maximum input level is defined as the maximum mean power, for which the throughput shall meet or exceed the minimum requirements for the specified reference measurement channel.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved.

The throughput shall be  $\geq 95$  % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal) with parameters specified in Table 7.4.-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.4-1: Maximum input level

		Channel bandwidth			
Rx Parameter	Units	50 MHz	100 MHz	200 MHz	400 MHz
Power in transmission bandwidth configuration	dBm	-25 (NOTE 2)			

NOTE 1: The transmitter shall be set to 4 dB below the lower limit of the P<sub>UMAX,f,c</sub> inequality defined in subclause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.

NOTE 2: Reference measurement channel is specified in Annex A.3.3.2: QPSK, R=1/3 variant with one sided dynamic OCNG Pattern as described in Annex A.

Table 7.4-2: Void

## 7.4A Maximum input level for CA

For carrier aggregation the input level is defined as the cumulative received power, summed over the transmission bandwidth configurations of each active DL CC. All DL CCs shall be active throughout the test. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. At the maximum input level, the specified relative throughput shall meet or exceed the minimum requirements for the specified reference measurement channel over each component carrier. The minimum requirement is specified in Table 7.4A-1.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.4A-1: Maximum input level for CA

Rx Parameter	Units	All CA configurations included in BCS 0			
Power summed over transmission bandwidth configurations of all active DL CCs	dBm	-25 (NOTE 2)			
NOTE 4. The transmitter shall be set to 4 dD below the lower limit of the D inequality defined in					

NOTE 1: The transmitter shall be set to 4 dB below the lower limit of the P<sub>UMAX,f,c</sub> inequality defined in subclause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2

NOTE 2: Reference measurement channel in each CC is specified in Annex A.3.3.2: QPSK, R=1/3 variant with one sided dynamic OCNG Pattern as described in Annex A.

Table 7.4A-2: Void

## 7.4D Maximum input level for UL MIMO

For UL MIMO, the maximum input level requirements in subclause 7.4 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 7.5 Adjacent channel selectivity

Adjacent Channel Selectivity (ACS) is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an adjacent channel signal at a given frequency offset from the centre frequency of the assigned channel. ACS is the ratio of the receive filter attenuation on the assigned channel frequency to the receive filter attenuation on the adjacent channel(s).

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

The UE shall fulfil the minimum requirement specified in Table 7.5-1 for all values of an adjacent channel interferer up to -25 dBm. However, it is not possible to directly measure the ACS, instead the lower and upper range of test parameters are chosen in Table 7.5-2 and Table 7.5-3 where the throughput shall be  $\geq 95$  % of the maximum throughput of the reference measurement channels as specified in Annexes A.3.2, with QPSK, R = 1/3 and one sided dynamic OCNG Pattern for the DL-signal as described in Annex A. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Operating band Adjacent channel selectivity / Channel bandwidth Units 200 400 50 100 MHz MHz MHz MHz n257, n258, dB 23 23 23 23 n261 dB 22 22 22 22 n260

Table 7.5-1: Adjacent channel selectivity

Table 7.5-2: Test parameters for adjacent channel selectivity, Case 1

Rx Parameter	Units	Channel bandwidth				
		50 MHz	100 MHz	200 MHz	400 MHz	
Power in Transmission Bandwidth Configuration	dBm	REFSENS + 14 dB				
P <sub>Interferer</sub> for band n257, n258, n261	dBm	REFSENS + 35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB	
P <sub>Interferer</sub> for band n260	dBm	REFSENS + 34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB	
BW <sub>Interferer</sub>	MHz	50	100	200	400	
F <sub>Interferer</sub> (offset)	MHz	50 / -50 NOTE 3	100 / -100 NOTE 3	200 / -200 NOTE 3	400 / -400 NOTE 3	

NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.2 with one sided dynamic OCNG Pattern as described in Annex A.3.2 and set-up according to Annex C.

NOTE 2: The REFSENS power level is specified in Section 7.3.2, which are applicable to different UE power classes.

NOTE 3: The absolute value of the interferer offset F<sub>Interferer</sub> (offset) shall be further adjusted to (CEIL(|F<sub>Interferer</sub>|/SCS) + 0.5)\*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.

Table 7.5-3: Test parameters for adjacent channel selectivity, Case 2

Rx Parameter	Units		Channel bandwidth		
		50 MHz	100 MHz	200 MHz	400 MHz
Power in Transmission Bandwidth Configuration for band n257, n258, n261	dBm	-46.5	-46.5	-46.5	-46.5
Power in Transmission Bandwidth Configuration for band n260	dBm	-45.5	-45.5	-45.5	-45.5
PInterferer	dBm			-25	•
BW <sub>Interferer</sub>	MHz	50	100	200	400
Finterferer (offset)	MHz	50 / -50 NOTE 2	100 / -100 NOTE 2	200 / -200 NOTE 2	400 / -400 NOTE 2

NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern TDD as described in Annex A and set-up according to Annex C.

NOTE 2: The absolute value of the interferer offset F<sub>Interferer</sub> (offset) shall be further adjusted to (CEIL(|F<sub>Interferer</sub>|/SCS) + 0.5)\*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.

## 7.5A Adjacent channel selectivity for CA

For intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The UE shall fulfil the minimum requirement specified in Table 7.5.1A-1 for an adjacent channel interferer on either side of the aggregated downlink signal at a specified frequency offset and for an interferer power up to -25 dBm.

The throughput of each carrier shall be  $\geq$  95% of the maximum throughput of the reference measurement channels as specified in Annexes A.3.2 with one sided dynamic OCNG Pattern for the DL-signal as described in Annex A. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.5A-1: Adjacent channel selectivity for CA

Operating band	Units	Adjacent channel selectivity / CA bandwidth class All CA bandwidth class
n257, n258, n261	dB	23
n260	dB	22

Table 7.5A-2: Adjacent channel selectivity test parameters for CA, Case 1

Rx Parameter	Units	All CA bandwidth Classes
Pw in Transmission Bandwidth Configuration, per CC		REFSENS + 14 dB
P <sub>Interferer</sub> for band n257, n258, n261	dBm	Aggregated power + 21.5
P <sub>Interferer</sub> for band n260	dBm	Aggregated power + 20.5
BW <sub>Interferer</sub>	MHz	BWchannel_CA
F <sub>Interferer</sub> (offset)	MHz	BW <sub>Channel_CA</sub>

NOTE 1:	The interferer consists of the Reference measurement channel specified in Annex
	3.2 with one sided dynamic OCNG Pattern as described in Annex A and set-up
	according to Annex C.
NOTE 2:	The Finterferer (offset) is the frequency separation between the center of the
	aggregated CA bandwidth and the center frequency of the Interferer signal
NOTE 3:	The absolute value of the interferer offset F <sub>Interferer</sub> (offset) shall be further adjusted to
	(CEIL( F <sub>Interferer</sub>  /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the
	wanted signal in MHz. Wanted and interferer signal have same SCS.

Table 7.5A-3: Adjacent channel selectivity test parameters for CA, Case 2

Rx Parameter	Units	All CA bandwidth classes	
Pw in Transmission Bandwidth Configuration, aggregated power for band n257, n258, n261	dBm	- 46.5	
Pw in Transmission Bandwidth Configuration, aggregated power for band n260	dBm	- 45.5	
Pinterferer	dBm	- 25	
BWInterferer	MHz	BW <sub>Channel_</sub> CA	
Finterferer (offset)	MHz	BW <sub>Channel_CA</sub>	
NOTE 3  NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern as described in Annex A and set-up according to Annex C.  NOTE 2: The F <sub>interferer</sub> (offset) is the frequency separation between the center of the aggregated CA bandwidth and the center frequency of the Interferer signal NOTE 3: The absolute value of the interferer offset F <sub>Interferer</sub> (offset) shall be further adjusted to (CEIL( F <sub>Interferer</sub>  /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the			

For intra-band non-contiguous carrier aggregation with two component carriers, two different requirements apply for out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier as specified in subclauses 7.5. For in-gap, the requirement applies if the following minimum gap condition is met:

wanted signal in MHz. Wanted and interferer signal have same SCS.

$$\Delta f_{ACS} \ge BW_1/2 + BW_2/2 + \max(BW_1, BW_2),$$

where  $\Delta f_{ACS}$  is the frequency separation between the center frequencies of the component carriers and BW<sub>k</sub>/2 are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirements specified in subclauses 7.5 for each component carrier considered. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met.

For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active.

# 7.5D Adjacent channel selectivity for UL MIMO

For UL MIMO, the adjacent channel selectivity requirements in subclause 7.5 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

# 7.6 Blocking characteristics

#### 7.6.1 General

The blocking characteristic is a measure of the receiver's ability to receive a wanted signal at its assigned channel frequency in the presence of an unwanted interferer on frequencies other than those of the spurious response or the

adjacent channels, without this unwanted input signal causing a degradation of the performance of the receiver beyond a specified limit. The blocking performance shall apply at all frequencies except those at which a spurious response occurs.

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

## 7.6.2 In-band blocking

In-band blocking is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel.

The throughput shall be  $\geq$  95 % of the maximum throughput of the reference measurement channels as specified in Annex A with one sided dynamic OCNG Pattern for the DL-signal as described in Annex A. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.6.2-1: In band blocking requirements

Rx parameter	Units		Channel I	Channel bandwidth			
-		50 MHz	100 MHz	200 MHz	400 MHz		
Power in Transmission Bandwidth Configuration	dBm		REFSEN	S + 14 dB			
BW <sub>Interferer</sub>	MHz	50	100	200	400		
P <sub>Interferer</sub> for bands n257, n258, n261	dBm	REFSENS + 35.5 dB	REFSENS + 35.5 dB	REFSENS + 35.5 dB	REFSENS + 35.5 dB		
P <sub>Interferer</sub> for band n260	dBm	REFSENS + 34.5 dB	REFSENS + 34.5 dB	REFSENS + 34.5 dB	REFSENS + 34.5 dB		
Floffset	MHz	≤ -100 & ≥ 100 NOTE 5	≤ -200 & ≥ 200 NOTE 5	≤ -400 & ≥ 400 NOTE 5	≤ -800 & ≥ 800 NOTE 5		
FInterferer	MHz	F <sub>DL_low</sub> + 25 to F <sub>DL_high</sub> - 25	F <sub>DL_low</sub> + 50 to F <sub>DL_high</sub> - 50	F <sub>DL_low</sub> + 100 to F <sub>DL high</sub> - 100	F <sub>DL_low</sub> + 200 to F <sub>DL_high</sub> - 200		

- NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.2 with one sided dynamic OCNG Pattern as described in Annex A and set-up according to Annex C.
- NOTE2: The REFSENS power level is specified in Section 7.3.2, which are applicable according to different UE power classes.
- NOTE 3: The wanted signal consists of the reference measurement channel specified in Annex A.3.2 QPSK, R = 1/3 with one sided dynamic OCNG pattern as described in Annex A and set-up according to Annex C.
- NOTE 4: Floffset is the frequency separation between the center of the aggregated CA bandwidth and the center frequency of the Interferer signal.
- NOTE 5: The absolute value of the interferer offset F<sub>loffset</sub> shall be further adjusted (CEIL(|F<sub>Interferer</sub>|/SCS) + 0.5)\*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.
- NOTE 6: F<sub>Interferer</sub> range values for unwanted modulated interfering signals are interferer center frequencies.

#### 7.6.3 Void

## 7.6A Blocking characteristics for CA

#### 7.6A.1 General

## 7.6A.2 In-band blocking

For intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The UE shall fulfil the minimum requirement specified in Table 7.6A.2-1 for in the presence of an interferer at a given

frequency offset from the centre frequency of the assigned channel and for an interferer power up to -25 dBm. The throughput of each carrier shall be  $\geq$  95% of the maximum throughput of the reference measurement channels as specified in Annexes A.3.2 with one sided dynamic OCNG Pattern for the DL-signal as described in Annex A. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.6A.2-1: In band blocking minimum requirements for intra-band contiguous CA

Rx Parameter	Units	All CA bandwidth classes							
Power in									
Transmission		DEFORMO AA ID							
Bandwidth		REFSENS + 14 dB							
Configuration, per CC									
Pinterferer for									
band n257,	dBm	Aggregated power + 21.5							
n258, n261		1.99.09.000 F 2.100 / 2.10							
Pinterferer for	dBm	Aggregated power + 20.5							
band n260		1							
BWInterferer	MHz	BW <sub>Channel_CA</sub>							
		Q*D\M, / Q*D\M,							
Floffset	MHz	+2*BWchannel_CA / -2*BWchannel_CA							
1 Ionset	IVII IZ	NOTE 5							
	F <sub>DL_low</sub> + 0.5*BW <sub>Channel_CA</sub>								
F <sub>Interferer</sub>									
	FDL_high - 0.5*BWChannel_CA								
		onsists of the Reference measurement channel specified in Annex							
		ed dynamic OCNG Pattern as described in Annex A. and set-up							
	ng to Ani								
		power level is specified in Table 7.3.2-1.  nal consists of the reference measurement channel specified in							
		PSK, R=1/3 with one sided dynamic OCNG pattern as described in							
	nex A and set-up according to Annex C.								
		set) is the frequency separation between the center of the							
aggreg	ated CA	bandwidth and the center frequency of the Interferer signal.							
		lue of the interferer offset F <sub>Interferer</sub> (offset) shall be further adjusted to							
		SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the							
		MHz. Wanted and interferer signal have same SCS.							
NOTE 6: Finterferer frequer		alues for unwanted modulated interfering signals are interferer center							

For intra-band non-contiguous carrier aggregation with two component carriers, the requirement applies to out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier with parameters as specified in 7.6.2-1. The requirement associated to the maximum channel between across the component carriers is selected. For in-gap, the requirement shall apply if the following minimum gap condition is met:

$$\Delta f_{IBB} \ge 0.5(BW_1 + BW_2) + 2 \max(BW_1, BW_2),$$

where  $\Delta f_{IBB}$  is the frequency separation between the center frequencies of the component carriers and BW<sub>k</sub>/2 are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirement specified in Table 7.6.2-1 for each component carrier. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met. For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active.

Table 7.6A.2-2: (Void)

## 7.6D Blocking characteristics for UL MIMO

For UL MIMO, the blocking characteristics requirements in subclause 7.6 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.3-3.

## 7.7 Void

## 7.8 Void

# 7.9 Spurious emissions

The spurious emissions power is the power of emissions generated or amplified in a receiver. The spurious emissions power level is measured as TRP.

The power of any narrow band CW spurious emission shall not exceed the maximum level specified in Table 7.9-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

Table 7.9-1: General receiver spurious emission requirements

Frequency range	Measurement bandwidth	Maximum level	NOTE
30MHz ≤ f < 1GHz	100 kHz	-57 dBm	1
1GHz ≤ f ≤ 2 <sup>nd</sup> harmonic of the upper frequency edge of the DL operating band in GHz	1 MHz	-47 dBm	
NOTE 1: Unused PDCCH res	cources are padde	d with recourse	a element groups with nower level given

NOTE 1: Unused PDCCH resources are padded with resource element groups with power level given by PDCCH\_RA/RB as defined in Annex C.3.1.

## 7.10 Void

# Annex A (normative): Measurement channels

# A.1 General

- A.2 UL reference measurement channels
- A.2.1 General
- A.2.2 Void

## A.2.3 Reference measurement channels for TDD

For UL RMCs defined below, TDD slot pattern defined in Table A.2.3-1 will be used for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, TDD slot patterns defined for reference sensitivity tests in Table A.3.3.1-1 will be used.

Table A.2.3-1: Additional reference channels parameters for TDD

		Va	lue
	Parameter	SCS 60 kHz (µ=2)	SCS 120 kHz (µ=3)
UL-DL	referenceSubcarrierSpacing	60 kHz	120 kHz
configuration	dl-UL-TransmissionPeriodicity	2 ms	2 ms
	nrofDownlinkSlots	3	7
	nrofDownlinkSymbols	4	12
	nrofUplinkSlot	4	8
	nrofUplinkSymbols	40	0
	UL slot numbers	mod(slot index, 32) = {28,,31}	mod(slot index, 64) = {56,,63}

## A.2.3.1 DFT-s-OFDM Pi/2-BPSK

Table A.2.3.1-1: Reference Channels for DFT-s-OFDM pi/2-BPSK for 60 kHz SCS

Parameter	Channel bandwidth	Subcarrier Spacing	Allocated resource blocks	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transport block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulated symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits		-	Bits	
	50-200	60	1	11	pi/2 BPSK	0	1/4	32	16	2	1	132	132
	50-200	60	16	11	pi/2 BPSK	0	1/4	480	16	2	1	2024	2024
	50	60	32	11	pi/2 BPSK	0	1/4	1032	16	2	1	4224	4224
	50	60	64	11	pi/2 BPSK	0	1/4	2024	16	2	1	8448	8448
	100	60	64	11	pi/2 BPSK	0	1/4	2024	16	2	1	8448	8448
	100	60	128	11	pi/2 BPSK	0	1/4	3976	24	2	2	16896	16896
	200	60	128	11	pi/2 BPSK	0	1/4	3976	24	2	2	16896	16896
	200	60	256	11	pi/2 BPSK	0	1/4	7944	24	2	3	33792	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.1-2: Reference Channels for DFT-s-OFDM pi/2-BPSK for 120 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	DFT-s- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	pi/2 BPSK	0	1/4	32	16	2	1	132	132
	50	120	16	11	pi/2 BPSK	0	1/4	504	16	2	1	2112	2112
	50	120	32	11	pi/2 BPSK	0	1/4	1032	16	2	1	4224	4224
	100	120	32	11	pi/2 BPSK	0	1/4	1032	16	2	1	4224	4224
•	100	120	64	11	pi/2 BPSK	0	1/4	2024	16	2	1	8448	8448
•	200	120	64	11	pi/2 BPSK	0	1/4	2024	16	2	1	8448	8448
•	200	120	128	11	pi/2 BPSK	0	1/4	3976	24	2	2	16896	16896
	400	120	128	11	pi/2 BPSK	0	1/4	3976	24	2	2	16896	16896
_	400	120	256	11	pi/2 BPSK	0	1/4	7944	24	2	3	33792	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

## A.2.3.2 DFT-s-OFDM QPSK

Table A.2.3.2-1: Reference Channels for DFT-s-OFDM QPSK for 60 kHz SCS

Parameter	Channel bandwidth	Subcarrier Spacing	Allocated resource blocks	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transport block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulated symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits		-	Bits	
	50-200	60	1	11	QPSK	2	1/6	56	16	2	1	264	132
	50-200	60	16	11	QPSK	2	1/6	768	16	2	1	4048	2024
	50	60	32	11	QPSK	2	1/6	1608	16	2	1	8448	4224
	50	60	64	11	QPSK	2	1/6	3240	16	2	1	16896	8448
	100	60	64	11	QPSK	2	1/6	3240	16	2	1	16896	8448
	100	60	128	11	QPSK	2	1/6	6408	24	2	2	33792	16896
	200	60	128	11	QPSK	2	1/6	6408	24	2	2	33792	16896
	200	60	256	11	QPSK	2	1/6	12808	24	2	4	67584	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.2-2: Reference Channels for DFT-s-OFDM QPSK for 120 kHz SCS

Parameter	Channel bandwidth	Subcarrier Spacing	Allocated resource blocks	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transport block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulated symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	QPSK	2	1/6	56	16	2	1	264	132
	50	120	16	11	QPSK	2	1/6	808	16	2	1	4224	2112
	50	120	32	11	QPSK	2	1/6	1608	16	2	1	8448	4224
	100	120	20	11	QPSK	2	1/6	984	16	2	1	5060	2530
	100	120	32	11	QPSK	2	1/6	1608	16	2	1	8448	4224
	100	120	64	11	QPSK	2	1/6	3240	16	2	1	16896	8448
_	200	120	64	11	QPSK	2	1/6	3240	16	2	1	16896	8448
	200	120	128	11	QPSK	2	1/6	6408	24	2	2	33792	16896
	400	120	128	11	QPSK	2	1/6	6408	24	2	2	33792	16896
	400	120	256	11	QPSK	2	1/6	12808	24	2	4	67584	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

## A.2.3.3 DFT-s-OFDM 16QAM

Table A.2.3.3-1: Reference Channels for DFT-s-OFDM 16QAM for 60 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	DFT-s- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-200	60	1	11	16QAM	10	1/3	176	16	2	1	528	132
	50	60	32	11	16QAM	10	1/3	5632	24	1	1	16896	4224
	50	60	64	11	16QAM	10	1/3	11272	24	1	2	33792	8448
	100	60	64	11	16QAM	10	1/3	11272	24	1	2	33792	8448
	100	60	128	11	16QAM	10	1/3	22536	24	1	3	67584	16896
	200	60	128	11	16QAM	10	1/3	22536	24	1	3	67584	16896
	200	60	256	11	16QAM	10	1/3	45096	24	1	6	135168	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.3-2: Reference Channels for DFT-s-OFDM 16QAM for 120 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	DFT-s- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	16QAM	10	1/3	176	16	2	1	528	132
	50	120	16	11	16QAM	10	1/3	2792	16	2	1	8448	2112
	50	120	32	11	16QAM	10	1/3	5632	24	1	1	16896	4224
	100	120	32	11	16QAM	10	1/3	5632	24	1	1	16896	4224
	100	120	64	11	16QAM	10	1/3	11272	24	1	2	33792	8448
	200	120	64	11	16QAM	10	1/3	11272	24	1	2	33792	8448
	200	120	128	11	16QAM	10	1/3	22536	24	1	3	67584	16896
	400	120	128	11	16QAM	10	1/3	22536	24	1	3	67584	16896
	400	120	256	11	16QAM	10	1/3	45096	24	1	6	135168	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

## A.2.3.4 DFT-s-OFDM 64QAM

Table A.2.3.4-1: Reference Channels for DFT-s-OFDM 64QAM for 60 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	DFT-s- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-200	60	1	11	64QAM	18	1/2	408	16	2	1	792	132
	50	60	32	11	64QAM	18	1/2	12808	24	1	2	25344	4224
	50	60	64	11	64QAM	18	1/2	25608	24	1	4	50688	8448
	100	60	64	11	64QAM	18	1/2	25608	24	1	4	50688	8448
	100	60	128	11	64QAM	18	1/2	51216	24	1	7	101376	16896
	200	60	128	11	64QAM	18	1/2	51216	24	1	7	101376	16896
	200	60	256	11	64QAM	18	1/2	102416	24	1	13	202752	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.4-2: Reference Channels for DFT-s-OFDM 64QAM for 120 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	DFT-s- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	64QAM	18	1/2	408	16	2	1	792	132
	50	120	16	11	64QAM	18	1/2	6400	24	1	1	12672	2112
	50	120	32	11	64QAM	18	1/2	12808	24	1	2	25344	4224
	100	120	32	11	64QAM	18	1/2	12808	24	1	2	25344	4224
	100	120	64	11	64QAM	18	1/2	25608	24	1	4	50688	8448
	200	120	64	11	64QAM	18	1/2	25608	24	1	4	50688	8448
	200	120	128	11	64QAM	18	1/2	51216	24	1	7	101376	16896
	400	120	128	11	64QAM	18	1/2	51216	24	1	7	101376	16896
	400	120	256	11	64QAM	18	1/2	102416	24	1	13	202752	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

## A.2.3.5 CP-OFDM QPSK

Table A.2.3.5-1: Reference Channels for CP-OFDM QPSK for 60 kHz SCS

Parameter	Channel bandwidth	Subcarrier Spacing	Allocated resource blocks	CP- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transport block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulated symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-200	60	1	11	QPSK	2	1/6	56	16	2	1	264	132
	50-200	60	16	11	QPSK	2	1/6	768	16	2	1	4048	2024
	50	60	33	11	QPSK	2	1/6	1672	16	2	1	8712	4356
	50	60	66	11	QPSK	2	1/6	3368	16	2	1	17424	8712
	100	60	66	11	QPSK	2	1/6	3368	16	2	1	17424	8712
	100	60	132	11	QPSK	2	1/6	6536	24	2	2	34848	17424
	200	60	132	11	QPSK	2	1/6	6536	24	2	2	34848	17424
	200	60	264	11	QPSK	2	1/6	13064	24	2	4	69696	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.5-2: Reference Channels for CP-OFDM QPSK for 120 kHz SCS

Parameter	Channel bandwidth	Subcarrier Spacing	Allocated resource blocks	CP- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transport block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots(Note 4)	Total modulated symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	QPSK	2	1/6	56	16	2	1	264	132
	50	120	16	11	QPSK	2	1/6	808	16	2	1	4224	2112
	50	120	32	11	QPSK	2	1/6	1608	16	2	1	8448	4224
	100	120	33	11	QPSK	2	1/6	1672	16	2	1	8712	4356
	100	120	66	11	QPSK	2	1/6	3368	16	2	1	17424	8712
	200	120	66	11	QPSK	2	1/6	3368	16	2	1	17424	8712
	200	120	132	11	QPSK	2	1/6	6536	24	2	2	34848	17424
	400	120	132	11	QPSK	2	1/6	6536	24	2	2	34848	17424
	400	120	264	11	QPSK	2	1/6	13064	24	2	4	69696	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

#### A.2.3.6 CP-OFDM 16QAM

Table A.2.3.6-1: Reference Channels for CP-OFDM 16QAM for 60 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	CP- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-200	60	1	11	16QAM	10	1/3	176	16	2	1	528	132
	50	60	33	11	16QAM	10	1/3	5760	24	1	1	17424	4356
	50	60	66	11	16QAM	10	1/3	11528	24	1	2	34848	8712
	100	60	66	11	16QAM	10	1/3	11528	24	1	2	34848	8712
	100	60	132	11	16QAM	10	1/3	23040	24	1	3	69696	17424
	200	60	132	11	16QAM	10	1/3	23040	24	1	3	69696	17424
	200	60	264	11	16QAM	10	1/3	46104	24	1	6	139392	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.6-2: Reference Channels for CP-OFDM 16QAM for 120 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	CP- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	16QAM	10	1/3	176	16	2	1	528	132
	50	120	16	11	16QAM	10	1/3	2792	16	2	1	8448	2112
	50	120	32	11	16QAM	10	1/3	5632	24	1	1	16896	4224
	100	120	33	11	16QAM	10	1/3	5760	24	1	1	17424	4356
•	100	120	66	11	16QAM	10	1/3	11528	24	1	2	34848	8712
•	200	120	66	11	16QAM	10	1/3	11528	24	1	2	34848	8712
•	200	120	132	11	16QAM	10	1/3	23040	24	1	3	69696	17424
•	400	120	132	11	16QAM	10	1/3	23040	24	1	3	69696	17424
•	400	120	264	11	16QAM	10	1/3	46104	24	1	6	139392	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

#### A.2.3.7 CP-OFDM 64QAM

Table A.2.3.7-1: Reference Channels for CP-OFDM 64QAM for 60 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	CP- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-200	60	1	11	64QAM	19	1/2	408	16	2	1	792	132
	50	60	33	11	64QAM	19	1/2	13064	24	1	2	26136	4356
	50	60	66	11	64QAM	19	1/2	26120	24	1	4	52272	8712
	100	60	66	11	64QAM	19	1/2	26120	24	1	4	52272	8712
	100	60	132	11	64QAM	19	1/2	53288	24	1	7	104544	17424
	200	60	132	11	64QAM	19	1/2	53288	24	1	7	104544	17424
	200	60	264	11	64QAM	19	1/2	106576	24	1	13	209088	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

Table A.2.3.7-2: Reference Channels for CP-OFDM 64QAM for 120 kHz SCS

Paramete r	Channel bandwidt h	Subcarrie r Spacing	Allocate d resource blocks	CP- OFDM Symbol s per slot (Note 1)	Modulatio n	MCS Index (Note 2)	Target Coding Rate	Payload size for UL slots (Note 4)	Transpor t block CRC	LDPC Base Graph	Number of code blocks per slot for UL slots (Note 3, Note 4)	Total number of bits per slot for UL slots (Note 4)	Total modulate d symbols per slot for UL slots (Note 4)
Unit	MHz	KHz						Bits	Bits			Bits	
	50-400	120	1	11	64QAM	19	1/2	408	16	2	1	792	132
	50	120	16	11	64QAM	19	1/2	6400	24	1	1	12672	2112
	50	120	32	11	64QAM	19	1/2	12808	24	1	2	25344	4224
	100	120	33	11	64QAM	19	1/2	13064	24	1	2	26136	4356
	100	120	66	11	64QAM	19	1/2	26120	24	1	4	52272	8712
	200	120	66	11	64QAM	19	1/2	26120	24	1	4	52272	8712
	200	120	132	11	64QAM	19	1/2	53288	24	1	7	104544	17424
	400	120	132	11	64QAM	19	1/2	53288	24	1	7	104544	17424
	400	120	264	11	64QAM	19	1/2	106576	24	1	13	209088	34848

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data.

NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: UL slot numbers are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, UL slot numbers are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

## A.3 DL reference measurement channels

#### A.3.1 General

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 are applicable for measurements of the Receiver Characteristics (clause 7).

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 also apply for the modulated interferer used in Clauses 7.5 and 7.6 with test specific bandwidths.

Table A.3.1-1: Test parameters

Parameter	Unit	Value
CORESET frequency domain allocation		Full BW
CORESET time domain allocation		2 OFDM symbols at the begin of each slot
PDSCH mapping type		Туре А
PDSCH start symbol index (S)		2
Number of consecutive PDSCH symbols (L)		12
PDSCH PRB bundling	PRBs	2
Dynamic PRB bundling		false
MCS table for TBS determination		64QAM
Overhead value for TBS determination		0
First DMRS position for Type A PDSCH mapping		2
DMRS type		Type 1
Number of additional DMRS		2
FDM between DMRS and PDSCH		Disable
TRS configuration		1 slot, periodicity 10 ms, offset 0
PTRS configuration		PTRS is not configured

#### A.3.2 Void

#### A.3.3 DL reference measurement channels for TDD

#### A.3.3.1 General

Table A.3.3.1-1. Additional test parameters for TDD

	Doromotor	Va	lue	
	Parameter	SCS 60 kHz (μ=2)	SCS 120 kHz (µ=3)	
UL-DL	referenceSubcarrierSpacing	60 kHz	120 kHz	
configuration	dl-UL-	1.25 ms	0.625 ms	
	TransmissionPeriodicity			
	nrofDownlinkSlots	3	3	
nrofDownlinkSymbols		4	10	
	nrofUplinkSlot	1	1	
	nrofUplinkSymbols	4	2	
Number	of HARQ Processes	8	8	
	K1 value	K1 = 4  if mod(i,5) = 0	K1 = 4  if mod(i,5) = 0	
		K1 = 3  if  mod(i,5) = 1	K1 = 3  if  mod(i,5) = 1	
		K1 = 2  if  mod(i,5) = 2	K1 = 2  if  mod(i,5) = 2	
		where i is slot index per frame;	where i is slot index per frame;	
		$i = \{0,, 39\}$	$i = \{0,, 79\}$	

#### A.3.3.2 FRC for receiver requirements for QPSK

Table A.3.3.2-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit		Value	
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration $\mu$		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame		23	23	23
MCS index		4	4	4
Modulation		QPSK	QPSK	QPSK
Target Coding Rate		1/3	1/3	1/3
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,39\}$ (NOTE 5)	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,39\}$ (NOTE 6)	Bits	4224	8456	16896
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,39\}$ (NOTE 5)	CBs	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,39\}$ (NOTE 6)	CBs	1	2	2
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,39} (NOTE 5)	Bits	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,39\}$ (NOTE 6)	Bits	14256	28512	57024
Max. Throughput averaged over 1 frame	Mbps	9.715	19.449	38.861

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). SS/PBCH block is transmitted in slot 0 of each frame
- NOTE 4: Slot i is slot index per frame
- NOTE 5: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 8) =  $\{3,4,5,6,7\}$  for i from  $\{0,...,39\}$  together with the TDD UL-DL configuration specified in A2.3.
- NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 8) =  $\{0,1,2\}$  for i from  $\{0,...,39\}$  together with the TDD UL-DL configuration specified in A2.3.

Table A.3.3.2-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

Parameter	Unit		Va	lue	
Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration $^{\mu}$		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame		47	47	47	47
MCS index		4	4	4	4
Modulation		QPSK	QPSK	QPSK	QPSK
Target Coding Rate		1/3	1/3	1/3	1/3
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$ (NOTE 5)	Bits	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	Bits	2088	4224	8456	16896
Transport block CRC	Bits	16	24	24	24
LDPC base graph		2	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79} (NOTE 5)	CBs	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	CBs	1	1	2	2
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$ (NOTE 5)	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	Bits	6912	14256	28512	57024
Max. Throughput averaged over 1 frame	Mbps	9.814	19.853	39.743	79.411

NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.

NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).

NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame

NOTE 4: Slot i is slot index per frame

NOTE 5: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if  $mod(i, 16) = \{7,...,15\}$  for i from  $\{0,...,79\}$  together with the TDD UL-DL configuration specified in A2.3.

NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 16) = {0,...,6} for i from {0,...,79} together with the TDD UL-DL configuration specified in A2.3.

#### A.3.3.3 FRC for receiver requirements for 16QAM

#### A.3.3.4 FRC for receiver requirements for 64QAM

Table A.3.3.4-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit		Value	
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration $^{\mu}$		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame		23	23	23
MCS index		19	19	19
Modulation		64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,39\}$	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 10) = \{0,1,2\}$ for i from $\{1,,39\}$	Bits	20496	40976	81976
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,39\}$	CBs	N/A	N/A	N/A
For Slot i, if $mod(i, 10) = \{0,1,2\}$ for i from $\{1,,39\}$	CBs	3	5	10
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,39\}$	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 10) = \{0,1,2\}$ for i from $\{1,,39\}$	Bits	40986	81972	163944
Max. Throughput averaged over 1 frame	Mbps	47.141	94.245	188.545

NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.

NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).

NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame

NOTE 4: Slot i is slot index per frame

NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.

Table A.3.3.4-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

Parameter	Unit		Va	lue	
Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration $\mu$		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame		47	47	47	47
MCS index		19	19	19	19
Modulation		64QAM	64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	Bits	9992	20496	40976	81976
Transport block CRC	Bits	24	24	24	24
LDPC base graph		1	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	CBs	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	CBs	2	3	5	10
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	Bits	19872	40986	81972	163944
Max. Throughput averaged over 1 frame	Mbps	46.962	96.331	192.587	385.287

NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.

NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).

NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame

NOTE 4: Slot i is slot index per frame

NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.

#### A.4 Void

### A.5 OFDMA Channel Noise Generator (OCNG)

#### A.5.1 OCNG Patterns for FDD

#### A.5.2 OCNG Patterns for TDD

#### A.5.2.1 OCNG TDD pattern 1: Generic OCNG TDD Pattern for all unused REs

Table A.5.2.1-1: OP.1 TDD: Generic OCNG TDD Pattern for all unused REs

OCNG Appliance OCNG Parameters	Control Region (Core Set)	Data Region
Resources allocated	All unused REs (Note 1)	All unused REs (Note 2)
Structure	PDCCH	PDSCH
Content	Uncorrelated pseudo random QPSK modulated data	Uncorrelated pseudo random QPSK modulated data
Transmission scheme for multiple antennas ports transmission	Single Tx port transmission	Spatial multiplexing using any precoding matrix with dimensions same as the precoding matrix for PDSCH
Subcarrier Spacing	Same as for RMC PDCCH in the active BWP	Same as for RMC PDSCH in the active BWP
Power Level	Same as for RMC PDCCH	Same as for RMC PDSCH

Note 1: All unused REs in the active CORESETS appointed by the search spaces in use.

Note 2: Unused available REs refer to REs in PRBs not allocated for any physical channels, CORESETs, synchronization signals or reference signals in channel bandwidth.

## Annex B (informative): Void

## Annex C (normative): Downlink physical channels

#### C.1 General

## C.2 Setup

Table C.2-1 describes the downlink Physical Channels that are required for connection set up.

Table C.2-1: Downlink Physical Channels required for connection set-up

Physical Channel
PBCH
SSS
PSS
PDCCH
PDSCH
PBCH DMRS
PDCCH DMRS
PDSCH DMRS
CSI-RS
PTRS

#### C.3 Connection

#### C.3.1 Measurement of Receiver Characteristics

Unless otherwise stated, Table C.3.1-1 is applicable for measurements on the Receiver Characteristics (clause 7).

Table C.3.1-1: Downlink Physical Channels transmitted during a connection (TDD)

Parameter	Unit	Value
SSS transmit power	W	Test specific
EPRE ratio of PSS to SSS	dB	0
EPRE ratio of PBCH to SSS	dB	0
EPRE ratio of PBCH to PBCH DMRS	dB	0
EPRE ratio of PDCCH to SSS	dB	0
EPRE ratio of PDCCH to PDCCH DMRS	dB	0
EPRE ratio of PDSCH to SSS	dB	0
EPRE ratio of PDSCH to PDSCH DMRS (Note 1)	dB	-3
EPRE ratio of CSI-RS to SSS	dB	0
EPRE ratio of PTRS to PDSCH	dB	Test specific
EPRE ratio of OCNG DMRS to SSS	dB	0
EPRE ratio of OCNG to OCNG DMRS (Note 1)	dB	0
Alice A Alice of the British College of the College		20011 21120 0 12

Note 1: No boosting is applied to any of the channels except PDSCH DMRS. For PDSCH DMRS, 3 dB power boosting is applied assuming DMRS Type 1 configuration when DMRS and PDSCH are TDM'ed and only half of the DMRS REs are occupied.

Note 2: Number of DMRS CDM groups without data for PDSCH DMRS configuration for OCNG is set to 1.

## Annex D (normative): Characteristics of the interfering signal

#### D.1 General

Unless otherwise stated, a modulated full bandwidth NR downlink signal, which equals to channel bandwidth of the wanted signal for Single Carrier case is used as interfering signals when RF performance requirements for NR UE receiver are defined. For intra-band contiguous CA case, a modulated NR downlink signal which equals to the aggregated channel bandwidth of the wanted signal is used.

## D.2 Interference signals

Table D.2-1 describes the modulated interferer for different channel bandwidth options.

Table D.2-1: Description of modulated NR interferer

	С	hannel bandwi	Intra band				
	50 MHz   100 MHz   200 MHz   400 MHz						
BW <sub>Interferer</sub>	50 MHz	100 MHz	200 MHz	400MHz	BW <sub>Channel_CA</sub>		
RB	NOTE1						
NOTE 1: The RB configured for interfering signal is the same as maximum RB number							
defined in Table 5.3.2-1 for each sub-carrier spacing.							

## Annex E (normative): Environmental conditions

#### E.1 General

This annex specifies the environmental requirements of the UE. Within these limits the requirements of the present documents shall be fulfilled.

#### E.2 Environmental

The requirements in this clause apply to all types of UE(s).

#### E.2.1 Temperature

All RF requirements for UEs operating in FR2 are defined over the air and can only be tested in an OTA chamber.

The UE shall fulfil all the requirements in the temperature range for extreme conditions, as defined in Table E.2.1-1, unless explicitly stated otherwise in any requirement.

**Table E.2.1-1: Temperature conditions** 

	+ 25 °C ± 10 °C	For normal (room temperature) conditions with relative humidity of 25 % to 75 %
Ī	-10°C to +55°C	For extreme conditions

Outside this temperature range the UE, if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation.

#### E.2.2 Voltage

Editor's note: This requirement is incomplete. The following aspects are either missing or not yet determined:

Methodology to control the voltage in a case which a power cable is not connected to DUT is FFS since it is not agreed whether we can connect the power cable to DUT at the OTA measurement situation yet.

The UE shall fulfil all the requirements in the full voltage range, i.e. the voltage range between the extreme voltages.

The manufacturer shall declare the lower and higher extreme voltages and the approximate shutdown voltage. For the equipment that can be operated from one or more of the power sources listed below, the lower extreme voltage shall not be higher, and the higher extreme voltage shall not be lower than that specified below.

**Table E.2.2-1: Voltage conditions** 

Power source	Lower extreme voltage	Higher extreme voltage	Normal conditions voltage
AC mains	0,9 * nominal	1,1 * nominal	nominal
Regulated lead acid battery	0,9 * nominal	1,3 * nominal	1,1 * nominal
Nonregulated batteries:			
Leclanché	0,85 * nominal	Nominal	Nominal
Lithium	0,95 * nominal	1,1 * Nominal	1,1 * Nominal
Mercury/nickel & cadmium	0,90 * nominal		Nominal

Outside this voltage range the UE if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation. In particular, the UE shall inhibit all RF transmissions when the power supply voltage is below the manufacturer declared shutdown voltage.

#### E.2.3 Void

## Annex F (normative): Transmit modulation

### F.1 Measurement Point

Figure F.1-1 shows the measurement point for the unwanted emission falling into non-allocated RB(s) and the EVM for the allocated RB(s).

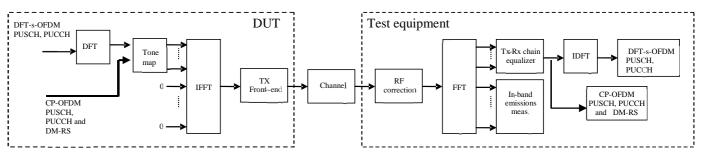


Figure F.1-1: EVM measurement points

#### F.2 Basic Error Vector Magnitude measurement

The EVM is the difference between the ideal waveform and the measured waveform for the allocated RB(s)

$$EVM = \sqrt{\frac{\sum_{v \in T_m} |z'(v) - i(v)|^2}{|T_m| \cdot P_0}},$$

where

 $T_m$  is a set of  $|T_m|$  modulation symbols with the considered modulation scheme being active within the measurement period,

z'(v) are the samples of the signal evaluated for the EVM,

i(v) is the ideal signal reconstructed by the measurement equipment, and

 $P_0$  is the average power of the ideal signal. For normalized modulation symbols  $\,P_0\,$  is equal to 1.

The basic EVM measurement interval is defined over one slot in the time domain for PUCCH and PUSCH and over one preamble sequence for the PRACH.

#### F.3 Basic in-band emissions measurement

The in-band emissions are a measure of the interference falling into the non-allocated resources blocks. The in-band emission requirement is evaluated for PUCCH and PUSCH transmissions. The in-band emission requirement is not evaluated for PRACH transmissions.

The in-band emissions are measured as follows

$$Emissions_{absolute}(\Delta_{RB}) = \begin{cases} \frac{1}{|T_{s}|} \sum_{t \in T_{s}} \sum_{\substack{max(f_{\min}, f_{l} + 12 \cdot \Delta_{RB} + \lambda f) \\ \min(f_{\max}, f_{h} + 12 \cdot \Delta_{RB} * \Delta f)}} |Y(t, f)|^{2}, \Delta_{RB} < 0 \\ \frac{1}{|T_{s}|} \sum_{t \in T_{s}} \sum_{\substack{f_{h} + (12 \cdot \Delta_{RB} - 11) * \Delta f \\ f_{h} + (12 \cdot \Delta_{RB} - 11) * \Delta f}} |Y(t, f)|^{2}, \Delta_{RB} > 0 \end{cases}$$

where

 $T_s$  is a set of  $|T_s|$  OFDM symbols with the considered modulation scheme being active within the measurement period,

 $\Delta_{RB}$  is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g.  $\Delta_{RB} = 1$  or  $\Delta_{RB} = -1$  for the first adjacent RB),

 $f_{
m min}$  (resp.  $f_{
m max}$  ) is the lower (resp. upper) edge of the UL system BW,

 $\boldsymbol{f}_l$  and  $\boldsymbol{f}_h$  are the lower and upper edge of the allocated BW, and

Y(t, f) is the frequency domain signal evaluated for in-band emissions as defined in the subsection (ii)

The relative in-band emissions are, given by

$$Emissions_{relative}(\Delta_{RB}) = \frac{Emissions_{absolute}(\Delta_{RB})}{\frac{1}{\left|T_{s}\right| \cdot N_{RB}} \sum_{t \in T_{s}}^{f_{t} + (12N_{RB} - 1)\Delta f} \left|Y(t, f)\right|^{2}}$$

where

 $N_{\!\scriptscriptstyle RR}$  is the number of allocated RBs

The basic in-band emissions measurement interval is defined over one slot in the time domain. When the PUSCH or PUCCH transmission slot is shortened due to multiplexing with SRS, the in-band emissions measurement interval is reduced by one OFDM symbol, accordingly.

In the evaluation of in-band emissions, the timing is set according to  $\Delta \tilde{t} = \Delta \tilde{c}$ , where sample time offsets  $\Delta \tilde{t}$  and  $\Delta \tilde{c}$  are defined in subclause F.4.

## F.4 Modified signal under test

Implicit in the definition of EVM is an assumption that the receiver is able to compensate a number of transmitter impairments.

The DFT-s-OFDM modulated signals or PRACH signal under test is modified and, in the case of DFT-s-OFDM modulated signals, decoded according to:

$$Z'(t,f) = IDFT \left\{ \frac{FFT \left\{ z(v - \Delta \widetilde{t}) \cdot e^{-j2\pi \Delta \widetilde{f}v} \right\} e^{j2\pi j\Delta \widetilde{t}}}{\widetilde{a}(t,f) \cdot e^{j\widetilde{\varphi}(t,f)}} \right\}$$

where

 $\mathcal{Z}(\mathcal{V})$  is the time domain samples of the signal under test.

The CP-OFDM modulated signals or PUSCH demodulation reference signal or CP-OFDM modulated signals under test is equalised and, in the case of PUCCH data signal decoded according to:

$$Z'(t,f) = \frac{FFT\left\{z(v - \Delta \tilde{t}) \cdot e^{-j2\pi\Delta \tilde{f}v}\right\} e^{j2\pi f\Delta \tilde{t}}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}}$$

where

 $\mathcal{Z}(\mathcal{V})$  is the time domain samples of the signal under test.

To minimize the error, the signal under test should be modified with respect to a set of parameters following the procedure explained below.

Notation:

 $\Delta \tilde{t}$  is the sample timing difference between the FFT processing window in relation to nominal timing of the ideal signal.

 $\Delta \tilde{f}$  is the RF frequency offset.

 $\widetilde{\varphi}(t,f)$  is the phase response of the TX chain.

 $\widetilde{a}(t,f)$  is the amplitude response of the TX chain.

In the following  $\Delta \tilde{c}$  represents the middle sample of the EVM window of length W (defined in the next subsections) or the last sample of the first window half if W is even.

The EVM analyser shall

- detect the start of each slot and estimate  $\Delta \widetilde{t}$  and  $\Delta \widetilde{f}$  ,
- determine  $\Delta \widetilde{c}$  so that the EVM window of length W is centred
  - on the time interval determined by the measured cyclic prefix minus  $16\kappa$  samples of the considered OFDM symbol for symbol 1 for subcarrier spacing configuration  $\mu$  in a subframe, with l=0 or  $l=7*2^{\text{h}}\mu$  for normal CP, i.e. the first  $16\kappa$  samples of the CP should not be taken into account for this step. In the determination of the number of excluded samples, a sampling rate of  $1/T_c$  is assumed. If a different sampling rate is used, the number of excluded samples is scaled linearly.
  - on the measured cyclic prefix of the considered OFDM symbol symbol for all other symbols for normal CP and for symbol 0 to 11 for extended CP.
  - on the measured preamble cyclic prefix for the PRACH

To determine the other parameters a sample timing offset equal to  $\Delta \widetilde{c}$  is corrected from the signal under test. The EVM analyser shall then

- correct the RF frequency offset  $\Delta \widetilde{f}$  for each time slot, and
- apply an FFT of appropriate size. The chosen FFT size shall ensure that in the case of an ideal signal under test, there is no measured inter-subcarrier interference.

The carrier leakage shall be removed from the evaluated signal before calculating the EVM and the in-band emissions; however, the removed relative carrier leakage power also has to satisfy the applicable requirement.

At this stage the allocated RBs shall be separated from the non-allocated RBs. In the case of PUCCH and PUSCH EVM, the signal on the non-allocated RB(s), Y(t, f), is used to evaluate the in-band emissions.

Moreover, the following procedure applies only to the signal on the allocated RB(s).

- In the case of PUCCH and PUSCH, the UL EVM analyzer shall estimate the TX chain equalizer coefficients  $\widetilde{a}(t,f)$  and  $\widetilde{\varphi}(t,f)$  used by the ZF equalizer for all subcarriers by time averaging at each signal subcarrier of the amplitude and phase of the reference and data symbols. The time-averaging length is 1 slot. This process creates an average amplitude and phase for each signal subcarrier used by the ZF equalizer. The knowledge of data modulation symbols may be required in this step because the determination of symbols by demodulation is not reliable before signal equalization.
- In the case of PRACH, the UL EVM analyzer shall estimate the TX chain coefficients  $\widetilde{a}(t)$  and  $\widetilde{\varphi}(t)$  used for phase and amplitude correction and are seleted so as to minimize the resulting EVM. The TX chain coefficients are not dependent on frequency, i.e.  $\widetilde{a}(t,f) = \widetilde{a}(t)$  and  $\widetilde{\varphi}(t,f) = \widetilde{\varphi}(t)$ . The TX chain coefficient are chosen independently for each preamble transmission and for each  $\Delta \widetilde{t}$ .

At this stage estimates of  $\Delta \widetilde{f}$ ,  $\widetilde{\alpha}(t,f)$ ,  $\widetilde{\varphi}(t,f)$  and  $\Delta \widetilde{c}$  are available.  $\Delta \widetilde{t}$  is one of the extremities of the window W, i.e.  $\Delta \widetilde{t}$  can be  $\Delta \widetilde{c} + \alpha - \left\lfloor \frac{W}{2} \right\rfloor$  or  $\Delta \widetilde{c} + \left\lfloor \frac{W}{2} \right\rfloor$ , where  $\alpha = 0$  if W is odd and  $\alpha = 1$  if W is even. The EVM analyser shall then

- calculate EVM<sub>1</sub> with  $\Delta \tilde{t}$  set to  $\Delta \tilde{c} + \alpha \left\lfloor \frac{W}{2} \right\rfloor$ ,
- calculate EVM<sub>h</sub> with  $\Delta \tilde{t}$  set to  $\Delta \tilde{c} + \left\lfloor \frac{W}{2} \right\rfloor$ .

### F.5 Window length

#### F.5.1 Timing offset

As a result of using a cyclic prefix, there is a range of  $\Delta \tilde{t}$ , which, at least in the case of perfect Tx signal quality, would give close to minimum error vector magnitude. As a first order approximation, that range should be equal to the length of the cyclic prefix. Any time domain windowing or FIR pulse shaping applied by the transmitter reduces the  $\Delta \tilde{t}$  range within which the error vector is close to its minimum.

### F.5.2 Window length

The window length *W* affects the measured EVM and is expressed as a function of the configured cyclic prefix length. In the case where equalization is present, as with frequency domain EVM computation, the effect of FIR is reduced. This is because the equalization can correct most of the linear distortion introduced by the FIR. However, the time domain windowing effect can't be removed.

### F.5.3 Window length for normal CP

Table F.5.3-1 and Table F.5.3-2 below specify the EVM window length (W) for normal CP for FR2.

Table F.5.3-1: EVM window length for normal CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length for symbols 1-13 in FFT samples	EVM window length W	Ratio of W to total CP length for symbols 1-13 <sup>(Note</sup> 1) (%)			
50	1024	72	36	50			
100	2048	144	72	50			
200	4096	288	144	50			
Note 1: These percentages are informative and apply to a slot's symbols 1 through 13. Symbol 0 may have a longer CP and therefore a lower percentage.							

Table F.5.3-2: EVM window length for normal CP for 120 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length for symbols 1-13 in FFT samples	EVM window length W	Ratio of W to total CP length for symbols 1-13 <sup>(Note</sup> 1) (%)		
50	512	36	18	50		
100	1024	72	36	50		
200	2048	144	72	50		
400	4096	288	144	50		
Note 1: These percentages are informative and apply to a slot's symbols 1 through 13. Symbol 0 may have a longer CP						

### F.5.4 Window length for Extended CP

Table F.5.4-1 below specifies the EVM window length (*W*) for extended CP. The number of CP samples excluded from the EVM window is the same as for normal CP length.

and therefore a lower percentage.

Table F.5.4-1: EVM window length for extended CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length (Note 1)		
				(%)		
50	1024	256	220	85.9		
100	2048	512	440	85.9		
200	4096	1024	880	85.9		
Note 1: These percentages are informative.						

#### F.5.5 Window length for PRACH

The table below specifies the EVM window length for PRACH preamble formats for  $L_{RA} = 139$  and  $\Delta f^{RA} = 15 \cdot 2^{\mu} \text{ kHz}_{\text{where}} \mu \in \{2,3\}$ .

Table F.5.5-1: EVM window length for PRACH formats for  $L_{RA} = 139$ 

Preamble format	Cyclic prefix $N_{cp}$ length	Nominal FFT size <sup>1</sup>	EVM window length W in FFT samples	Ratio of <i>W</i> to CP*
A1	1152·2 <sup>-</sup>	8192·2 <sup>-</sup>	576·2 <sup>-μ</sup>	50.0%
A2	2304·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	1728⋅2 <sup>-</sup> μ	75.0%
A3	3456·2 <sup>-</sup> µ	8192·2 <sup>-</sup>	2880·2 <sup>-</sup> µ	83.3%
B1	864·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	288·2 <sup>-</sup> µ	33.3%
B2	1440·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	864·2 <sup>-</sup>	60.0%
B3	2016·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	1440·2 <sup>-</sup>	71.4%
B4	3744·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	3168·2 <sup>-</sup>	84.6%
C0	4960·2 <sup>-μ</sup>	8192·2 <sup>-μ</sup>	4384·2 <sup>-μ</sup>	88.4%
C2	8192·2 <sup>-</sup> µ	8192·2 <sup>-</sup>	7616·2 <sup>-</sup> µ	93.0%

Note 1: The use of other FFT sizes is possible as long as appropriate scaling of the window length is applied

Note 2: These percentages are informative

## F.6 Averaged EVM

The general EVM is averaged over basic EVM measurements for n slots in the time domain.

$$\overline{EVM} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{i}^{2}},$$

where n is

$$n = \begin{cases} 40, for 60 \text{ kHz SCS} \\ 80, for 120 \text{ kHz SCS} \end{cases}$$

for PUCCH, PUSCH.

The EVM requirements shall be tested against the maximum of the RMS average at the window W extremities of the EVM measurements:

Thus  $\overline{EVN}$  is calculated using  $\Delta \widetilde{t} = \Delta \widetilde{t}_l$  in the expressions above and  $\overline{EVN}$  is calculated using  $\Delta \widetilde{t} = \Delta \widetilde{t}_h$ .

Thus we get:

$$EVM = \max(\overline{EVM_1}, \overline{EVM_h})$$

The calculation of the EVM for the demodulation reference signal,  $EVM_{DMRS}$ , follows the same procedure as calculating the general EVM, with the exception that the modulation symbol set  $T_m$  defined in clause F.2 is restricted to symbols containing uplink demodulation reference signals.

The basic  $EVM_{DMRS}$  measurements are first averaged over n slots in the time domain to obtain an intermediate average  $\overline{EVM}_{DMRS}$ .

$$\overline{EVM}_{DMRS} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{DMRS,i}^{2}}$$

In the determination of each  $EVM_{DMRS,i}$ , the timing is set to  $\Delta \tilde{t} = \Delta \tilde{t}_l$  if  $EVM_l > EVM_h$ , and it is set to

 $\Delta \widetilde{t} = \Delta \widetilde{t}_h$  otherwise, where  $\overline{\text{EVM}}_h$  and  $\overline{\text{EVM}}_h$  are the general average EVM values calculated in the same n slots

over which the intermediate average  $EVM_{DMRS}$  is calculated. Note that in some cases, the general average EVM may be calculated only for the purpose of timing selection for the demodulation reference signal EVM.

Then the results are further averaged to get the EVM for the demodulation reference signal,  $EVM_{DMRS}$ ,

$$EVM_{DMRS} = \sqrt{\frac{1}{6} \sum_{j=1}^{6} \overline{EVM}_{DMRS,j}^{2}}$$

The PRACH EVM,  $EVM_{PRACH}$ , is averaged over 2 preamble sequence measurements for long preamble formats as defined in table 6.3.3.1-1 in [9] and averaged over 10 preamble sequence measurements for short preamble formats as defined in table 6.3.3.1-2 in [9]..

The EVM requirements shall be tested against the maximum of the RMS average at the window *W* extremities of the EVM measurements:

Thus  $\overline{\text{EVM}}_{\text{PRACH,I}}$  is calculated using  $\Delta \widetilde{t} = \Delta \widetilde{t}_l$  and  $\overline{\text{EVM}}_{\text{PRACH,h}}$  is calculated using  $\Delta \widetilde{t} = \Delta \widetilde{t}_h$ .

Thus we get:

$$EVM_{PRACH} = \max(\overline{EVM}_{PRACH,1}, \overline{EVM}_{PRACH,h})$$

## F.7 Spectrum Flatness

The data shall be taken from FFT coded data symbols and the demodulation reference symbols of the allocated resource block.

Annex G (informative): Void

Annex H (informative): Void

Annex I (informative): Void

# Annex J (normative): UE coordinate system

## J.1 Reference coordinate system

This annex defines the measurement coordinate system for the NR UE. The reference coordinate system as defined in IEEE Std 149 [15] is provided in Figure J.1-1 below while Figure J.1.-2 shows the DUT in the default alignment, i.e., the DUT and the reference coordinate systems are aligned with  $\alpha=0^{\circ}$  and  $\beta=0^{\circ}$  and  $\gamma=0^{\circ}$  where  $\alpha$ ,  $\beta$ , and  $\gamma$  describe the relative angles between the two coordinate systems.

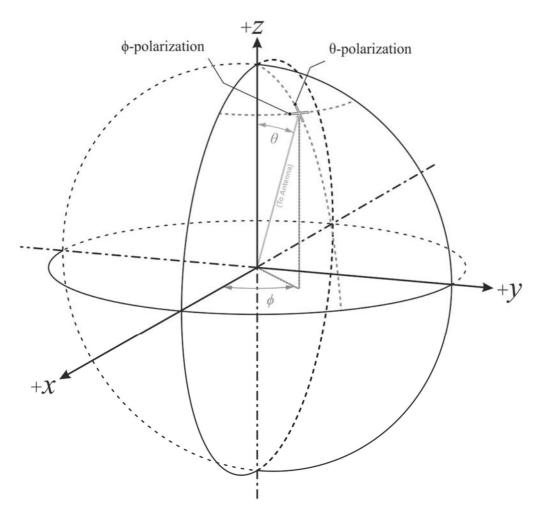


Figure J.1-1: Reference coordinate system

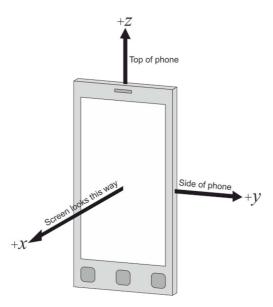


Figure J.1-2: DUT default alignment to coordinate system

The following aspects are necessary:

- A basic understanding of the top and bottom of the device is needed in order to define unambiguous DUT positioning requirements for the test, e.g., in the drawings used in this annex, the three buttons are on the bottom of the device (front) and the camera is on the top of the device (back).
- An understanding of the origin and alignment the coordinate system inside the test system i.e. the directions in which the x, y, z -axes points inside the test chamber is needed in order to define unambiguous DUT orientation, DUT beam, signal, interference, and measurement angles

## J.2 Test conditions and angle definitions

Tables J.2-1 through J.2-3 below provides the test conditions and angle definitions for three permitted device alignment for the default test condition, DUT orientation 1, and two different options for each permitted device alignment to reposition the device for DUT Orientation 2 as outlined in Figures J.2-1 and J.2-3.

Table J.2-1: Test conditions and angle definitions for Alignment Option 1

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$egin{array}{l} \alpha=0^{\circ}; \\ \beta=0^{\circ}; \\ \gamma=0^{\circ} \end{array}$	$\begin{array}{c} \theta_{Link;} \\ \phi_{Link} \\ with \\ polarization \\ reference \\ Pol_{Link} = \theta \text{ or } \\ \phi \end{array}$	$\begin{array}{c} \theta_{Meas;} \\ \phi_{Meas} \\ with \\ polarization \\ reference \\ Pol_{Meas} = \theta \text{ or } \\ \phi \end{array}$	Rotation Matrix $R_x(\alpha)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = 180^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	$\begin{array}{c} \theta_{Link;} \\ \phi_{Link} \\ with \\ polarization \\ reference \\ Pol_{Link} = \theta \text{ or } \\ \phi \end{array}$	$\begin{array}{c} \theta_{Meas;} \\ \phi_{Meas} \\ \text{with} \\ \text{polarization} \\ \text{reference} \\ \text{Pol}_{Meas} = \theta \text{ or} \\ \phi \end{array}$	Rotation Matrix $R_x(\alpha)$ $+X$ Rotation Matrix $R_x(\beta)$
Free space DUT Orientation 2 – Option 2 (based on repositioning approach)	$\begin{array}{c} \alpha=0^{\circ};\\ \beta=180^{\circ};\\ \gamma=0^{\circ} \end{array}$	$\begin{array}{c} \theta_{Link};\\ \phi_{Link}\\ with\\ polarization\\ reference\\ Pol_{Link}=\theta \text{ or }\\ \phi \end{array}$	$\theta_{Meas};$ $\phi_{Meas}$ $with$ $polarization$ $reference$ $Pol_{Meas} = \theta$ or $\phi$	Rotation Matrix $R_x(\alpha)$ $+\chi$ Rotation Matrix $R_y(\beta)$

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle.
 NOTE 2: The combination of rotations is captured by matrix M=R<sub>z</sub>(γ)•R<sub>x</sub>(β)•R<sub>x</sub>(α)

Table J.2-2: Test conditions and angle definitions for Alignment Option 2

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$\alpha = 0^{\circ};$ $\beta = -90^{\circ};$ $\gamma = 0^{\circ}$	$\begin{array}{c} \theta_{Link;} \\ \phi_{Link} \\ with \\ polarization \\ reference \\ Pol_{Link} = \theta \ or \\ \phi \end{array}$	$\begin{array}{c} \theta_{Meas;} \\ \phi_{Meas} \\ with \\ polarization \\ reference \\ Pol_{Meas} = \theta \text{ or } \\ \phi \end{array}$	Rotation Matrix $R_z(\gamma)$ Rotation Matrix $R_x(\alpha)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha=180^{\circ};$ $\beta=90^{\circ};$ $\gamma=0^{\circ}$	$\begin{array}{c} \theta_{Link;} \\ \phi_{Link} \\ with \\ polarization \\ reference \\ Pol_{Link} = \theta \ or \\ \phi \end{array}$	$\begin{array}{c} \theta_{Meas;} \\ \phi_{Meas} \\ with \\ polarization \\ reference \\ Pol_{Meas} = \theta \text{ or } \\ \phi \end{array}$	Rotation Matrix $R_z(\gamma)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$\alpha=0^{\circ};$ $\beta=90^{\circ};$ $\gamma=0^{\circ}$	$\begin{array}{c} \theta_{Link;} \\ \phi_{Link} \\ with \\ polarization \\ reference \\ Pol_{Link} = \theta \ or \\ \phi \end{array}$	$\begin{array}{c} \theta_{Meas;} \\ \phi_{Meas} \\ with \\ polarization \\ reference \\ Pol_{Meas} = \theta \text{ or } \\ \phi \end{array}$	Rotation Matrix $R_z(\gamma)$ $+\chi$ Rotation Matrix $R_x(\alpha)$ Matrix $R_y(\beta)$

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle. NOTE 2: The combination of rotations is captured by matrix  $M=R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$ 

Test DUT Link Measurement Diagram condition orientation angle angle Rotation Matrix  $R_{s}(\gamma)$  $\theta_{Link}$ θ<sub>Meas</sub>;  $\alpha = 90^{\circ}$ : **\$**Link **\$**Meas Free space  $\beta = 0^{\circ}$ ; with with DUT  $y = 0^{0}$ polarization polarization Orientation 1 reference reference (default)  $Pol_{Link} = \theta$  or  $Pol_{Meas} = \theta$  or Matrix  $R_{x}(\alpha)$ φ Rotation Matrix  $R_{\nu}(\beta)$ Rotation Matrix  $R_z(\gamma)$ Free space  $\theta_{Link}$ θ<sub>Meas;</sub> DUT  $\alpha = -90^{\circ}$  $\Phi_{Link}$ **ф**меаs Orientation 2  $\beta = 0^{\circ}$ ; with with  $y = 0^{\circ}$ Option 1 polarization polarization (based on rereference reference positioning  $Pol_{Link} = \theta$  or  $Pol_{Meas} = \theta$  or Rotation Matrix  $R_{\nu}(\alpha)$ approach) ф φ Rotation Matrix  $R_{\nu}(\beta)$ Rotation Matrix  $R_*(\gamma)$ Free space  $\theta_{Link;}$  $\theta_{\text{Meas}}$ ; DUT  $\alpha = 90^{\circ}$ : **₫**I ink **d**Meas  $\beta = 180^{\circ};$ Orientation 2 with with - Option 2  $\gamma = 0^{\circ}$ polarization polarization (based on rereference reference Rotation positioning  $Pol_{Link} = \theta$  or  $Pol_{Meas} = \theta$  or Matrix  $R_r(\alpha)$ approach) φ ф Rotation Matrix  $R_{\nu}(\beta)$ 

Table J.2-3: Test conditions and angle definitions for Alignment Option 3

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle.

NOTE 2: The combination of rotations is captured by matrix  $M=R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$ 

For each UE requirement and test case, each of the parameters in Table J.2-1 through J.2-3 need to be recorded, such that DUT positioning, DUT beam direction, and angles of the signal, link/interferer, and measurement are specified in terms of the fixed coordinate system.

Due to the non-commutative nature of rotations, the order of rotations is important and needs to be defined when multiple DUT orientations are tested.

The rotations around the x, y, and z axes can be defined with the following rotation matrices

$$R_{x}(\alpha) = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos \alpha & -\sin \alpha & 0 \\ 0 & \sin \alpha & \cos \alpha & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

$$R_{y}(\beta) = \begin{bmatrix} \cos \beta & 0 & \sin \beta & 0 \\ 0 & 1 & 0 & 0 \\ -\sin \beta & 0 & \cos \beta & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

and

$$R_{z}(\gamma) = \begin{bmatrix} \cos \gamma & -\sin \gamma & 0 & 0 \\ \sin \gamma & \cos \gamma & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with the respective angles of rotation,  $\alpha$ ,  $\beta$ ,  $\gamma$ , and

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = R \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

Additionally, any translation of the DUT can be defined with the translation matrix

$$T(t_x, t_y, t_z) = \begin{bmatrix} 1 & 0 & 0 & t_x \\ 0 & 1 & 0 & t_y \\ 0 & 0 & 1 & t_z \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with offsets tx, ty, tz in x, y, and z, respectively and with

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = T \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

The combination of rotations and translation is captured by the multiplication of rotation and translation matrices.

For instance, the matrix M

$$M = T(t_x, t_y, t_z) \cdot R_z(\gamma) \cdot R_v(\beta) \cdot R_x(\alpha)$$

describes an initial rotation of the DUT around the x axis with angle  $\alpha$ , a subsequent rotation around the y axis with angle  $\beta$ , and a final rotation around the z axis with angle  $\gamma$ . After those rotations, the DUT is translated by  $t_x$ ,  $t_y$ ,  $t_z$  in x, y, and z, respectively.

## J.3 DUT positioning guidelines

The centre of the reference coordinate system shall be aligned with the geometric centre of the DUT in order to minimize the offset between antenna arrays integrated at any position of the UE and the centre of the quiet zone.

Near-field coupling effects between the antenna and the pedestals/positioners/fixtures generally cause increased signal ripples. Re-positioning the DUT by directing the beam peak away from those areas can reduce the effect of signal ripple on EIRP/EIS measurements. Figure J.3-1 and J.3-2 illustrate how to reposition the DUT in distributed axes and combined axes system, when the beam peak is directed to the DUTs upper hemisphere (DUT orientation 1) or the DUTs lower hemisphere (DUT orientation 2). While these figures are examples of different positioning systems and other implementations are not precluded, the relative orientation of the coordinate system with respect to the antennas/reflectors and the axes of rotation shall apply to any measurement setup.

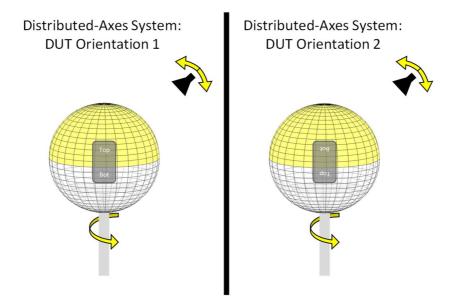


Figure J.3-1: DUT re-positioning for an example of distributed-axes system

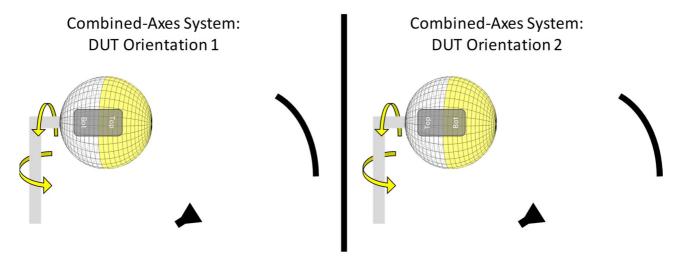


Figure J.3-2: DUT re-positioning for an example of combined-axes system

For EIRP/EIS measurements, re-positioning the DUT makes sure the pedestal is not obstructing the beam path and that the pedestal is not in closer proximity to the measurement antenna/reflector than the DUT. For TRP measurements, repositioning the DUT makes sure that the beam peak direction is not obstructed by the pedestal and the pedestal is in the measurement path only when measuring the back-hemisphere. No re-positioning during the TRP measurement is required.

## Annex K (informative): Void

# Annex L (informative): Change history

	Change history						
Date	Meeting	TDoc	CR	Rev	Cat	Subject/Comment	New versio n
2017-08	RAN4#84					Initial Skeleton	0.0.1
2017-10	RAN4#84 Bis	R4- 1711979				TPs from R4#84Bis by editors	0.1.0
2017-12	RAN4#85	R4- 1713806				Approved TPs from R4#85 R4-1714537, TP for TS 38.101-2: Channel Bandwidth Definition, Qualcomm Incorporated R4-1714115, TP for TS 38.101-2: Channel Arrangement,: Qualcomm Incorporated (Note: this TP was further discussed and edited in the reflector) R4-1713205, TP on general parts for 38.101-2 NR FR,: Ericsson R4-1712884, TP to TS38.101-2 on environmental conditions, Intel Corporation R4-1714018, TP to TS 38.101-2 for definition of UE RF terminologies, Anritsu Corporation R4-1714447, TP on UE power class for FR2, Intel Corporation R4-1714372, TP to TS38.101-2 on EVM equalizer spectrum flatness requirements, Intel Corporation R4-1714330, TP to TR 38.101-02 v0.1.0: ON/OFF mask design for NR UE transmissions for FR2, Ericsson R4-1714364, TP to TR 38.101: NR UE transmit OFF power for FR2, CATT R4-1714347, TP to TS38.101-2 on spurious emissions requirements for FR2, Intel Corporation (Note: this TP was further discussed and edited in the reflector) R4-1714337 TP to TS 38.101-2 ACS requirement for mmW (section 7.5), Qualcomm Incorporated R4-1714338, TP to TS 38.101-2 IBB requirement for mmW (section 7.6.1), Qualcomm Incorporated R4-1714348, TP to TS 38.101-2 on Rx spurious emissions for FR2, Intel Corporation Min power for EVM requirement according to R4-1711568, TP to TR 38.xxx - UE minimum transmit power for range 2, CATT Band list according to R4-1714542, List of bands and band combinations to be introduced into RAN4 NR core requirements by December 2017, RAN4 Chairmen	0.2.0
2017-12	RAN4#85	R4- 1714570				Further corrections and alignments with 38.104 after email review	0.3.0
2017-12		RP-172476				v1.0.0 submitted for plenary approval. Contents same as 0.3.0	1.0.0
2017-12 2018-03	RAN#79	RP-180264	0004		F	Approved by plenary – Rel-15 spec under change control Implementation of endorsed CR on to 38.101-2 Endorsed draft CRs in RAN4-NR-AH#1801 F: R4-1800918, Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801097, Modification for TS38.101-2, CATT F: R4-1801098 Draft CR for TS38.101-2: On requirement metrics. Sumitomo Elec. Industries, Ltd F: R4-1800401, Editorial corections to 38.101-2, Qualcomm F: R4-1801122: Draft pCR for TS 38.101-2 version 15.0.0: Remaining ON/OFF masks for FR2 NR UE transmissions, Ericsson F: R4-1800418, Correction of NR SEM for FR2 table, vivo F: R4-1800316 Draft CR to 38.101-2: Tx spurious emission for NR FR2 (section 6.5.3), ZTE Corporation F: R4-1800918 Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801013, Draft CR to 38.101-2: Clarifications to UE spectrum utilization section 5.3, Ericsson F: R4-1801229, Draft CR to 38.101-2: Channel spacing for CA for NR FR2(section 5.4.1.2), ZTE Corporation F: R4-1801232, Correction CR for channel spacing:38.101-2, Samsung	15.0.0

F: R4-1801325, Draft CR to TS 38.101-2: Corrections on chan	nel
raster calculation in section 5.4.2, ZTE Corporation	
F: R4-1800860, Corrections of GSCN, Nokia	
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R4-1803054, Draft CR for new spec structure of 38.101-2, Eric	rsson
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and REFSENS, ROHDE & SCHWARZ R4-1802567, Draft CR to TS 38.101-2: Clarification of mixed	
numerology guardband size, Ericsson	
R4-1803238, Draft CR for TS 38.101-2: ACLR requirement	
clarification, Huawei	
R4-1803365, Draft CR to 38.101-2: Clarification on REFSENS	
Definition, ROHDE & SCHWARZ	
R4-1803453, draft CR for introduction of completed band	
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R4-1803566, Draft CR for TS 38.101-2: Sync raster offset in refarming bands (5.4.3), Ericsson	<del>-</del>
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R4-1803736, Draft CR on channel raster entry of band n258 fo	or TS
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R4-1804022, CR for modifications and clarifications for NR FR BW Classes, Nokia	2 CA
R4-1804585, Draft CR to 38.101-2: IBE Section Update, Quality	comm
Inc.	50.11.11,
R4-1804657, Introduction of UE to UE coexistence requirement	nts
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numerologies (Section 5.3.4), ZTE Corporation	
R4-1805704, Update of UE emission requirements for FR2,	
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R4-1805705, Draft CR to 38.101-2: Update of section 7.1, Roh	nde &
Schwarz R4-1805757, Update of ACS requirement for FR2, Qualcomm	
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R4-1805771, Update of IBB requirement for FR2, Qualcomm	
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R4-1805949, Draft CR on minimum guardband of SCS 240 kH	IZ SSB
for TS 38.101-2, ZTE Wistron Telecom AB R4-1805982, draft CR for 38.101-2: sync raster, Samsung	
R4-1804878, draft CR introduction completed band combination	ons
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R4-1803628, pi/2 BPSK related CR, IITH	
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R4-1806167, Draft CR on channel raster entry of band n261 for 38.101-2, ZTE Corporation	JI 13
R4-1806169, Draft CR on SSB clarification for TS 38.101-2, Z	TE
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mmWave, Anritsu Corporation	_
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R4-1807853, Draft CR to TS 38.101-2: UE maximum output po	ower
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					R4-1807855, Draft CR on 38.101-2: Transmit ON/OFF time mask for UL CA, Nokia	
					R4-1807857, Draft CR on 38.101-2: Occupied BW for UL CA, Nokia	
					R4-1808101, Draft CR to 38.101-2: On EVM Averaging Length,	
					Wording, Qualcomm Incorporated R4-1808105, Configured maximum output power for FR2, Ericsson	
					R4-1808124, draft CR on UE RF requirement for UE type 2 in FR2,	
					LG Electronics	
					R4-1808125, Draft CR to TS 38.101-2: Minimum output and OFF Power, Nokia	
					R4-1808147, Draft CR for NR FR2 CA BW class modifications,	
					MediaTek Inc.	
					R4-1808148, EVM equaliser spectral flatness for FR2, Ericsson R4-1808149, UE Shaping Filter Requirement for pi/2 BPSK, Indian	
					Institute of Tech (M)	
					R4-1808152, Draft CR for Finalizing UE RF Requirement for FWA,	
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					R4-1808266, Draft CR for TS 38.101-2: Channel and sync raster corrections (5.4), Ericsson	
					R4-1808545, Draft CR on UE RF requirement for UE type 3 in FR2,	
					Verizon	
					R4-1808546, Power class 3 Spherical coverage introduction and peak EIRP requirement update, Qualcomm	
					R4-1808206, Draft CR to 38.101-2: FR2 Type 1 UE Power Control,	
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					R4-1808208, Draft CR to 38.101-2: FR2 Type 1 UE CA EIS update, Qualcomm	
					R4-1808191, TP to TS38.101-2 - UE ON/OFF masks, Ericsson	
					R4-1807102, draft CR introduction completed band combinations 37.865-01-01 -> 38.101-2, Ericsson	
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					R4-1809338, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation	
					R4-1809397, Draft CR on measurement of receiver characteristics	
					for FR2 RF Tests, Qualcomm Incorporated R4-1809566, Draft CR on OCNG pattern for FR2 REFSENS test,	
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					R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections	
					(5.4.2), Ericsson	
					R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson	
					R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB	
					allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2	
					in FR2, LG Electronics Inc	
					R4-1810373, Draft CR to 38.101-2: Corrections on symbols and	
					abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia	
					R4-1810863, Draft CR to 13 38.101-2: Addition of Transmit Modulation	
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					R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated	
					R4-1811104, Finalization of SEM requirements in FR2, Qualcomm	
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					R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1,	
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					Qualcomm Inc	
					R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and	
					Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm	
					Incorporated	
					R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated	
					R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,	
					Keysight Technologies UK Ltd	

						R4-1811517, Draft CR on NR DL FRCs for FR2 UE RF	
						requirements, Intel Corporation	
						R4-1811519, Draft CR to 38.101-2: On FR2 MPR for single CC PC1 and PC3, Qualcomm	
						R4-1811520, Draft CR to 38.101-2: FR2 Max. Input Power,	
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						R4-1811524, Clearification of UL MIMO for FR2, OPPO	
						R4-1811551, Draft CR to TS 38.101-2 on channel bandwidth and	
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						R4-1811554, Draft CR to 38.101-2: Corrections on description of channel raster entries, ZTE Corporation	
						R4-1811802, Draft CR to TS 38.101-2 update the Pumax tolerance	
						table for configured transmitted power, Intel Corporation	
						R4-1811807, Draft CR to 38.101-2: FR2 UE Transmit Signal Quality	
						update, Qualcomm Incorporated	
						R4-1811813, Correction on UE transmitter requirement for FR2,	
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						R4-1811800, DRAFT CR for PCmax FR2 correction, Qualcomm	
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						R4-1812122, Draft CR for FR2 ACLR Measurement BW, Qualcomm	
						R4-1812134, CR on Out of Band Blocking for FR2, Intel Corporation	
						R4-1812426, draft CR of MPR for Power Class 2 in FR2, LG	
						Electronics R4-1812428, draft CR of transmit signal quality for Power Class 2 in	
						FR2, LG Electronics	
						R4-1812453, Draft CR to TS 38.101-2 Adjust placement of 0dB MPR	
						reference waveform, Intel Corporation	
						R4-1812495, Draft CR to 38.101-2: Corrections on channel raster & SS raster, ZTE Corporation	
						R4-1813470, draftCR on applicability of TDD configuratiin for CA in	
						TS 38.101-2, Huawei	
						R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2,	
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						Cases, Keysight	
						R4-1813815, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation	
						R4-1814149, Changes to FR2 UL MIMO, OPPO	
						R4-1814180, Draft CR to TS 38.101-2 on channel arrangement	
						descriptions, LG Electronics Inc.	
						R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions	
						of UE channel bandwidth for CA, ZTE Corporation R4-1814163, draft CR of operating band for Power Class 2 in FR2,	
						LG Electronics	
						R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde &	
						Schwarz	
						R4-1814164, draftCR on MPR for TS 38.101-2, Huawei	
						R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated	
						R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing,	
						Qualcomm Incorporated	
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						R4-1815951, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated	
						R4-1814497, Correction on UL MIMO requirement for PC1 UE,	
						Samsung	
						R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2,	
						Intel Corporation	
						R4-1814698, Draft CR to TS38.101-2 updating references, Apple Inc.	
						R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL	
						Configuration, Qualcomm Incorporated	
						R4-1815801, draft CR editorial correction in 38.101-2, Ericsson	
						R4-1815810, draft Rel-15 CR to 38.101-2 to include n260 fallbacks needed, Ericsson	
						R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated	
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						Qualcomm Incorporated	
						R4-1816205, Draft CR to TS38.101-2 correcting the Pcmax	
			<u> </u>		<u> </u>	requirement, Apple Inc.	

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Incorporated R4-1816239, Draft CR to 38.101-2: On FR2 EISS A-MPR for n258, Qualcomm Incorporated R4-1816245, Draft CR to 38.101-2: TR2 EIS DL Signal Polarization Control of the Control o								
R4-196239, Draft CR to 38.101-2: Draft ZESS A-MPR for n258, Qualcomm Incorporated R4-1916245, Draft CR to 38.101-2: FRZ EIS DL Signal Polarization Clarification, Qualcomm Incorporated R4-1916257, Draft CR to TS38.101-2: focorrect UL CA scope for FRZ in Rev 15, Apple in  R4-1916267, Draft CR to TS38.101-2: to correct UL CA scope for FRZ in Rev 15, Apple in  R4-1916269, Draft CR to R5 83.101-2: (So.34) R8 alignment, Huawei R4-1916269, Draft CR for R5 exposure compliance in TS38.101-2; LG Electronics France R4-1916269, Draft CR to TS 38.101-2: Introducing multi-band applicability for PG3, Apple Inc  R4-1916269, Draft CR to TS 38.101-2: PRZ EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1916263, Verification of beam correspondence, Eicsson, Sony et al. 1916 1916, Draft CR to TS 38.301-12: Engrature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.  Electronics R4-1916644, Draft CR to TS 38.301-12: Emperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.  EN To TS 38.101-12: Implementation of endorsed draft CRs from RAN490 plus PG3 MPR changes to accommodate FR2 OBW Endorsed draft CRs from RAN490 plus PG3 MPR changes to accommodate FR2 OBW Endorsed draft CRs from RAN490 plus PG3 MPR changes to accommodate FR2 OBW Endorsed GR4-1900030, Draft CR on UL RIMC for FR2 UE RF Tests, Qualcomm Incorporated CR 4-1900031, draft CR to 38101-2 Cprecion to EVM equalizer spectrum flatness for Piz DeFSK, Intel Corporation R4-1900032, Draft CR on UL RIMC for FR2 UE RF Tests, Qualcomm Incorporated CR 4-1900033, GR3 to 38101-2 Cprecion on maxUpinKoUtyCycle in R74, 1900032, Draft CR on CR of Special Corporation R4-1900034, GR to shanes for Piz DeFSK, Intel Corporation R4-1900034, GR to shanes for Piz DeFSK, Intel Corporation R4-1900034, GR to shanes for Piz DeFSK, Intel Corporation R4-1900034, GR to Shanes Franciscus R4-1900035, GR to 38101-2 CR on ASMPR for power class 2 in FR2, LG Electronics R4-1900059, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics								
Qualcomm Incorporated R4-181626A, Draft CR to 38.101-2: FR2 EIS DL Signal Polarization Clarification, Qualcomm Incorporated R4-1816267. Draft CR to 1538.101-2 to correct UL CA scope for FR2 in Reh-15, Apple Inc. R4-1816269. Draft CR to 38.101-2 (S.3.4) RB alignment, Huawei A4-1816267. Draft CR to 38.101-2 (S.3.4) RB alignment, Huawei A4-1816269. Draft CR to 38.101-2; Introducing multi-band applicability for PC3, Apple Inc. R4-1816269. Draft CR to 15 38.101-2: Introducing multi-band applicability for PC3, Apple Inc. R4-1816263, draft CR to 18.38.101-2: Introducing multi-band applicability for PC3, Apple Inc. R4-1816263, draft CR to 18.38.101-2: Temperature Coordition for R4-1816263, draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816269. Part CR to 15 38.101-2: Temperature Coordition for R4-1816269. Part CR To 15 38.101-2: Temperature Coordition for R5-181626, draft CR for T6 38.101-2: Temperature Coordition for R6-181626, draft CR for T6 38.101-2: Temperature Coordition for R6-181626, draft CR for T6 R4-1816269. Part CR for R6-181626. Part CR for								
RA-1816245, Draft CR to 38.101-2: FRZ EIS D. Signal Polarization Clarification, Qualcomm Incorporated R4-1816257, Draft CR to TS38.101-2: to correct UL CA scope for FR2 in Rel-15. Apple Inc. R4-1816805, TDD contiguration for UE Tx test in FR2, Eriosson R4-1816805, Draft CR to 38.101-2 (5.3.4) R8 alignment, Huawei R4-1816751, Draft CR for RF exposure compliance in TS38.101-2, Draft CR for RF exposure compliance in TR38.101-2, Draft CR for RF exposure compliance							· · · · · · · · · · · · · · · · · · ·	
RA-1816257, Draft CR to TS38,101-2 to correct UL CA scope for FR2 in Rel-16, Apple Inc. R4-1816605, TDD configuration for UE Tx test in FR2, Encisson R4-1816605, Draft CR to 38.101-2 (5.3.4) RB alignment, Husweil R4-1816751, Draft CR for RF exposure compliance in TS38,101-2, LG Electronics France R4-1816020, Draft CR for RF exposure compliance in TS38, 101-2, R4-1816020, Draft CR for RF exposure compliance in TS38, 101-2, R4-1816020, Draft CR for RF exposure compliance in TS38, 101-2, R4-1816020, Draft CR for RF exposure compliance in TS38, 101-2, R4-1816020, Draft CR for RF exposure compliance in TS38, 101-2, R4-1816020, Draft CR for Obeam correspondence, Encisson, Sony R4-1816633, draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816644, Draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816649, Draft CR on UE, Type Towner, Traft CR for R6 f								
FR2 in Rel-15, Apple Inc. R4-1816695, TDID configuration for UE Tx test in FR2, Ericsson R4-1816695, TDID configuration for UE Tx test in FR2, Ericsson R4-1816695, TDID configuration for UE Tx test in FR2, Ericsson R4-1816695, Draft CR to S3,101-2 (5.3.4) RB alignment, Huswei R4-1816650, Draft CR to TS 38.101-2; Introducing multi-band applicability for PC3, Apple Inc. R4-1816650, Draft CR to TS 38.101-2; FR2 EIS Spherical Coverage Requirement, Qualcomm incorporated R5-181650, Verification of beam correspondence, Ericsson, Sony R4-1816650, Draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816664, Draft CR to TS 38.101-2; Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. R5-181664, Draft CR to TS 38.101-2; Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. R6-181664, Draft CR to TS 38.101-2; Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. R6-181664, Draft CR to TS 38.101-2; Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. R6-181664, Draft CR to TS 38.101-2; Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. R6-181664, Draft CR to TS 38.101-2; Temperature Condition for R6-181664, Draft CR to R6-181664, Draft CR to R7-181664, Draft CR to R7-18							Clarification, Qualcomm Incorporated	
R4-1816665, TDID configuration for UE Tx test in FR2, Ericsson R4-1816666, Jraft CR to S3, 510-12, C3, 514, B8 alignment, Huawei R4-1816751, Draft CR for RF exposure compliance in TS38,101-2, LG Electronics France R4-1816628, Draft CR to TS, 38,101-2; Introducing multi-band applicability for PG3, Apple Inc. R4-1816634, Draft CR to TS, 38,101-2; Introducing multi-band applicability for PG3, Apple Inc. R4-1816639, Verification of beam correspondence, Ericsson, Sony R4-1816639, Verification of Properties and Sony R4-1816639, Verification of R4-1816639, Verification R4-1816639, Verification of R4-1816639, Verification R4-1816639,							· ·	
R4-1816664, Draft CR to 38.101-2 (S.3.4) RB alignment, Huawei R4-1816751, Draft CR for RF exposure compliance in TS38.101-2, LG Electronics France R4-1816668, Draft CR to TS 38.101-2: Introducing multi-band applicability for Pc3, Apple Inc. R4-1816683, Draft CR to 18.3.101-2: FR2 EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1816683, Verification of beam correspondence, Ericsson, Sony R4-1816633, Verification of beam correspondence, Ericsson, Sony R4-1816633, Verification of beam correspondence, Ericsson, Sony R4-1816643, Draft CR to TS 38.101-2: FR2 EIS Spherical Coverage Requirement, Apple Inc.  2019-03 RAN#83 RP-190747 0018 1 F CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN4#89 (Draft CR of TS 38.101-2: Implementation of endorsed draft CRs from RAN4#89 (Draft CR of TS 38.101-2: Implementation of endorsed draft CRs from RAN4#89 (Draft CR of TS 2004) List Composition (Draft CR of TS 2004) List Composition (Draft CR of TS 2004) List Composition (Draft CR of TS 2004) List Corporation (Draft CR of TS 2004) List Corporation R4-190031, draft CR to 18101-2 CR 2004) List Corporation R4-190031, draft CR of 1810-12 CR 2004 (Draft CR of TS 2004) List Corporation R4-190031, draft CR of 1810-2 on CA BW Classes fallback groups, Intel Corporation (Draft CR of CR 2004), Draft CR 2004 (Draft CR 2004) List Corporation R4-1900386, CR 10.38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900383, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900532, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900532, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900674, Draft CR to 38.101-2: REV LUMIMO max. output power, Caulcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for CA Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for CA Qualcomm Incorporat								
R4-1816751, Draft CR for RF exposure compliance in TS38.101-2, LG Electronics France R4-1816626, Draft CR to TS 38.101-2: Introducing multi-band applicability for PG3, Apple Inc. R4-1816634, Draft CR to 38.101-2: FRZ EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1816639, Verification of beam correspondence, Ericsson, Sony R4-1816639, Verification of beam correspondence, Ericsson, Sony R4-1816639, derication of beam correspondence, Ericsson, Sony R4-1816640, derication of the R4-1816640, derication of R4-1816640, der								
LG Electronics France R4-1816626, Draft CR to TS 38.101-2: Introducing multi-band applicability for PC3, Apple Inc. R4-1816630, Partic Rto I as 38.101-2: FR2 EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1816630, Verification of beam correspondence, Ericsson, Sony R4-1816633, Varification of beam correspondence, Ericsson, Sony R4-1816633, Varification of beam correspondence, Ericsson, Sony R4-1816633, Varification of beam correspondence, Ericsson, Sony R4-1816644, Draft CR to TS 38.101-2: Temperature Condition for tasting EIRF Spherical Coverage requirement, Apple Inc. 2019-03 RAN#83 RP-190747 0018 1 F CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN4#90 RA1990049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm incorporated RA1990049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm incorporated RA1990132, draft CRs to 38101-2; FR2 transmit modulation quality for CA, Intel Corporation RA1990343, draft CRs on Sal101-2; FR2 transmit modulation quality for CA, Intel Corporation RA1990343, Draft CR on clarification of max/UplinkDutyCycle in FR2, OPPO RA1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung RA1990386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation RA1990433, CR to chance Annex E2.1, Qualcomm Incorporated RA1990599, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE corporation RA1990531, draft CR on AMPR for power class 2 in FR2, LG Electronics RA1990533, draft CR on AMPR for power class 2 in FR2, LG Electronics RA1990530, draft CR on AMPR for CA for power class 2 in FR2, LG Electronics RA1990677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Caulcomm Incorporated RA1990679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated RA1990679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated RA1990679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated RA1								
applicability for PC3, Apple Inc. R4-1816634, Draft CR to 38.101-2: FR2 EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1816639, Verification of beam correspondence, Ericsson, Sony R4-1816639, Verification of beam correspondence, Ericsson, Sony R4-1816639, Agriation of beam correspondence, Ericsson, Sony R4-1816634, Graft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816634, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN4#90 R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900132, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900254, Draft CR on dample and the propertion on R4-1900366, CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900387, draft CR to TS 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900383, draft CR on Amer Ex 1, Qualcomm Incorporated R4-1900393, draft CR to TS 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900394, Draft CR to TS 38.101-2 on CA BW Classes failback groups, Intel Corporation R4-1900385, draft CR to TS 38.101-2 in CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR to 38.101-2 in CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR to 38.101-2 in CA for power class 2 in FR2, LG Electronics R4-1900534, Draft CR to 38.101-2 in CA for power class 2 in FR2, LG Electronics for CA for power class 2 in FR2, LG							·	
R4-1816634, Draft CR to 38.101-2: FRZ EIS Spherical Coverage Requirement, Qualcomm Incorporated R4-1816639, Werlification of beam correspondence, Ericsson, Sony R4-18166303, draft CR on UE type for Power Class 2: in FRZ, LG Electronics R4-1816644, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.  2019-03 RAN#83 RP-190747 0018 1 F C R to TS 38.101-2: Implementation of endorsed draft CRs from RAN#90 plus PC3 MPR changes to accommodate FRZ OBW Endorced draft CRs from RAN#90 PC RAN#90 PC RAN#90 PC RESPONSIVE CRS from RAN#90 PC RESPONSIVE CRS from RAN#90 R4-1900049, Draft CR on UL RMC for FRZ UE RF Tests, Qualcomm Incorporated R4-1900049, Draft CR on UL RMC for FRZ UE RF Tests, Qualcomm Incorporated R4-19000131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900132, draft CR to 39101-2 FRZ transmit modulation quality for CA, Intel Corporation R4-190033, draft CR to 39101-2 FRZ transmit modulation quality for CA, Intel Corporation R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900308, CRt to 38.101-2 on CA BW Classes fallback groupe, Intel Corporation R4-190038, CRt to 38.101-2 on A BW Classes fallback groupe, Intel Corporation R4-190039, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-190039, draft CR on A-MBPR for power class 2 in FRZ, LG Electronics R4-1900333, draft CR on A-MBPR for power reduction for CA for 1900-835, draft CR on A maximum undupt power reduction for CA for 1900-835, and CR on A-MBPR for Dower class 2 in FRZ, LG Electronics R4-1900-835, and CR on A-MBPR for CA for power reduction for CA (Dalcomm Incorporated R4-1900-842, Draft CR to 38.101-2: ERZ ULMIMO max. output power, Qualcomm Incorporated R4-1900-806, Praft CR to 38.101-2: ERZ ULMIMO max. output power, Qualcomm Incorporated R4-1900-806, Praft CR to 38.101-2: LB requirement update, Qualcomm Incorporated R4-1900-906, Praft CR to R5.1								
Requirement, Qualcomm Incorporated R4-1816633, Verification of beam correspondence, Ericsson, Sony R4-1816633, draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816634, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.  2019-03 RAN#83 RP-190747 0018 1 F CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN#90 R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900132, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for P2 BPSK, Intel Corporation R4-1900254, Draft CR on Satis Corporation R4-1900386, CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900380, CR to 38.3.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900383, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900383, CR to to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900534, Craft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Add annex for UE coordinate								
R4-1816839, Verification of beam correspondence, Ericsson, Sony R4-1816833, draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816644, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.  To TS 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN4#90 R4-1900049, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on Garification of Annex on Characteristics of the Interfering Signal, Samsung R4-1900380, Draft CR introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900380, Draft CR to TS 38.101-2 on BCS definition for intra-band non-contiguous CA, ZTE Corporation R4-1900331, draft CR to TS 38.101-2 on BCS definition for intra-band non-contiguous CA, ZTE Corporation R4-1900333, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900333, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900333, draft CR on A-MPR for For CA for power class 2 in FR2, LG Electronics R4-1900330, draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900575, Draft CR to 38.101-2: EVM Requirement to PRACH, Qualcomm Incorporated R4-1900679, Draft CR to Ro 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to Ro 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to Ro neditorial error of TS38.101-2, LG Electronics Inc. R4-1900736, Draft CR on power class Sinting in R4-1900736, Draft CR on purious emission limit in 38.101-2, Qualcomm Incorporated R4-1900769, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated								
R4-1816833, draft CR on UE type for Power Class 2 in FR2, LG Electronics R4-1816844, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement. Apple Inc.  Provided the Common State of CR of TS 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for PI2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900380, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900309, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900380, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900331, draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900331, draft CR to R4-MPR for power class 2 in FR2, LG Electronics R4-1900333, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900335, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900350, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900370, Traft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900673, Draft CR to 38.101-2: EVM Requirement update, Qualcomm Incorporated R4-1900670, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900736, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900736, Draft CR to neditorial error of TS38.101-2, LG Electronics Inc. R4-1900736, Dra								
Electronics R4-1816844, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc. To TS 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorced draft CRs from RAN4#90 R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900540, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 FR2 transmit modulation quality for CA. Intel Corporation R4-1900304, Draft CR on activation of Annex on Characteristics of the Interfering Signal, Samsung R4-190036, CR to 38.101-2 FR2 transmit modulation quality for CA. Intel Corporation R4-190036, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-190036, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-190039, Draft CR to TS 38. 101-2 on BCS definition for intra-band non-contiguous CA, 2TE Corporation R4-1900331, draft CR to TS 38. 101-2 on BCS definition for intra-band non-contiguous CA, 2TE Corporation R4-1900333, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR to R on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900530, Draft CR on Sa.101-2: EVM Requirement proft CR A, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement update, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmi								
Itesting EIRP Spherical Coverage requirement, Apple Inc.							Electronics	
2019-03 RAN#83 RP-190747 0018 1 F CR to Ts 38.101-2: Implementation of endorsed draft CRs from RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW Endorsed draft CRs from RAN4#90 RA-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900690, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900593, draft CR on AMPR for power class 2 in FR2, LG Electronics R4-1900531, draft CR on AMPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-190057, Draft CR to 38.101-2: PR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EWR Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EWR Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900759, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900759, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900759, Draft CR to 38.101-2: Add annex for UE coordinate							*	
Endorsed draft CRs from RAN4#90 R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900051, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900389, Draft CR to T5 38.101-2 on BC5 definition for intraband non-contiguous CA, ZTE Corporation R4-1900539, Jraft CR to T5 38.101-2 on BC5 definition for intraband non-contiguous CA, ZTE Corporation R4-1900533, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900539, Traft CR to T6 APR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR to Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for PRACH Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement update, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for FR2, Rohde & Schwarz R4-1900758, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900758, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900758, Draft CR to 38.101-2: Add annex for UE coordinate	2212.22	D.4.1	55 466545	2212		_		
Endorced draft CRs from RAN##90 RA-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated RA-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated RA-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation RA-1900131, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation RA-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO RA-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung RA-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation RA-1900443, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation RA-1900430, GR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation RA-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics RA-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics RA-1900533, draft CR on A-MPR for Dower class 2 in FR2, LG Electronics RA-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated RA-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated RA-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900778, Update to PRACH EVM window length for FR2, Rohde & Schwarz RA-1900778, Update to PRACH EVM window length for FR2, Rohde & Schwarz RA-1900778, Draft CR to 38.101-2: Add annex for UE coordinate	2019-03	RAN#83	RP-190747	0018	1	F		15.5.0
R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900131, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900509, Draft CR to TS 38.101-2 on ESC definition for intraband non-contiguous CA, ZTE Corporation R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-19005031, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900536, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR to 38.101-2: ER2 ULMIMO max. output power, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement type CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement to CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement to CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Actional legal control l							11.7.114#30 plus 1 C3 Wil 11 changes to accommodate 1 112 ODW	
Incorporated RA-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated RA-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for PI2 BPSK, Intel Corporation RA-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation RA-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO RA-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung RA-1900336, CR to 38.101-2 on CA BW Classes fallback groups, intel Corporation RA-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation RA-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics RA-1900533, draft CR on A-MPR for power class 2 in FR2, LG Electronics RA-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics RA-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics RA-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics RA-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated RA-1900677, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: EVM Requirement for RACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900678, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated RA-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated RA-1900755, Draft CR to 10 spurious emission limit in 38.101-2, Qualcomm Incorporated							Endorced draft CRs from RAN4#90	
R4-190050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm Incorporated R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for PI2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900234, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-190043, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on aximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900536, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900536, draft CR on 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to R5.101-2: Add annex for UE coordinate							·	
Incorporated RA-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation RA-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation RA-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO RA-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung RA-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation RA-190043, CR to chance Annex E2.1, Qualcomm Incorporated RA-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation RA-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics RA-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics RA-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics RA-1900533, draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated RA-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated RA-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated RA-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated RA-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900736, Draft CR to 88.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900736, Draft CR to 88.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated RA-1900736, Draft CR on on editorial error of TS38.101-2, LG Electronics Inc. RA-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. RA-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated RA-1900755, Draft CR to 38.101-2: Add annex for UE coordinate								
R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-190301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-190043, CR to chance Annex E2.1, Qualcomm Incorporated R4-190059, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900679, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900755, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to 38.101-2: Add annex for UE coordinate								
spectrum flatness for Pi2 BPSK, Intel Corporation R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-190043, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement to PRACH, Qualcomm Incorporated R4-1900689, Draft CR to 38.101-2: EWM Requirement for CA, Qualcomm Incorporated R4-1900689, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900689, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900689, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900785, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900786, Draft CR to 38.101-2: Add annex for UE coordinate								
for CA, Intel Corporation R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900534, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement update, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900690, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-19007055, Draft CR to 38.101-2: Add annex for UE coordinate								
R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900755, Draft CR to 38.101-2: Add annex for UE coordinate							R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality	
FR2, OPPO R4-1900301, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900736, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900738, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900738, Update to RACH EVM window length for FR2, Rohde & Schwarz								
R4-190031, Draft CR: Introduction of Annex on Characteristics of the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: Add annex for UE coordinate								
the Interfering Signal, Samsung R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups, Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-190079, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900736, Draft CR to R58.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900736, Draft CR to R58.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900736, Draft CR to R58.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to R58.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to R58.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900755, Draft CR to R58.101-2: Add annex for UE coordinate								
Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-19005049, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-19007055, Draft CR to 38.101-2: Add annex for UE coordinate								
R4-1900543, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900533, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: LBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900755, Draft CR on spurious emission limit in 28.101-2, Qualcomm Incorporated R4-1900755, Draft CR to 38.101-2: Add annex for UE coordinate								
R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intraband non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900792, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated R4-1900755, Draft CR on spurious emission limit in 28.101-2, Qualcomm Incorporated								
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2010.06	DANHOA	DD 101240	0024	-	Section 6.2.2.3 requirements	ction 6.2.2.0 to modify the MPR=0dB waveform and to modify the MPR tables to accommodate the OBW	45.6.0
2019-06	RAN#84	RP-191240	0021	F	CR to TS 38.10 RAN4#90bis ar	11-2: Implementation of endorsed draft CRs from and RAN4#91	15.6.0
						CRs from RAN4#90Bis: Draft CR to TS 38.101-2 Correction to Pcmax, Intel Corporation Draft CR on PRACH and PUCCH format description for EVM in FR2Anritsu corporation	
					R4-1903121	Draft CR on DL power allocation for TS 38.101-2 Intel Corporation	
					R4-1903242 R4-1903474	Adding BCS definition in TS38.101-2 CATT draft CR of in-band emission for FR2 PC2 LG Electronics	
					R4-1903888	Draft CR: Alignment of FR2 DL scheduling of DL	
					R4-1904001	RMC with UL RMCEricsson Draft CR for TS 38.101-2 – UE coordinate system	
					R4-1904411	Rohde & Schwarz draft Rel-15 CR for editorial corrections in 38.101-2	
					R4-1904553	Ericsson Draft CR to 38.101-2: FR2 power dynamics DTX	
					R4-1904930	removal Qualcomm Incorporated Draft CR to 38.101-2: Updating MPR wording in	
					R4-1904931	ULMIMO section Qualcomm Incorporated Draft CR to clarify frequency of carrier leakage in	
					R4-1904932	RBs for FR2 Anritsu corporation Draft CR on editorial error of TS38.101-2 LG	
						Electronics France	
					R4-1904933	Draft CR on UE optional bandwidth for FR2 Huawei, HiSilicon	
					R4-1904956	Draft CR for TS 38.101-2: Corrections to configurations for intra-band non-contiguous CA	
					R4-1904961	MediaTek Inc.  Draft CR for TR38.101-2 – Update to EVM	
						averaging Rohde & Schwarz	
					R4-1904962	Draft CR to 38.101-2: FR2 ULMIMO EVM Qualcomm Incorporated	
					R4-1904966	Draft CR to TS 38.101-2 CA maximum input level Intel Corporation	
					R4-1904986	Draft CR for TS 38.101-2: Corrections to EVM equalizer spectrum flatness requirements MediaTek Inc.	
					R4-1904994	draft CR to 38.101-2 Correction to ACS and In-band	
					R4-1905003	Blocking notes Intel Corporation Draft CR to 38.101-2: FR2 PC3 and PC1 MPR	
					R4-1905005	Qualcomm Incorporated Draft CR for 38.101-2 frequency separation class Huawei, HiSilicon	
					Endorsed draft	CRs from RAN4#91:	
					R4-1905504	Change description 4.2(d) in Applicability of	
					R4-1905685	minimum requirements for TS 38.101-2 vivo Draft CR to 38.101-2: FR2 Sensitivity Qualcomm	
					R4-1905764	Incorporated draft CR to 38.101-2 UE maximum output power	
					R4-1905765	reduction for UL-MIMOIntel Corporation draft CR to 38.101-2 UE maximum output power for	
					1000700	UL-MIMO Intel Corporation	

R4-1905796	Correction to a description of PRB for in-band	
	emission in FR2 Anritsu Corporation	
R4-1905798	Correction to power control in FR2 Anritsu	
	Corporation	
R4-1905821	draft CR of loosening EIS for FR2 PC2 LG	
	Electronics Inc.	
R4-1907003	Draft CR for editorial corrections in TS 38.101-2	
	Google Inc.	
R4-1907420	draft CR of simple application for FR2 PC2 and 4	
	requirements with PC3 same requirements LG	
	Electronics Inc.	
R4-1907423	Draft CR for TS 38.101-2 Correction of channel	
	bandwidth set for NR CA Huawei, HiSilicon,	
	CMCC	
R4-1907437	Draft CR to 38.101-2: Insert definitions Qualcomm	
	Incorporated	
R4-1907443	Draft CR to TS38.101-2 Complete FR2 MPR/A-	
	MPR Intel Corporation	
R4-1907444	Amendment of the relative power tolerance	
	requirement Ericsson, Qualcomm Incorporated	
R4-1907446	Draft CR to 38.101-2: FR2 CA REFESNS	
	Qualcomm Incorporated	
R4-1907447	Draft CR to 38.101-2 on UL RMC slot patterns	
	Apple Inc.	
R4-1907466	Draft CR to 38.101-2: FR2 CA MPR enhancement	
	Qualcomm Incorporated	
R4-1907468	Draft CR to 38.101-2: FR2 MPR Wording CleanUp	
	Qualcomm Incorporated	
R4-1907473	Draft CR to TS38.101-2 on FR2 PC3 UE	
	maxUplinkDutyCycle Nokia, Nokia Shanghai Bell	
R4-1907478	Draft CR to TS 38.101-2 on configurations for intra-	
	band contiguous CA  ZTE Corporation	
R4-1907493	Correction to Pcmax and Pumax for CA Ericsson	
R4-1907611	Draft CR to TS38.101-2 on beam correspondence	
	Samsung, Apple, Verizon	
R4-1907688	Correction to CA carrier spacing Ericsson	

## History

Document history							
V15.2.0	July 2018	Publication					
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